

EPROM/ROM-Based 8-bit CMOS Microcontroller Series

Devices Included in this Data Sheet:

- PIC16C54
- PIC16CR54
- PIC16C55
- PIC16C56
- PIC16CR56
- PIC16C57
- PIC16CR57
- PIC16C58

Note:

PIC16CR58

PIC16C5X refers to all revisions of the part (i.e., PIC16C54 refers to PIC16C54, PIC16C54A, and PIC16C54C), unless specifically called out otherwise.

High-Performance RISC CPU:

- · Only 33 single word instructions to learn
- All instructions are single cycle except for program branches which are two-cycle
- Operating speed: DC 40 MHz clock input DC - 100 ns instruction cycle

Device	Pins	I/O	EPROM/ ROM	RAM
PIC16C54	18	12	512	25
PIC16C54A	18	12	512	25
PIC16C54C	18	12	512	25
PIC16CR54A	18	12	512	25
PIC16CR54C	18	12	512	25
PIC16C55	28	20	512	24
PIC16C55A	28	20	512	24
PIC16C56	18	12	1K	25
PIC16C56A	18	12	1K	25
PIC16CR56A	18	12	1K	25
PIC16C57	28	20	2K	72
PIC16C57C	28	20	2K	72
PIC16CR57C	28	20	2K	72
PIC16C58B	18	12	2K	73
PIC16CR58B	18	12	2K	73

- 12-bit wide instructions
- · 8-bit wide data path
- · Seven or eight special function hardware registers
- Two-level deep hardware stack
- Direct, indirect and relative addressing modes for data and instructions

Peripheral Features:

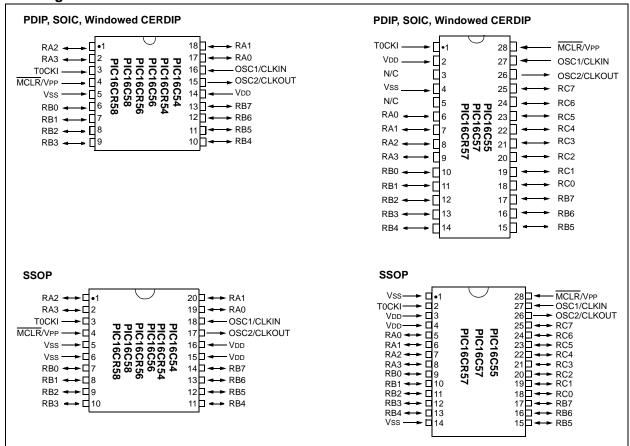
- 8-bit real time clock/counter (TMR0) with 8-bit programmable prescaler
- Power-on Reset (POR)
- Device Reset Timer (DRT)
- Watchdog Timer (WDT) with its own on-chip RC oscillator for reliable operation
- Programmable Code Protection
- · Power saving SLEEP mode
- · Selectable oscillator options:
 - RC: Low cost RC oscillator
 - XT: Standard crystal/resonator
 - HS: High speed crystal/resonator
 - LP: Power saving, low frequency crystal

CMOS Technology:

- Low power, high speed CMOS EPROM/ROM technology
- · Fully static design
- Wide operating voltage and temperature range:
 - EPROM Commercial/Industrial 2.0V to 6.25V
 - ROM Commercial/Industrial 2.0V to 6.25V
 - EPROM Extended 2.5V to 6.0V
 - ROM Extended 2.5V to 6.0V
- Low power consumption
 - < 2 mA typical @ 5V, 4 MHz
 - 15 μA typical @ 3V, 32 kHz
 - < 0.6 μA typical standby current (with WDT disabled) @ 3V, 0°C to 70°C

Note: In this document, figure and table titles refer to all varieties of the part number indicated, (i.e., The title "Figure 15-1: Load Conditions For Device Timing Specifications - PIC16C54A", also refers to PIC16LC54A and PIC16LV54A parts), unless specifically called out otherwise.

Pin Diagrams



Device Differences

Device Dillere	11669					
Device	Voltage Range	Oscillator Selection (Program)	Oscillator	Process Technology (Microns)	ROM Equivalent	MCLR Filter
PIC16C54	2.5-6.25	Factory	See Note 1	1.2	PIC16CR54A	No
PIC16C54A	2.0-6.25	User	See Note 1	0.9	_	No
PIC16C54C	2.5-5.5	User	See Note 1	0.7	PIC16CR54C	Yes
PIC16C55	2.5-6.25	Factory	See Note 1	1.7	_	No
PIC16C55A	2.5-5.5	User	See Note 1	0.7	_	Yes
PIC16C56	2.5-6.25	Factory	See Note 1	1.7	_	No
PIC16C56A	2.5-5.5	User	See Note 1	0.7	PIC16CR56A	Yes
PIC16C57	2.5-6.25	Factory	See Note 1	1.2	_	No
PIC16C57C	2.5-5.5	User	See Note 1	0.7	PIC16CR57C	Yes
PIC16C58B	2.5-5.5	User	See Note 1	0.7	PIC16CR58B	Yes
PIC16CR54A	2.5-6.25	Factory	See Note 1	1.2	N/A	Yes
PIC16CR54C	2.5-5.5	Factory	See Note 1	0.7	N/A	Yes
PIC16CR56A	2.5-5.5	Factory	See Note 1	0.7	N/A	Yes
PIC16CR57C	2.5-5.5	Factory	See Note 1	0.7	N/A	Yes
PIC16CR58B	2.5-5.5	Factory	See Note 1	0.7	N/A	Yes

Note 1: If you change from this device to another device, please verify oscillator characteristics in your application.

Note: The table shown above shows the generic names of the PIC16C5X devices. For device varieties, please refer to Section 2.0.

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NOTES:



8-Bit EPROM/ROM-Based CMOS Microcontrollers

1.0 GENERAL DESCRIPTION

The PIC16C5X from Microchip Technology is a family of low cost, high performance, 8-bit fully static, EPROM/ROM-based CMOS microcontrollers. It employs a RISC architecture with only 33 single word/single cycle instructions. All instructions are single cycle except for program branches which take two cycles. The PIC16C5X delivers performance in an order of magnitude higher than its competitors in the same price category. The 12-bit wide instructions are highly symmetrical resulting in 2:1 code compression over other 8-bit microcontrollers in its class. The easy to use and easy to remember instruction set reduces development time significantly.

The PIC16C5X products are equipped with special features that reduce system cost and power requirements. The Power-on Reset (POR) and Device Reset Timer (DRT) eliminate the need for external RESET circuitry. There are four oscillator configurations to choose from, including the power saving LP (Low Power) oscillator and cost saving RC oscillator. Power saving SLEEP mode, Watchdog Timer and Code Protection features improve system cost, power and reliability.

The UV erasable CERDIP packaged versions are ideal for code development, while the cost effective One Time Programmable (OTP) versions are suitable for production in any volume. The customer can take full advantage of Microchip's price leadership in OTP microcontrollers, while benefiting from the OTP's flexibility.

The PIC16C5X products are supported by a full featured macro assembler, a software simulator, an in-circuit emulator, a low cost development programmer and a full featured programmer. All the tools are supported on IBM® PC and compatible machines.

1.1 Applications

The PIC16C5X series fits perfectly in applications ranging from high speed automotive and appliance motor control to low power remote transmitters/receivers, pointing devices and telecom processors. The EPROM technology makes customizing application programs (transmitter codes, motor speeds, receiver frequencies, etc.) extremely fast and convenient. The small footprint packages, for through hole or surface mounting, make this microcontroller series perfect for applications with space limitations. Low cost, low power, high performance ease of use and I/O flexibility make the PIC16C5X series very versatile even in areas where no microcontroller use has been considered before (e.g., timer functions, replacement of "glue" logic in larger systems, co-processor applications).

TABLE 1-1: PIC16C5X FAMILY OF DEVICES

Features	PIC16C54	PIC16CR54	PIC16C55	PIC16C56	PIC16CR56
Maximum Operation Frequency	40 MHz	20 MHz	40 MHz	40 MHz	20 MHz
EPROM Program Memory (x12 words)	512	_	512	1K	_
ROM Program Memory (x12 words)	_	512	_	_	1K
RAM Data Memory (bytes)	25	25	24	25	25
Timer Module(s)	TMR0	TMR0	TMR0	TMR0	TMR0
I/O Pins	12	12	20	12	12
Number of Instructions	33	33	33	33	33
Packages	18-pin DIP, SOIC; 20-pin SSOP	18-pin DIP, SOIC; 20-pin SSOP	28-pin DIP, SOIC; 28-pin SSOP	18-pin DIP, SOIC; 20-pin SSOP	18-pin DIP, SOIC; 20-pin SSOP

All PIC® Family devices have Power-on Reset, selectable Watchdog Timer, selectable Code Protect and high I/O current capability.

Features	PIC16C57	PIC16CR57	PIC16C58	PIC16CR58
Maximum Operation Frequency	40 MHz	20 MHz	40 MHz	20 MHz
EPROM Program Memory (x12 words)	2K	_	2K	_
ROM Program Memory (x12 words)	_	2K	_	2K
RAM Data Memory (bytes)	72	72	73	73
Timer Module(s)	TMR0	TMR0	TMR0	TMR0
I/O Pins	20	20	12	12
Number of Instructions	33	33	33	33
Packages	28-pin DIP, SOIC; 28-pin SSOP	28-pin DIP, SOIC; 28-pin SSOP	18-pin DIP, SOIC; 20-pin SSOP	18-pin DIP, SOIC; 20-pin SSOP

All PIC^{\otimes} Family devices have Power-on Reset, selectable Watchdog Timer, selectable Code Protect and high I/O current capability.

2.0 PIC16C5X DEVICE VARIETIES

A variety of frequency ranges and packaging options are available. Depending on application and production requirements, the proper device option can be selected using the information in this section. When placing orders, please use the PIC16C5X Product Identification System at the back of this data sheet to specify the correct part number.

For the PIC16C5X family of devices, there are four device types, as indicated in the device number:

- C, as in PIC16C54C. These devices have EPROM program memory and operate over the standard voltage range.
- LC, as in PIC16LC54A. These devices have EPROM program memory and operate over an extended voltage range.
- CR, as in PIC16CR54A. These devices have ROM program memory and operate over the standard voltage range.
- LCR, as in PIC16LCR54A. These devices have ROM program memory and operate over an extended voltage range.

2.1 UV Erasable Devices (EPROM)

The UV erasable versions offered in CERDIP packages, are optimal for prototype development and pilot programs.

UV erasable devices can be programmed for any of the four oscillator configurations. Microchip's PICSTART® Plus⁽¹⁾ and PRO MATE® programmers both support programming of the PIC16C5X. Third party programmers also are available. Refer to the

Third Party Guide (DS00104) for a list of sources.2.2 One-Time-Programmable (OTP) Devices

The availability of OTP devices is especially useful for customers expecting frequent code changes and updates, or small volume applications.

The OTP devices, packaged in plastic packages, permit the user to program them once. In addition to the program memory, the configuration bits must be programmed.

Note 1: PIC16LC54C and PIC16C54A devices require OSC2 not to be connected while programming with PICSTART® Plus programmer.

2.3 Quick-Turnaround-Production (QTP) Devices

Microchip offers a QTP Programming Service for factory production orders. This service is made available for users who choose not to program a medium to high quantity of units and whose code patterns have stabilized. The devices are identical to the OTP devices but with all EPROM locations and configuration bit options already programmed by the factory. Certain code and prototype verification procedures apply before production shipments are available. Please contact your Microchip Technology sales office for more details.

2.4 Serialized Quick-Turnaround-Production (SQTPSM) Devices

Microchip offers the unique programming service where a few user defined locations in each device are programmed with different serial numbers. The serial numbers may be random, pseudo-random or sequential. The devices are identical to the OTP devices but with all EPROM locations and configuration bit options already programmed by the factory.

Serial programming allows each device to have a unique number which can serve as an entry code, password or ID number.

2.5 Read Only Memory (ROM) Devices

Microchip offers masked ROM versions of several of the highest volume parts, giving the customer a low cost option for high volume, mature products.

NOTES:

3.0 ARCHITECTURAL OVERVIEW

The high performance of the PIC16C5X family can be attributed to a number of architectural features commonly found in RISC microprocessors. To begin with, the PIC16C5X uses a Harvard architecture in which program and data are accessed on separate buses. This improves bandwidth over traditional von Neumann architecture where program and data are fetched on the same bus. Separating program and data memory further allows instructions to be sized differently than the 8-bit wide data word. Instruction opcodes are 12 bits wide making it possible to have all single word instructions. A 12-bit wide program memory access bus fetches a 12-bit instruction in a single cycle. A twostage pipeline overlaps fetch and execution of instructions. Consequently, all instructions (33) execute in a single cycle except for program branches.

The PIC16C54/CR54 and PIC16C55 address 512 x 12 of program memory, the PIC16C56/CR56 address 1K x 12 of program memory, and the PIC16C57/CR57 and PIC16C58/CR58 address 2K x 12 of program memory. All program memory is internal.

The PIC16C5X can directly or indirectly address its register files and data memory. All special function registers including the program counter are mapped in the data memory. The PIC16C5X has a highly orthogonal (symmetrical) instruction set that makes it possible to carry out any operation on any register using any addressing mode. This symmetrical nature and lack of 'special optimal situations' make programming with the PIC16C5X simple yet efficient. In addition, the learning curve is reduced significantly.

The PIC16C5X device contains an 8-bit ALU and working register. The ALU is a general purpose arithmetic unit. It performs arithmetic and Boolean functions between data in the working register and any register file.

The ALU is 8 bits wide and capable of addition, subtraction, shift and logical operations. Unless otherwise mentioned, arithmetic operations are two's complement in nature. In two-operand instructions, typically one operand is the W (working) register. The other operand is either a file register or an immediate constant. In single operand instructions, the operand is either the W register or a file register.

The W register is an 8-bit working register used for ALU operations. It is not an addressable register.

Depending on the instruction executed, the ALU may affect the values of the Carry (C), Digit Carry (DC), and Zero (Z) bits in the STATUS register. The C and DC bits operate as a borrow and digit borrow out bit, respectively, in subtraction. See the SUBWF and ADDWF instructions for examples.

A simplified block diagram is shown in Figure 3-1, with the corresponding device pins described in Table 3-1 (for PIC16C54/56/58) and Table 3-2 (for PIC16C55/57).

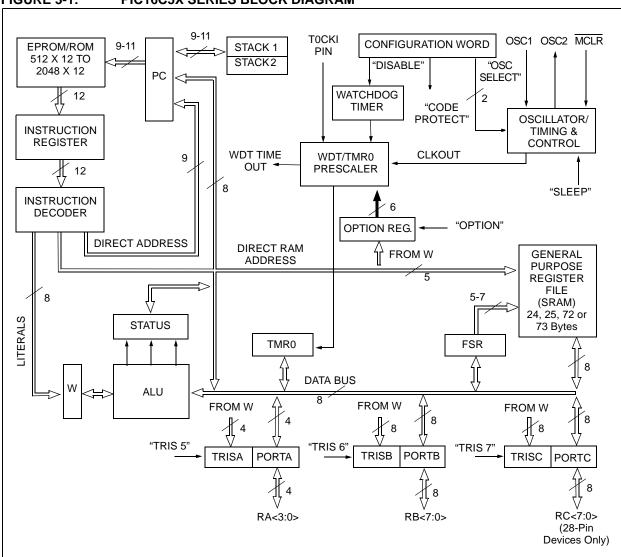


FIGURE 3-1: PIC16C5X SERIES BLOCK DIAGRAM

TABLE 3-1: PINOUT DESCRIPTION - PIC16C54, PIC16C754, PIC16C756, PIC16C756, PIC16C758, PIC16C758

D' N	Pi	n Numb	er	Pin	Buffer	B t di
Pin Name	DIP	SOIC	SSOP	Туре	Туре	Description
RA0	17	17	19	I/O	TTL	Bi-directional I/O port
RA1	18	18	20	I/O	TTL	
RA2	1	1	1	I/O	TTL	
RA3	2	2	2	I/O	TTL	
RB0	6	6	7	I/O	TTL	Bi-directional I/O port
RB1	7	7	8	I/O	TTL	
RB2	8	8	9	I/O	TTL	
RB3	9	9	10	I/O	TTL	
RB4	10	10	11	I/O	TTL	
RB5	11	11	12	I/O	TTL	
RB6	12	12	13	I/O	TTL	
RB7	13	13	14	I/O	TTL	
T0CKI	3	3	3	I	ST	Clock input to Timer0. Must be tied to Vss or VDD, if not in
						use, to reduce current consumption.
MCLR/VPP	4	4	4	I	ST	Master clear (RESET) input/programming voltage input.
						This pin is an active low RESET to the device. Voltage on the MCLR/VPP pin must not exceed VDD to avoid unin-
						tended entering of Programming mode.
OSC1/CLKIN	16	16	18	I	ST	Oscillator crystal input/external clock source input.
OSC2/CLKOUT	15	15	17	0		Oscillator crystal output. Connects to crystal or resonator
						in crystal Oscillator mode. In RC mode, OSC2 pin outputs
						CLKOUT, which has 1/4 the frequency of OSC1 and
						denotes the instruction cycle rate.
VDD	14	14	15,16	Р	_	Positive supply for logic and I/O pins.
Vss	5	5	5,6	Р	_	Ground reference for logic and I/O pins.

Legend: I = input, O = output, I/O = input/output, P = power, — = Not Used, TTL = TTL input, ST = Schmitt Trigger input

TABLE 3-2: PINOUT DESCRIPTION - PIC16C55, PIC16C57, PIC16CR57

Din Name	Pin Number			Pin	Buffer	Description
Pin Name	DIP	SOIC	SSOP	Туре	Type	Description
RA0	6	6	5	I/O	TTL	Bi-directional I/O port
RA1	7	7	6	I/O	TTL	·
RA2	8	8	7	I/O	TTL	
RA3	9	9	8	I/O	TTL	
RB0	10	10	9	I/O	TTL	Bi-directional I/O port
RB1	11	11	10	I/O	TTL	·
RB2	12	12	11	I/O	TTL	
RB3	13	13	12	I/O	TTL	
RB4	14	14	13	I/O	TTL	
RB5	15	15	15	I/O	TTL	
RB6	16	16	16	I/O	TTL	
RB7	17	17	17	I/O	TTL	
RC0	18	18	18	I/O	TTL	Bi-directional I/O port
RC1	19	19	19	I/O	TTL	
RC2	20	20	20	I/O	TTL	
RC3	21	21	21	I/O	TTL	
RC4	22	22	22	I/O	TTL	
RC5	23	23	23	I/O	TTL	
RC6	24	24	24	I/O	TTL	
RC7	25	25	25	I/O	TTL	
T0CKI	1	1	2	I	ST	Clock input to Timer0. Must be tied to Vss or VDD, if not in use, to reduce current consumption.
MCLR	28	28	28	I	ST	Master clear (RESET) input. This pin is an active low RESET to the device.
OSC1/CLKIN	27	27	27	I	ST	Oscillator crystal input/external clock source input.
OSC2/CLKOUT	26	26	26	0	_	Oscillator crystal output. Connects to crystal or resonator in crystal Oscillator mode. In RC mode, OSC2 pin outputs CLKOUT which has 1/4 the frequency of OSC1, and denotes the instruction cycle rate.
VDD	2	2	3,4	Р	_	Positive supply for logic and I/O pins.
Vss	4	4	1,14	Р		Ground reference for logic and I/O pins.
N/C	3,5	3,5		_		Unused, do not connect.

Legend: I = input, O = output, I/O = input/output, P = power, — = Not Used, TTL = TTL input, ST = Schmitt Trigger input

3.1 Clocking Scheme/Instruction Cycle

The clock input (OSC1/CLKIN pin) is internally divided by four to generate four non-overlapping quadrature clocks, namely Q1, Q2, Q3 and Q4. Internally, the program counter is incremented every Q1 and the instruction is fetched from program memory and latched into the instruction register in Q4. It is decoded and executed during the following Q1 through Q4. The clocks and instruction execution flow are shown in Figure 3-2 and Example 3-1.

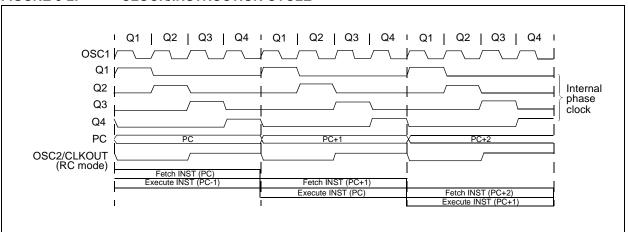
3.2 Instruction Flow/Pipelining

An Instruction Cycle consists of four Q cycles (Q1, Q2, Q3 and Q4). The instruction fetch and execute are pipelined such that fetch takes one instruction cycle, while decode and execute takes another instruction cycle. However, due to the pipelining, each instruction effectively executes in one cycle. If an instruction causes the program counter to change (e.g., GOTO), then two cycles are required to complete the instruction (Example 3-1).

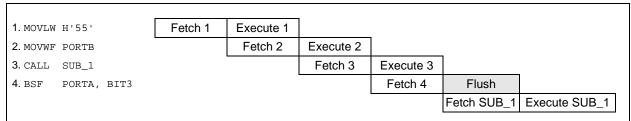
A fetch cycle begins with the program counter (PC) incrementing in Q1.

In the execution cycle, the fetched instruction is latched into the Instruction Register in cycle Q1. This instruction is then decoded and executed during the Q2, Q3 and Q4 cycles. Data memory is read during Q2 (operand read) and written during Q4 (destination write).

FIGURE 3-2: CLOCK/INSTRUCTION CYCLE



EXAMPLE 3-1: INSTRUCTION PIPELINE FLOW



All instructions are single cycle, except for any program branches. These take two cycles since the fetch instruction is "flushed" from the pipeline, while the new instruction is being fetched and then executed.

NOTES:

4.0 OSCILLATOR CONFIGURATIONS

4.1 Oscillator Types

PIC16C5Xs can be operated in four different oscillator modes. The user can program two configuration bits (FOSC1:FOSC0) to select one of these four modes:

LP: Low Power Crystal
 XT: Crystal/Resonator

3. HS: High Speed Crystal/Resonator

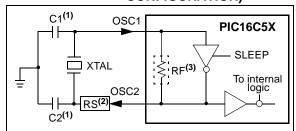
4. RC: Resistor/Capacitor

Note: Not all oscillator selections available for all parts. See Section 9.1.

4.2 Crystal Oscillator/Ceramic Resonators

In XT, LP or HS modes, a crystal or ceramic resonator is connected to the OSC1/CLKIN and OSC2/CLKOUT pins to establish oscillation (Figure 4-1). The PIC16C5X oscillator design requires the use of a parallel cut crystal. Use of a series cut crystal may give a frequency out of the crystal manufacturers specifications. When in XT, LP or HS modes, the device can have an external clock source drive the OSC1/CLKIN pin (Figure 4-2).

FIGURE 4-1: CRYSTAL/CERAMIC
RESONATOR OPERATION
(HS, XT OR LP OSC
CONFIGURATION)



- **Note 1:** See Capacitor Selection tables for recommended values of C1 and C2.
 - **2:** A series resistor (RS) may be required for AT strip cut crystals.
 - 3: RF varies with the Oscillator mode chosen (approx. value = $10 \text{ M}\Omega$).

FIGURE 4-2: EXTERNAL CLOCK INPUT OPERATION (HS, XT OR LP OSC CONFIGURATION)

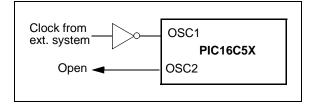


TABLE 4-1: CAPACITOR SELECTION FOR CERAMIC RESONATORS - PIC16C5X, PIC16CR5X

Osc Type	Resonator Freq	1	
XT	455 kHz	68-100 pF	68-100 pF
	2.0 MHz	15-33 pF	15-33 pF
	4.0 MHz	10-22 pF	10-22 pF
HS	8.0 MHz	10-22 pF	10-22 pF
	16.0 MHz	10 pF	10 pF

These values are for design guidance only. Since each resonator has its own characteristics, the user should consult the resonator manufacturer for appropriate values of external components.

TABLE 4-2: CAPACITOR SELECTION FOR CRYSTAL OSCILLATOR - PIC16C5X. PIC16CR5X

		000X, 1 10 10	011071
Osc Type	Crystal Freq	Cap.Range C1	Cap. Range C2
LP	32 kHz ⁽¹⁾	15 pF	15 pF
XT	100 kHz	15-30 pF	200-300 pF
	200 kHz	15-30 pF	100-200 pF
	455 kHz	15-30 pF	15-100 pF
	1 MHz	15-30 pF	15-30 pF
	2 MHz	15 pF	15 pF
	4 MHz	15 pF	15 pF
HS	4 MHz	15 pF	15 pF
	8 MHz	15 pF	15 pF
	20 MHz	15 pF	15 pF

Note 1: For VDD > 4.5V, C1 = C2 \approx 30 pF is recommended.

These values are for design guidance only. Rs may be required in HS mode as well as XT mode to avoid overdriving crystals with low drive level specification. Since each crystal has its own characteristics, the user should consult the crystal manufacturer for appropriate values of external components.

Note: If you change from this device to another device, please verify oscillator characteristics in your application.

4.3 External Crystal Oscillator Circuit

Either a prepackaged oscillator or a simple oscillator circuit with TTL gates can be used as an external crystal oscillator circuit. Prepackaged oscillators provide a wide operating range and better stability. A well-designed crystal oscillator will provide good performance with TTL gates. Two types of crystal oscillator circuits can be used: one with parallel resonance, or one with series resonance.

Figure 4-3 shows an implementation example of a parallel resonant oscillator circuit. The circuit is designed to use the fundamental frequency of the crystal. The 74AS04 inverter performs the 180-degree phase shift that a parallel oscillator requires. The 4.7 k Ω resistor provides the negative feedback for stability. The 10 k Ω potentiometers bias the 74AS04 in the linear region. This circuit could be used for external oscillator designs.

FIGURE 4-3: EXAMPLE OF EXTERNAL PARALLEL RESONANT

CRYSTAL OSCILLATOR
CIRCUIT (USING XT, HS
OR LP OSCILLATOR
MODE)

+5V To Other Devices

10K 4.7K 74AS04 PIC16C5X

74AS04 Open OSC2

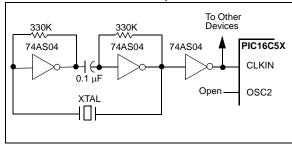
XTAL

20 pF = 20 pF

Figure 4-4 shows a series resonant oscillator circuit. This circuit is also designed to use the fundamental frequency of the crystal. The inverter performs a 180-degree phase shift in a series resonant oscillator circuit. The 330 $k\Omega$ resistors provide the negative feedback to bias the inverters in their linear region.

FIGURE 4-4:

EXAMPLE OF EXTERNAL SERIES RESONANT CRYSTAL OSCILLATOR CIRCUIT (USING XT, HS OR LP OSCILLATOR MODE)



4.4 RC Oscillator

For timing insensitive applications, the RC device option offers additional cost savings. The RC oscillator frequency is a function of the supply voltage, the resistor (REXT) and capacitor (CEXT) values, and the operating temperature. In addition to this, the oscillator frequency will vary from unit to unit due to normal process parameter variation. Furthermore, the difference in lead frame capacitance between package types will also affect the oscillation frequency, especially for low CEXT values. The user also needs to take into account variation due to tolerance of external R and C components used.

Figure 4-5 shows how the R/C combination is connected to the PIC16C5X. For REXT values below 2.2 k Ω , the oscillator operation may become unstable, or stop completely. For very high REXT values (e.g., 1 M Ω) the oscillator becomes sensitive to noise, humidity and leakage. Thus, we recommend keeping REXT between 3 k Ω and 100 k Ω .

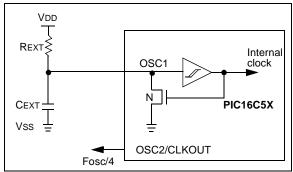
Although the oscillator will operate with no external capacitor (CEXT = 0 pF), we recommend using values above 20 pF for noise and stability reasons. With no or small external capacitance, the oscillation frequency can vary dramatically due to changes in external capacitances, such as PCB trace capacitance or package lead frame capacitance.

The Electrical Specifications sections show RC frequency variation from part to part due to normal process variation. The variation is larger for larger R (since leakage current variation will affect RC frequency more for large R) and for smaller C (since variation of input capacitance will affect RC frequency more).

Also, see the Electrical Specifications sections for variation of oscillator frequency due to VDD for given REXT/CEXT values as well as frequency variation due to operating temperature for given R, C, and VDD values.

The oscillator frequency, divided by 4, is available on the OSC2/CLKOUT pin, and can be used for test purposes or to synchronize other logic.

FIGURE 4-5: RC OSCILLATOR MODE



Note: If you change from this device to another device, please verify oscillator characteristics in your application.

NOTES:

5.0 RESET

PIC16C5X devices may be RESET in one of the following ways:

- Power-On Reset (POR)
- MCLR Reset (normal operation)
- MCLR Wake-up Reset (from SLEEP)
- WDT Reset (normal operation)
- WDT Wake-up Reset (from SLEEP)

Table 5-1 shows these RESET conditions for the PCL and STATUS registers.

Some registers are not affected in any RESET condition. Their status is unknown on POR and unchanged in any other RESET. Most other registers are reset to a "RESET state" on Power-On Reset (POR), MCLR or WDT Reset. A MCLR or WDT wake-up from SLEEP also results in a device RESET, and not a continuation of operation before SLEEP.

The TO and PD bits (STATUS <4:3>) are set or cleared depending on the different RESET conditions (Table 5-1). These bits may be used to determine the nature of the RESET.

Table 5-3 lists a full description of RESET states of all registers. Figure 5-1 shows a simplified block diagram of the On-chip Reset circuit.

TABLE 5-1: STATUS BITS AND THEIR SIGNIFICANCE

Condition	TO	PD
Power-On Reset	1	1
MCLR Reset (normal operation)	u	u
MCLR Wake-up (from SLEEP)	1	0
WDT Reset (normal operation)	0	1
WDT Wake-up (from SLEEP)	0	0

Legend: u = unchanged, x = unknown, -= unimplemented read as '0'.

TABLE 5-2: SUMMARY OF REGISTERS ASSOCIATED WITH RESET

Address	Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Value on POR	Value on MCLR and WDT Reset
03h	STATUS	PA2	PA1	PA0	TO	PD	Z	DC	С	0001 1xxx	000q quuu

Legend: u = unchanged, x = unknown, q = see Table 5-1 for possible values.

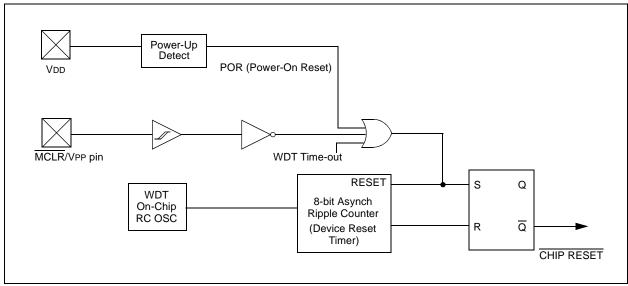
TABLE 5-3: RESET CONDITIONS FOR ALL REGISTERS

Register	Address	Power-On Reset	MCLR or WDT Reset
W	N/A	xxxx xxxx	uuuu uuuu
TRIS	N/A	1111 1111	1111 1111
OPTION	N/A	11 1111	11 1111
INDF	00h	xxxx xxxx	uuuu uuuu
TMR0	01h	xxxx xxxx	uuuu uuuu
PCL	02h	1111 1111	1111 1111
STATUS	03h	0001 1xxx	000q quuu
FSR ⁽¹⁾	04h	1xxx xxxx	luuu uuuu
PORTA	05h	xxxx	uuuu
PORTB	06h	xxxx xxxx	uuuu uuuu
PORTC ⁽²⁾	07h	xxxx xxxx	uuuu uuuu
General Purpose Register Files	07-7Fh	xxxx xxxx	uuuu uuuu

Legend: x = unknown u = unchanged - = unimplemented, read as '0' q = see tables in Table 5-1 for possible values.

2: General purpose register file on PIC16C54/CR54/C56/CR56/C58/CR58.

FIGURE 5-1: SIMPLIFIED BLOCK DIAGRAM OF ON-CHIP RESET CIRCUIT



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Note 1: These values are valid for PIC16C57/CR57/C58/CR58. For the PIC16C54/CR54/C55/C56/CR56, the value on RESET is 111x xxxx and for MCLR and WDT Reset, the value is 111u uuuu.

5.1 Power-On Reset (POR)

The PIC16C5X family incorporates on-chip Power-On Reset (POR) circuitry which provides an internal chip RESET for most power-up situations. To use this feature, the user merely ties the $\overline{\text{MCLR}}/\text{VPP}$ pin to VDD. A simplified block diagram of the on-chip Power-On Reset circuit is shown in Figure 5-1.

The Power-On Reset circuit and the Device Reset Timer (Section 5.2) circuit are closely related. On power-up, the RESET latch is set and the DRT is RESET. The DRT timer begins counting once it detects MCLR to be high. After the time-out period, which is typically 18 ms, it will RESET the reset latch and thus end the on-chip RESET signal.

A power-up example where \overline{MCLR} is not tied to VDD is shown in Figure 5-3. VDD is allowed to rise and stabilize before bringing \overline{MCLR} high. The chip will actually come out of reset TDRT msec after \overline{MCLR} goes high.

In Figure 5-4, the on-chip Power-On Reset feature is being used (MCLR and VDD are tied together). The VDD is stable before the start-up timer times out and there is no problem in getting a proper RESET. However, Figure 5-5 depicts a problem situation where VDD rises too slowly. The time between when the DRT senses a high on the MCLR/VPP pin, and when the MCLR/VPP pin (and VDD) actually reach their full value, is too long. In this situation, when the start-up timer times out, VDD has not reached the VDD (min) value and the chip is, therefore, not guaranteed to function correctly. For such situations, we recommend that external RC circuits be used to achieve longer POR delay times (Figure 5-2).

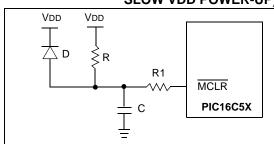
Note: When the device starts normal operation (exits the RESET condition), device operating parameters (voltage, frequency, temperature, etc.) must be met to ensure operation. If these conditions are not met, the device must be held in RESET until the

For more information on PIC16C5X POR, see *Power-Up Considerations* - AN522 in the <u>Embedded Control Handbook</u>.

operating conditions are met.

The POR circuit does not produce an internal RESET when VDD declines.

FIGURE 5-2: EXTERNAL POWER-ON RESET CIRCUIT (FOR SLOW VDD POWER-UP)



- External Power-On Reset circuit is required only if VDD power-up is too slow. The diode D helps discharge the capacitor quickly when VDD powers down.
- R < 40 k Ω is recommended to make sure that voltage drop across R does not violate the device electrical specification.
- R1 = 100Ω to 1 k Ω will limit any current flowing into $\overline{\text{MCLR}}$ from external capacitor C in the event of $\overline{\text{MCLR}}$ pin breakdown due to Electrostatic Discharge (ESD) or Electrical Overstress (EOS).

FIGURE 5-3: TIME-OUT SEQUENCE ON POWER-UP (MCLR NOT TIED TO VDD)

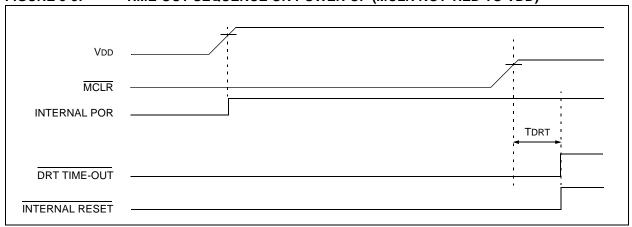


FIGURE 5-4: TIME-OUT SEQUENCE ON POWER-UP (MCLR TIED TO VDD): FAST VDD RISE TIME

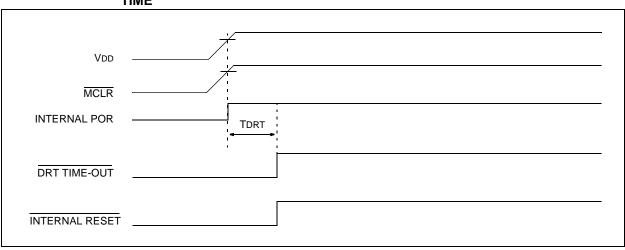
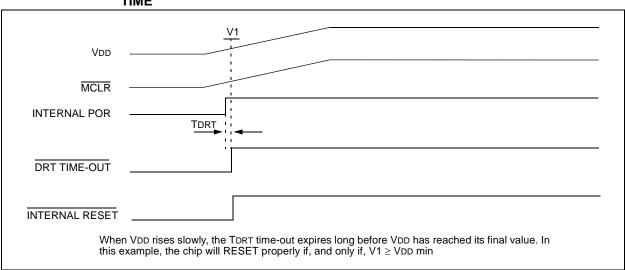


FIGURE 5-5: TIME-OUT SEQUENCE ON POWER-UP (MCLR TIED TO VDD): SLOW VDD RISE TIME



5.2 Device Reset Timer (DRT)

The Device Reset Timer (DRT) provides an 18 ms nominal time-out on RESET regardless of Oscillator mode used. The DRT operates on an internal RC oscillator. The processor is kept in RESET as long as the DRT is active. The DRT delay allows VDD to rise above VDD min., and for the oscillator to stabilize.

Oscillator circuits based on crystals or ceramic resonators require a certain time after power-up to establish a stable oscillation. The on-chip DRT keeps the device in a RESET condition for approximately 18 ms after the voltage on the MCLR/VPP pin has reached a logic high (VIH) level. Thus, external RC networks connected to the MCLR input are not required in most cases, allowing for savings in cost-sensitive and/or space restricted applications.

The Device Reset time delay will vary from chip to chip due to VDD, temperature, and process variation. See AC parameters for details.

The DRT will also be triggered upon a Watchdog Timer time-out. This is particularly important for applications using the WDT to wake the PIC16C5X from SLEEP mode automatically.

5.3 Reset on Brown-Out

A brown-out is a condition where device power (VDD) dips below its minimum value, but not to zero, and then recovers. The device should be RESET in the event of a brown-out.

To RESET PIC16C5X devices when a brown-out occurs, external brown-out protection circuits may be built, as shown in Figure 5-6, Figure 5-7 and Figure 5-8.

FIGURE 5-6: EXTERNAL BROWN-OUT PROTECTION CIRCUIT 1

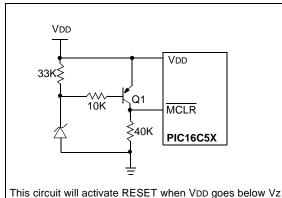
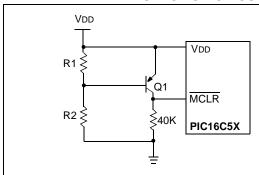


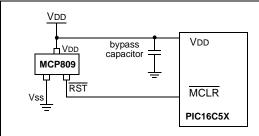
FIGURE 5-7: EXTERNAL BROWN-OUT PROTECTION CIRCUIT 2



This brown-out circuit is less expensive, although less accurate. Transistor Q1 turns off when VDD is below a certain level such that:

$$V_{DD} \bullet \frac{R1}{R1 + R2} = 0.7V$$

FIGURE 5-8: EXTERNAL BROWN-OUT PROTECTION CIRCUIT 3



This brown-out protection circuit employs Microchip Technology's MCP809 microcontroller supervisor. The MCP8XX and MCP1XX families of supervisors provide push-pull and open collector outputs with both "active high and active low" RESET pins. There are 7 different trip point selections to accommodate 5V and 3V systems.

+ 0.7V (where Vz = Zener voltage).

NOTES:

6.0 MEMORY ORGANIZATION

PIC16C5X memory is organized into program memory and data memory. For devices with more than 512 bytes of program memory, a paging scheme is used. Program memory pages are accessed using one or two STATUS Register bits. For devices with a data memory register file of more than 32 registers, a banking scheme is used. Data memory banks are accessed using the File Selection Register (FSR).

6.1 Program Memory Organization

The PIC16C54, PIC16CR54 and PIC16C55 have a 9-bit Program Counter (PC) capable of addressing a 512 x 12 program memory space (Figure 6-1). The PIC16C56 and PIC16CR56 have a 10-bit Program Counter (PC) capable of addressing a 1K x 12 program memory space (Figure 6-2). The PIC16CR57, PIC16C58 and PIC16CR58 have an 11-bit Program Counter capable of addressing a 2K x 12 program memory space (Figure 6-3). Accessing a location above the physically implemented address will cause a wraparound.

A NOP at the RESET vector location will cause a restart at location 000h. The RESET vector for the PIC16C54, PIC16CR54 and PIC16C55 is at 1FFh. The RESET vector for the PIC16C56 and PIC16CR56 is at 3FFh. The RESET vector for the PIC16C57, PIC16CR57, PIC16C58, and PIC16CR58 is at 7FFh. See Section 6.5 for additional information using CALL and GOTO instructions.

FIGURE 6-1: PIC16C54/CR54/C55
PROGRAM MEMORY MAP
AND STACK

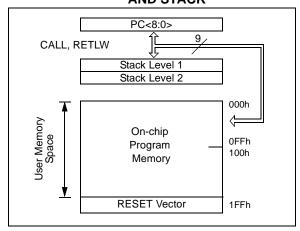


FIGURE 6-2: PIC16C56/CR56
PROGRAM MEMORY MAP
AND STACK

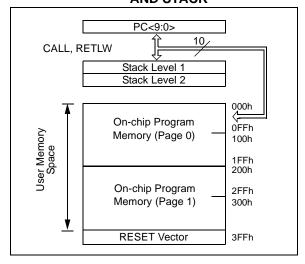
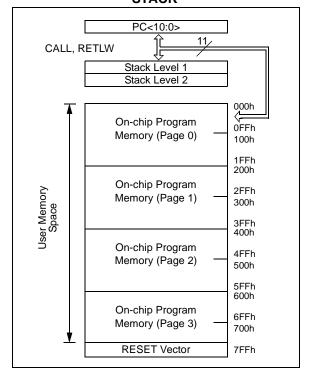


FIGURE 6-3: PIC16C57/CR57/C58/
CR58 PROGRAM
MEMORY MAP AND
STACK



6.2 Data Memory Organization

Data memory is composed of registers, or bytes of RAM. Therefore, data memory for a device is specified by its register file. The register file is divided into two functional groups: Special Function Registers and General Purpose Registers.

The Special Function Registers include the TMR0 register, the Program Counter (PC), the Status Register, the I/O registers (ports) and the File Select Register (FSR). In addition, Special Purpose Registers are used to control the I/O port configuration and prescaler options.

The General Purpose Registers are used for data and control information under command of the instructions.

For the PIC16C54, PIC16CR54, PIC16C56 and PIC16CR56, the register file is composed of 7 Special Function Registers and 25 General Purpose Registers (Figure 6-4).

For the PIC16C55, the register file is composed of 8 Special Function Registers and 24 General Purpose Registers.

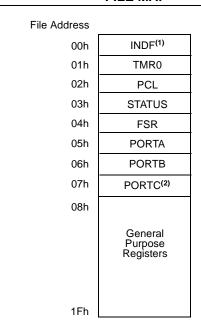
For the PIC16C57 and PIC16CR57, the register file is composed of 8 Special Function Registers, 24 General Purpose Registers and up to 48 additional General Purpose Registers that may be addressed using a banking scheme (Figure 6-5).

For the PIC16C58 and PIC16CR58, the register file is composed of 7 Special Function Registers, 25 General Purpose Registers and up to 48 additional General Purpose Registers that may be addressed using a banking scheme (Figure 6-6).

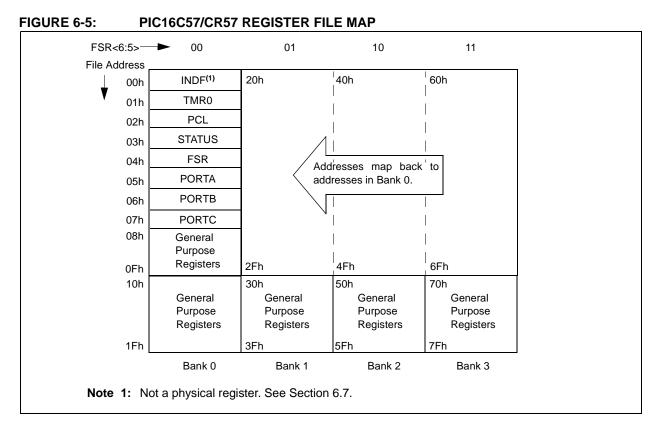
6.2.1 GENERAL PURPOSE REGISTER FILE

The register file is accessed either directly or indirectly through the File Select Register (FSR). The FSR Register is described in Section 6.7.

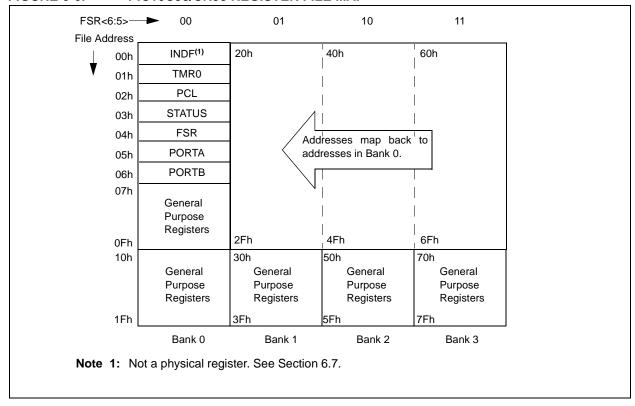
FIGURE 6-4: PIC16C54, PIC16CR54, PIC16C55, PIC16C56, PIC16CR56 REGISTER FILE MAP



- **Note 1:** Not a physical register. See Section 6.7.
 - **2:** PIC16C55 only, in all other devices this is implemented as a general purpose register.







6.2.2 SPECIAL FUNCTION REGISTERS

The Special Function Registers are registers used by the CPU and peripheral functions to control the operation of the device (Table 6-1).

The Special Registers can be classified into two sets. The Special Function Registers associated with the "core" functions are described in this section. Those related to the operation of the peripheral features are described in the section for each peripheral feature.

TABLE 6-1: SPECIAL FUNCTION REGISTER SUMMARY

Address	Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Value on Power-on Reset	Details on Page
N/A	TRIS	I/O Cont	/O Control Registers (TRISA, TRISB, TRISC)								35
N/A	OPTION	Contains	s control b	oits to con	figure Ti	mer0 and	Timer0/V	VDT pres	caler	11 1111	30
00h	INDF	Uses co	ntents of	FSR to ac	egister)	XXXX XXXX	32				
01h	TMR0	Timer0 N	Module R	egister		XXXX XXXX	38				
02h ⁽¹⁾	PCL	Low ord	Low order 8 bits of PC							1111 1111	31
03h	STATUS	PA2	PA1	PA0	TO	PD	Z	DC	С	0001 1xxx	29
04h	FSR	Indirect	Indirect data memory address pointer							1xxx xxxx ⁽³⁾	32
05h	PORTA	_	_	_	_	RA3	RA2	RA1	RA0	XXXX	35
06h	PORTB	RB7	RB6	RB5	RB4	RB3	RB2	RB1	RB0	XXXX XXXX	35
07h ⁽²⁾	PORTC	RC7	RC6	RC5	RC4	RC3	RC2	RC1	RC0	xxxx xxxx	35

Legend: x = unknown, u = unchanged, - = unimplemented, read as '0' (if applicable). Shaded cells = unimplemented or unused

Note: 1: The upper bute of the Program Counter is not directly accessible. See Section 6.5 for an explanation of how to access

Note 1: The upper byte of the Program Counter is not directly accessible. See Section 6.5 for an explanation of how to access these bits.

^{2:} File address 07h is a General Purpose Register on the PIC16C54, PIC16CR54, PIC16C56, PIC16CR56, PIC16C58 and PIC16CR58.

^{3:} These values are valid for PIC16C57/CR57/C58/CR58. For the PIC16C54/CR54/C55/C56/CR56, the value on RESET is 111x xxxx and for MCLR and WDT Reset, the value is 111u uuuu.

6.3 STATUS Register

This register contains the arithmetic status of the ALU, the RESET status and the page preselect bits for program memories larger than 512 words.

The STATUS Register can be the destination for any instruction, as with any other register. If the STATUS Register is the destination for an instruction that affects the Z, DC or C bits, then the write to these three bits is disabled. These bits are set or cleared according to the device logic. Furthermore, the $\overline{\text{TO}}$ and $\overline{\text{PD}}$ bits are not

writable. Therefore, the result of an instruction with the STATUS Register as destination may be different than intended.

For example, CLRF STATUS will clear the upper three bits and set the Z bit. This leaves the STATUS Register as 000u uluu (where u = unchanged).

It is recommended, therefore, that only BCF, BSF and MOVWF instructions be used to alter the STATUS Register because these instructions do not affect the Z, DC or C bits from the STATUS Register. For other instructions which do affect STATUS Bits, see Section 10.0, Instruction Set Summary.

REGISTER 6-1: STATUS REGISTER (ADDRESS: 03h)

R/W-0	R/W-0	R/W-0	R-1	R-1	R/W-x	R/W-x	R/W-x	
PA2	PA1	PA0	TO	PD	Z	DC	С	
bit 7							bit 0	

bit 7: **PA2**: This bit unused at this time.

Use of the PA2 bit as a general purpose read/write bit is not recommended, since this may affect upward compatibility with future products.

bit 6-5: PA<1:0>: Program page preselect bits (PIC16C56/CR56)(PIC16C57/CR57)(PIC16C58/CR58)

00 = Page 0 (000h - 1FFh) - PIC16C56/CR56, PIC16C57/CR57, PIC16C58/CR58

01 = Page 1 (200h - 3FFh) - PIC16C56/CR56, PIC16C57/CR57, PIC16C58/CR58

10 = Page 2 (400h - 5FFh) - PIC16C57/CR57, PIC16C58/CR58

11 = Page 3 (600h - 7FFh) - PIC16C57/CR57, PIC16C58/CR58

Each page is 512 words.

Using the PA<1:0> bits as general purpose read/write bits in devices which do not use them for program page preselect is not recommended since this may affect upward compatibility with future products.

bit 4: **TO**: Time-out bit

1 = After power-up, CLRWDT instruction, or SLEEP instruction

0 = A WDT time-out occurred

bit 3: **PD**: Power-down bit

1 = After power-up or by the CLRWDT instruction

0 = By execution of the SLEEP instruction

bit 2: Z: Zero bit

1 = The result of an arithmetic or logic operation is zero

0 = The result of an arithmetic or logic operation is not zero

bit 1: **DC**: Digit carry/borrow bit (for ADDWF and SUBWF instructions)

ADDWF

1 = A carry from the 4th low order bit of the result occurred

0 = A carry from the 4th low order bit of the result did not occur

SUBWF

1 = A borrow from the 4th low order bit of the result did not occur

0 = A borrow from the 4th low order bit of the result occurred

bit 0: C: Carry/borrow bit (for ADDWF, SUBWF and RRF, RLF instructions)

ADDWF SUBWF RRF or RLF

1 = A carry occurred 1 = A borrow did not occur

0 = A carry did not occur 0 = A borrow occurred

Legend:

R = Readable bit W = Writable bit U = Unimplemented bit, read as '0'

-n = Value at POR 1 = bit is set 0 = bit is cleared x = bit is unknown

Loaded with LSb or MSb, respectively

6.4 OPTION Register

The OPTION Register is a 6-bit wide, write-only register which contains various control bits to configure the Timer0/WDT prescaler and Timer0.

By executing the OPTION instruction, the contents of the W Register will be transferred to the OPTION Register. A RESET sets the OPTION<5:0> bits.

REGISTER 6-2: OPTION REGISTER

U-0	U-0	W-1	W-1	W-1	W-1	W-1	W-1
_	_	T0CS	TOSE	PSA	PS2	PS1	PS0
bit 7							bit 0

bit 7-6: Unimplemented: Read as '0'

bit 5: Tocs: Timer0 clock source select bit

1 = Transition on T0CKI pin

0 = Internal instruction cycle clock (CLKOUT)

bit 4: **T0SE**: Timer0 source edge select bit

1 = Increment on high-to-low transition on T0CKI pin0 = Increment on low-to-high transition on T0CKI pin

bit 3: **PSA**: Prescaler assignment bit

1 = Prescaler assigned to the WDT0 = Prescaler assigned to Timer0

bit 2-0: **PS<2:0>**: Prescaler rate select bits

Bit Value	Timer0 Rate	WDT Rate
000	1:2	1:1
001	1:4	1:2
010	1:8	1:4
011	1:16	1:8
100	1:32	1:16
101	1:64	1:32
110	1 : 128	1:64
111	1:256	1:128

Legend:

R = Readable bit W = Writable bit U = Unimplemented bit, read as '0'

-n = Value at POR 1 = bit is set 0 = bit is cleared x = bit is unknown

6.5 Program Counter

As a program instruction is executed, the Program Counter (PC) will contain the address of the next program instruction to be executed. The PC value is increased by one, every instruction cycle, unless an instruction changes the PC.

For a GOTO instruction, bits 8:0 of the PC are provided by the GOTO instruction word. The PC Latch (PCL) is mapped to PC<7:0> (Figure 6-7, Figure 6-8 and Figure 6-9).

For the PIC16C56, PIC16CR56, PIC16C57, PIC16CR57, PIC16C58 and PIC16CR58, a page number must be supplied as well. Bit5 and bit6 of the STATUS Register provide page information to bit9 and bit10 of the PC (Figure 6-8 and Figure 6-9).

For a CALL instruction, or any instruction where the PCL is the destination, bits 7:0 of the PC again are provided by the instruction word. However, PC<8> does not come from the instruction word, but is always cleared (Figure 6-7 and Figure 6-8).

Instructions where the PCL is the destination, or modify PCL instructions, include MOVWF PCL, ADDWF PCL, and BSF PCL, 5.

For the PIC16C56, PIC16CR56, PIC16C57, PIC16CR57, PIC16C58 and PIC16CR58, a page number again must be supplied. Bit5 and bit6 of the STATUS Register provide page information to bit9 and bit10 of the PC (Figure 6-8 and Figure 6-9).

Note: Because PC<8> is cleared in the CALL instruction, or any modify PCL instruction, all subroutine calls or computed jumps are limited to the first 256 locations of any program memory page (512 words long).

FIGURE 6-7: LOADING OF PC
BRANCH INSTRUCTIONS
- PIC16C54, PIC16CR54,

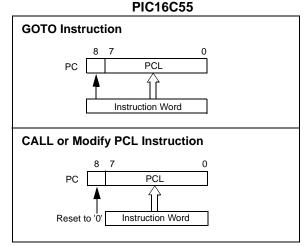


FIGURE 6-8: LOADING OF PC
BRANCH INSTRUCTIONS
- PIC16C56/PIC16CR56

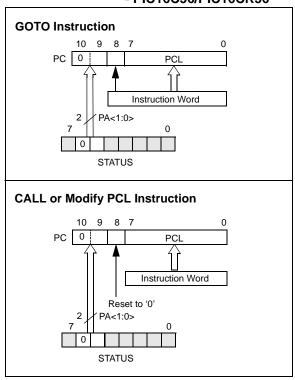
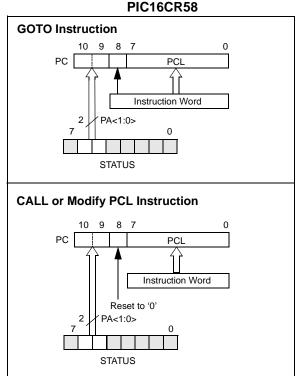


FIGURE 6-9: LOADING OF PC
BRANCH INSTRUCTIONS
- PIC16C57/PIC16CR57,
AND PIC16C58/



6.5.1 PAGING CONSIDERATIONS – PIC16C56/CR56, PIC16C57/CR57 AND PIC16C58/CR58

If the Program Counter is pointing to the last address of a selected memory page, when it increments it will cause the program to continue in the next higher page. However, the page preselect bits in the STATUS Register will not be updated. Therefore, the next GOTO, CALL or modify PCL instruction will send the program to the page specified by the page preselect bits (PA0 or PA<1:0>).

For example, a NOP at location 1FFh (page 0) increments the PC to 200h (page 1). A GOTO xxx at 200h will return the program to address xxh on page 0 (assuming that PA<1:0> are clear).

To prevent this, the page preselect bits must be updated under program control.

6.5.2 EFFECTS OF RESET

The Program Counter is set upon a RESET, which means that the PC addresses the last location in the last page (i.e., the RESET vector).

The STATUS Register page preselect bits are cleared upon a RESET, which means that page 0 is preselected.

Therefore, upon a RESET, a GOTO instruction at the RESET vector location will automatically cause the program to jump to page 0.

6.6 Stack

PIC16C5X devices have a 10-bit or 11-bit wide, two-level hardware push/pop stack.

A CALL instruction will push the current value of stack 1 into stack 2 and then push the current program counter value, incremented by one, into stack level 1. If more than two sequential CALL's are executed, only the most recent two return addresses are stored.

A RETLW instruction will pop the contents of stack level 1 into the program counter and then copy stack level 2 contents into level 1. If more than two sequential RETLW's are executed, the stack will be filled with the address previously stored in level 2. Note that the W Register will be loaded with the literal value specified in the instruction. This is particularly useful for the implementation of data look-up tables within the program memory.

For the RETLW instruction, the PC is loaded with the Top of Stack (TOS) contents. All of the devices covered in this data sheet have a two-level stack. The stack has the same bit width as the device PC, therefore, paging is not an issue when returning from a subroutine.

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6.7 Indirect Data Addressing; INDF and FSR Registers

The INDF Register is not a physical register. Addressing INDF actually addresses the register whose address is contained in the FSR Register (FSR is a *pointer*). This is indirect addressing.

EXAMPLE 6-1: INDIRECT ADDRESSING

- Register file 08 contains the value 10h
- Register file 09 contains the value 0Ah
- · Load the value 08 into the FSR Register
- A read of the INDF Register will return the value of 10h
- Increment the value of the FSR Register by one (FSR = 09h)
- A read of the INDF register now will return the value of 0Ah.

Reading INDF itself indirectly (FSR = 0) will produce 00h. Writing to the INDF Register indirectly results in a no-operation (although STATUS bits may be affected).

A simple program to clear RAM locations 10h-1Fh using indirect addressing is shown in Example 6-2.

EXAMPLE 6-2: HOW TO CLEAR RAM USING INDIRECT ADDRESSING

	MOVLW	H'10'	;initialize pointer
	MOVWF	FSR	; to RAM
NEXT	CLRF	INDF	;clear INDF Register
	INCF	FSR,F	;inc pointer
	BTFSC	FSR,4	;all done?
	GOTO	NEXT	;NO, clear next
CONTINUE			
	:		;YES, continue

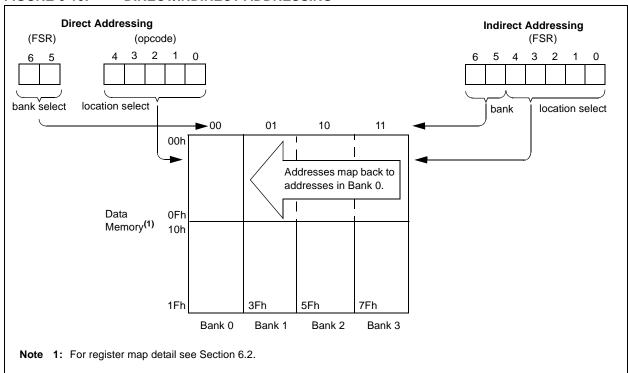
The FSR is either a 5-bit (PIC16C54, PIC16CR54, PIC16C55, PIC16C56, PIC16CR56) or 7-bit (PIC16C57, PIC16CR57, PIC16CR58, PIC16CR58) wide register. It is used in conjunction with the INDF Register to indirectly address the data memory area.

The FSR<4:0> bits are used to select data memory addresses 00h to 1Fh.

PIC16C54, PIC16CR54, PIC16C55, PIC16C56, PIC16CR56: These do not use banking. FSR<6:5> bits are unimplemented and read as '1's.

PIC16C57, PIC16CR57, PIC16C58, PIC16CR58: FSR<6:5> are the bank select bits and are used to select the bank to be addressed (00 = bank 0, 01 = bank 1, 10 = bank 2, 11 = bank 3).

FIGURE 6-10: DIRECT/INDIRECT ADDRESSING



NOTES:

7.0 I/O PORTS

As with any other register, the I/O Registers can be written and read under program control. However, read instructions (e.g., MOVF PORTB, W) always read the I/O pins independent of the pin's input/output modes. On RESET, all I/O ports are defined as input (inputs are at hi-impedance) since the I/O control registers (TRISA, TRISB, TRISC) are all set.

7.1 PORTA

PORTA is a 4-bit I/O Register. Only the low order 4 bits are used (RA<3:0>). Bits 7-4 are unimplemented and read as '0's.

7.2 PORTB

PORTB is an 8-bit I/O Register (PORTB<7:0>).

7.3 PORTC

PORTC is an 8-bit I/O Register for PIC16C55, PIC16C57 and PIC16CR57.

PORTC is a General Purpose Register for PIC16C54, PIC16CR54, PIC16C56, PIC16CR56, PIC16C58 and PIC16CR58.

7.4 TRIS Registers

The Output Driver Control Registers are loaded with the contents of the W Register by executing the TRIS f instruction. A '1' from a TRIS Register bit puts the corresponding output driver in a hi-impedance (input) mode. A '0' puts the contents of the output data latch on the selected pins, enabling the output buffer.

Note: A read of the ports reads the pins, not the output data latches. That is, if an output driver on a pin is enabled and driven high, but the external system is holding it low, a read of the port will indicate that the pin is low.

The TRIS Registers are "write-only" and are set (output drivers disabled) upon RESET.

7.5 I/O Interfacing

The equivalent circuit for an I/O port pin is shown in Figure 7-1. All ports may be used for both input and output operation. For input operations these ports are non-latching. Any input must be present until read by an input instruction (e.g., MOVF PORTB, W). The outputs are latched and remain unchanged until the output latch is rewritten. To use a port pin as output, the corresponding direction control bit (in TRISA, TRISB, TRISC) must be cleared (= 0). For use as an input, the corresponding TRIS bit must be set. Any I/O pin can be programmed individually as input or output.

FIGURE 7-1: EQUIVALENT CIRCUIT FOR A SINGLE I/O PIN

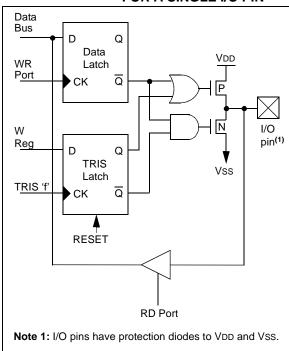


TABLE 7-1: SUMMARY OF PORT REGISTERS

Address	Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Value on Power-On Reset	Value on MCLR and WDT Reset
N/A	TRIS		I/O Control Registers (TRISA, TRISB, TRISC)							1111 1111	1111 1111
05h	PORTA	_	_	_	_	RA3	RA2	RA1	RA0	xxxx	uuuu
06h	PORTB	RB7	RB6	RB5	RB4	RB3	RB2	RB1	RB0	xxxx xxxx	uuuu uuuu
07h	PORTC	RC7	RC6	RC5	RC4	RC3	RC2	RC1	RC0	xxxx xxxx	uuuu uuuu

Legend: x = unknown, u = unchanged, — = unimplemented, read as '0', Shaded cells = unimplemented, read as '0'

7.6 I/O Programming Considerations

7.6.1 BI-DIRECTIONAL I/O PORTS

Some instructions operate internally as read followed by write operations. The BCF and BSF instructions, for example, read the entire port into the CPU, execute the bit operation and re-write the result. Caution must be used when these instructions are applied to a port where one or more pins are used as input/outputs. For example, a BSF operation on bit5 of PORTB will cause all eight bits of PORTB to be read into the CPU, bit5 to be set and the PORTB value to be written to the output latches. If another bit of PORTB is used as a bi-directional I/O pin (say bit0) and it is defined as an input at this time, the input signal present on the pin itself would be read into the CPU and rewritten to the data latch of this particular pin, overwriting the previous content. As long as the pin stays in the Input mode, no problem occurs. However, if bit0 is switched into Output mode later on, the content of the data latch may now be unknown.

Example 7-1 shows the effect of two sequential readmodify-write instructions (e.g., \mbox{BCF} , \mbox{BSF} , etc.) on an I/O port.

A pin actively outputting a high or a low should not be driven from external devices at the same time in order to change the level on this pin ("wired-or", "wired-and"). The resulting high output currents may damage the chip.

EXAMPLE 7-1: READ-MODIFY-WRITE INSTRUCTIONS ON AN I/O PORT

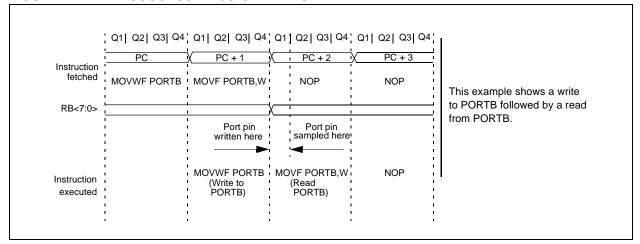
```
; Initial PORT Settings
; PORTB<7:4> Inputs
; PORTB<3:0> Outputs
;PORTB<7:6> have external pull-ups and are
; not connected to other circuitry
                    PORT latch PORT pins
  BCF
        PORTB, 7
                   ;01pp pppp
                                 11pp pppp
  BCF
        PORTB. 6
                   ;10pp pppp
                                 11pp pppp
 MOVLW H'3F'
                    ;
  TRIS
        PORTB
                   ;10pp pppp
                                 10pp pppp
; Note that the user may have expected the pin
; values to be 00pp pppp. The 2nd BCF caused
```

7.6.2 SUCCESSIVE OPERATIONS ON I/O PORTS

; RB7 to be latched as the pin value (High).

The actual write to an I/O port happens at the end of an instruction cycle, whereas for reading, the data must be valid at the beginning of the instruction cycle (Figure 7-2). Therefore, care must be exercised if a write followed by a read operation is carried out on the same I/O port. The sequence of instructions should allow the pin voltage to stabilize (load dependent) before the next instruction, which causes that file to be read into the CPU, is executed. Otherwise, the previous state of that pin may be read into the CPU rather than the new state. When in doubt, it is better to separate these instructions with a NOP or another instruction not accessing this I/O port.





8.0 TIMERO MODULE AND TMRO REGISTER

The Timer0 module has the following features:

- 8-bit timer/counter register, TMR0
 - Readable and writable
- 8-bit software programmable prescaler
- · Internal or external clock select
 - Edge select for external clock

Figure 8-1 is a simplified block diagram of the Timer0 module, while Figure 8-2 shows the electrical structure of the Timer0 input.

Timer mode is selected by clearing the TOCS bit (OPTION<5>). In Timer mode, the Timer0 module will increment every instruction cycle (without prescaler). If TMR0 register is written, the increment is inhibited for the following two cycles (Figure 8-3 and Figure 8-4). The user can work around this by writing an adjusted value to the TMR0 register.

Counter mode is selected by setting the T0CS bit (OPTION<5>). In this mode, Timer0 will increment either on every rising or falling edge of pin T0CKI. The incrementing edge is determined by the source edge select bit T0SE (OPTION<4>). Clearing the T0SE bit selects the rising edge. Restrictions on the external clock input are discussed in detail in Section 8.1.

Note: The prescaler may be used by either the Timer0 module or the Watchdog Timer, but not both.

The prescaler assignment is controlled in software by the control bit PSA (OPTION<3>). Clearing the PSA bit will assign the prescaler to Timer0. The prescaler is not readable or writable. When the prescaler is assigned to the Timer0 module, prescale values of 1:2, 1:4,..., 1:256 are selectable. Section 8.2 details the operation of the prescaler.

A summary of registers associated with the Timer0 module is found in Table 8-1.

FIGURE 8-1: TIMERO BLOCK DIAGRAM

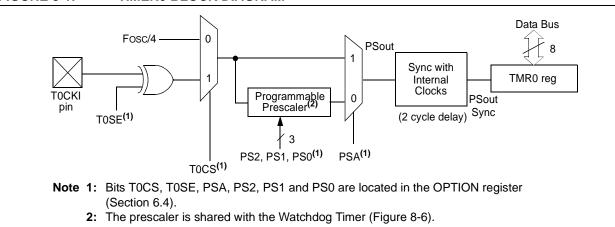


FIGURE 8-2: ELECTRICAL STRUCTURE OF TOCKI PIN

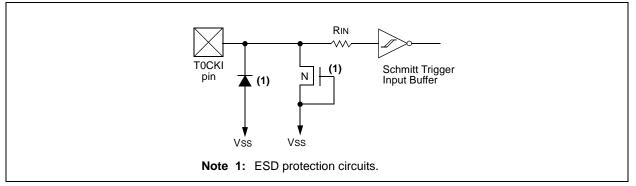


FIGURE 8-3: TIMER0 TIMING: INTERNAL CLOCK/NO PRESCALER

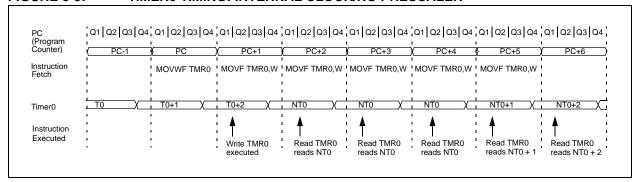


FIGURE 8-4: TIMERO TIMING: INTERNAL CLOCK/PRESCALER 1:2

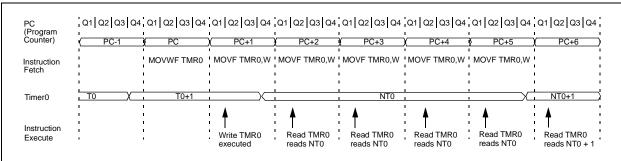


TABLE 8-1: REGISTERS ASSOCIATED WITH TIMERO

Address	Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Value on Power-on Reset	Value on MCLR and WDT Reset
01h	TMR0	Timer0 -	imer0 - 8-bit real-time clock/counter					xxxx xxxx	uuuu uuuu		
N/A	OPTION	_	_	T0CS	T0SE	PSA	PS2	PS1	PS0	11 1111	11 1111

Legend: x = unknown, u = unchanged, - = unimplemented. Shaded cells not used by Timer0.

8.1 Using Timer0 with an External Clock

When an external clock input is used for Timer0, it must meet certain requirements. The external clock requirement is due to internal phase clock (Tosc) synchronization. Also, there is a delay in the actual incrementing of Timer0 after synchronization.

8.1.1 EXTERNAL CLOCK SYNCHRONIZATION

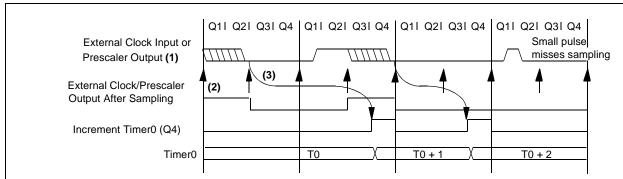
When no prescaler is used, the external clock input is the same as the prescaler output. The synchronization of T0CKI with the internal phase clocks is accomplished by sampling the prescaler output on the Q2 and Q4 cycles of the internal phase clocks (Figure 8-5). Therefore, it is necessary for T0CKI to be high for at least 2Tosc (and a small RC delay of 20 ns) and low for at least 2Tosc (and a small RC delay of 20 ns). Refer to the electrical specification of the desired device.

When a prescaler is used, the external clock input is divided by the asynchronous ripple counter-type prescaler so that the prescaler output is symmetrical. For the external clock to meet the sampling requirement, the ripple counter must be taken into account. Therefore, it is necessary for TOCKI to have a period of at least 4Tosc (and a small RC delay of 40 ns) divided by the prescaler value. The only requirement on TOCKI high and low time is that they do not violate the minimum pulse width requirement of 10 ns. Refer to parameters 40, 41 and 42 in the electrical specification of the desired device.

8.1.2 TIMERO INCREMENT DELAY

Since the prescaler output is synchronized with the internal clocks, there is a small delay from the time the external clock edge occurs to the time the Timer0 module is actually incremented. Figure 8-5 shows the delay from the external clock edge to the timer incrementing.

FIGURE 8-5: TIMERO TIMING WITH EXTERNAL CLOCK



- **Note 1:** External clock if no prescaler selected, prescaler output otherwise.
 - 2: The arrows indicate the points in time where sampling occurs.
 - 3: Delay from clock input change to Timer0 increment is 3Tosc to 7Tosc (duration of Q = Tosc). Therefore, the error in measuring the interval between two edges on Timer0 input = \pm 4Tosc max.

8.2 **Prescaler**

An 8-bit counter is available as a prescaler for the Timer0 module, or as a postscaler for the Watchdog Timer (WDT), respectively (Section 9.2.1). For simplicity, this counter is being referred to as "prescaler" throughout this data sheet. Note that the prescaler may be used by either the Timer0 module or the WDT, but not both. Thus, a prescaler assignment for the Timer0 module means that there is no prescaler for the WDT, and vice-versa.

The PSA and PS<2:0> bits (OPTION<3:0>) determine prescaler assignment and prescale ratio.

When assigned to the Timer0 module, all instructions writing to the TMR0 register (e.g., CLRF 1, MOVWF 1, BSF 1,x, etc.) will clear the prescaler. When assigned to WDT, a CLRWDT instruction will clear the prescaler along with the WDT. The prescaler is neither readable nor writable. On a RESET, the prescaler contains all '0's.

8.2.1 SWITCHING PRESCALER **ASSIGNMENT**

The prescaler assignment is fully under software control (i.e., it can be changed "on the fly" during program execution). To avoid an unintended device RESET, the following instruction sequence (Example 8-1) must be executed when changing the prescaler assignment from Timer0 to the WDT.

EXAMPLE 8-1: CHANGING PRESCALER (TIMER0→WDT)

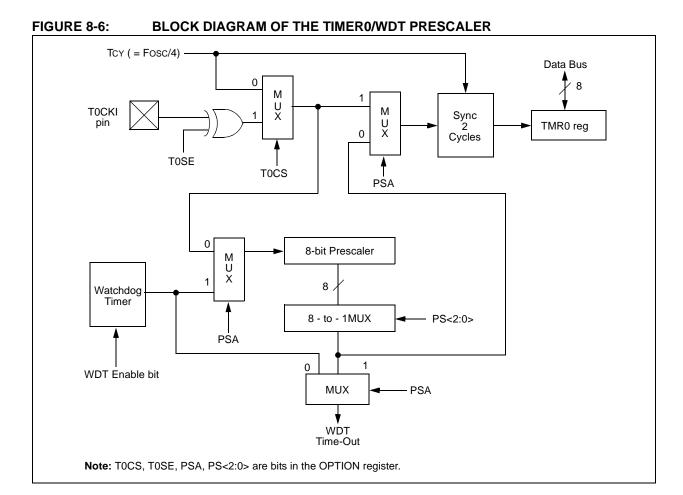
CLRWDT ;Clear WDT ;Clear TMR0 & Prescaler CLRF TMR0 MOVIW B'00xx1111' ;Last 3 instructions in this example OPTION ; are required only if ;desired CLRWDT ;PS<2:0> are 000 or ;001 MOVLW B'00xx1xxx' ;Set Prescaler to OPTION ;desired WDT rate

To change prescaler from the WDT to the Timer0 module, use the sequence shown in Example 8-2. This sequence must be used even if the WDT is disabled. A CLRWDT instruction should be executed before switching the prescaler.

EXAMPLE 8-2: CHANGING PRESCALER (WDT→TIMER0)

CLRWDT ;Clear WDT and ;prescaler ;Select TMR0, new MOVLW B'xxxx0xxx' ;prescale value and ; clock source

OPTION



NOTES:

9.0 SPECIAL FEATURES OF THE CPU

What sets a microcontroller apart from other processors are special circuits that deal with the needs of real-time applications. The PIC16C5X family of microcontrollers have a host of such features intended to maximize system reliability, minimize cost through elimination of external components, provide power saving operating modes and offer code protection. These features are:

- Oscillator Selection (Section 4.0)
- RESET (Section 5.0)
- Power-On Reset (Section 5.1)
- Device Reset Timer (Section 5.2)
- Watchdog Timer (WDT) (Section 9.2)
- SLEEP (Section 9.3)
- Code protection (Section 9.4)
- ID locations (Section 9.5)

The PIC16C5X Family has a Watchdog Timer which can be shut off only through configuration bit WDTE. It runs off of its own RC oscillator for added reliability. There is an 18 ms delay provided by the Device Reset Timer (DRT), intended to keep the chip in RESET until the crystal oscillator is stable. With this timer on-chip, most applications need no external RESET circuitry.

The SLEEP mode is designed to offer a very low current Power-down mode. The user can wake up from SLEEP through external RESET or through a Watchdog Timer time-out. Several oscillator options are also made available to allow the part to fit the application. The RC oscillator option saves system cost while the LP crystal option saves power. A set of configuration bits are used to select various options.

PIC16CR56A,

9.1 **Configuration Bits**

Configuration bits can be programmed to select various device configurations. Two bits are for the selection of the oscillator type and one bit is the Watchdog Timer enable bit. Nine bits are code protection bits for the PIC16C54A, PIC16CR54A, PIC16C54C, PIC16CR54C, PIC16C56A, PIC16C55A,

PIC16C57C,

One bit is for code protection for the PIC16C54, PIC16C55, PIC16C56 and PIC16C57 devices (Register 9-2).

PIC16C58B, and PIC16CR58B devices (Register 9-1).

QTP or ROM devices have the oscillator configuration programmed at the factory and these parts are tested accordingly (see "Product Identification System" diagrams in the back of this data sheet).

REGISTER 9-1: CONFIGURATION WORD FOR PIC16C54A/CR54A/C54C/CR54C/C55A/C56A/ CR56A/C57C/CR57C/C58B/CR58B

PIC16CR57C,

CP	CP	СР	CP	CP	CP	CP	CP	СР	WDTE	FOSC1	FOSC0
bit 11											bit 0

bit 11-3: CP: Code Protection Bit

1 = Code protection off 0 = Code protection on

bit 2: WDTE: Watchdog timer enable bit

> 1 = WDT enabled 0 = WDT disabled

FOSC1:FOSC0: Oscillator Selection Bit

00 = LP oscillator 01 = XT oscillator 10 = HS oscillator 11 = RC oscillator

Note 1: Refer to the PIC16C5X Programming Specification (Literature Number DS30190) to determine how to access the configuration word.

Legend:			
R = Readable bit	W = Writable bit	U = Unimplemented bit, re	ead as '0'
-n = Value at POR	1 = bit is set	0 = bit is cleared	x = bit is unknown

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REGISTER 9-2: CONFIGURATION WORD FOR PIC16C54/C55/C56/C57

bit 11 bit 0

bit 11-4: Unimplemented: Read as '0'

bit 3: **CP:** Code protection bit.

1 = Code protection off0 = Code protection on

bit 2: WDTE: Watchdog timer enable bit

1 = WDT enabled 0 = WDT disabled

bit 1-0: FOSC1:FOSC0: Oscillator selection bits⁽²⁾

00 = LP oscillator 01 = XT oscillator 10 = HS oscillator 11 = RC oscillator

Note 1: Refer to the PIC16C5X Programming Specifications (Literature Number DS30190) to determine how to access the configuration word.

2: PIC16LV54A supports XT, RC and LP oscillator only.

Legend:

R = Readable bit W = Writable bit U = Unimplemented bit, read as '0'

-n = Value at POR 1 = bit is set 0 = bit is cleared x = bit is unknown

9.2 Watchdog Timer (WDT)

The Watchdog Timer (WDT) is a free running on-chip RC oscillator which does not require any external components. This RC oscillator is separate from the RC oscillator of the OSC1/CLKIN pin. That means that the WDT will run even if the clock on the OSC1/CLKIN and OSC2/CLKOUT pins have been stopped, for example, by execution of a SLEEP instruction. During normal operation or SLEEP, a WDT Reset or Wake-up Reset generates a device RESET.

The TO bit (STATUS<4>) will be cleared upon a Watchdog Timer Reset (Section 6.3).

The WDT can be permanently disabled by programming the configuration bit WDTE as a '0' (Section 9.1). Refer to the PIC16C5X Programming Specifications (Literature Number DS30190) to determine how to access the configuration word.

9.2.1 WDT PERIOD

An 8-bit counter is available as a prescaler for the Timer0 module (Section 8.2), or as a postscaler for the Watchdog Timer (WDT), respectively. For simplicity, this counter is being referred to as "prescaler" throughout this data sheet. Note that the prescaler may be used by either the Timer0 module or the WDT, but not

both. Thus, a prescaler assignment for the Timer0 module means that there is no prescaler for the WDT, and vice-versa.

The PSA and PS<2:0> bits (OPTION<3:0>) determine prescaler assignment and prescale ratio (Section 6.4).

The WDT has a nominal time-out period of 18 ms (with no prescaler). If a longer time-out period is desired, a prescaler with a division ratio of up to 1:128 can be assigned to the WDT (under software control) by writing to the OPTION register. Thus, time-out a period of a nominal 2.3 seconds can be realized. These periods vary with temperature, VDD and part-to-part process variations (see Device Characterization).

Under worst case conditions (VDD = Min., Temperature = Max., WDT prescaler = 1:128), it may take several seconds before a WDT time-out occurs.

9.2.2 WDT PROGRAMMING CONSIDERATIONS

The CLRWDT instruction clears the WDT and the prescaler, if assigned to the WDT, and prevents it from timing out and generating a device RESET.

The SLEEP instruction RESETS the WDT and the prescaler, if assigned to the WDT. This gives the maximum SLEEP time before a WDT Wake-up Reset.

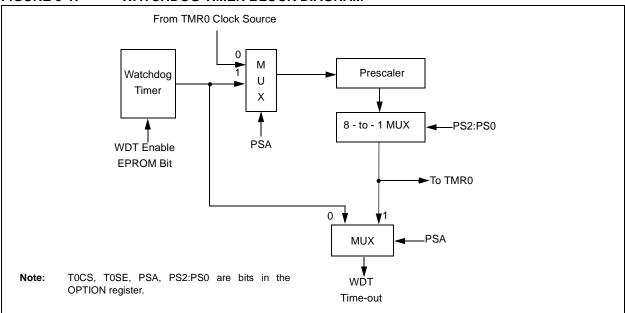


FIGURE 9-1: WATCHDOG TIMER BLOCK DIAGRAM

TABLE 9-1: SUMMARY OF REGISTERS ASSOCIATED WITH THE WATCHDOG TIMER

Address	Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Value on Power-On Reset	Value on MCLR and WDT Reset
N/A	OPTION		1	Tosc	Tose	PSA	PS2	PS1	PS0	11 1111	11 1111

Legend: u = unchanged, - = unimplemented, read as '0'. Shaded cells not used by Watchdog Timer.

9.3 Power-Down Mode (SLEEP)

A device may be powered down (SLEEP) and later powered up (Wake-up from SLEEP).

9.3.1 SLEEP

The Power-down mode is entered by executing a SLEEP instruction.

If enabled, the Watchdog Timer will be cleared but keeps running, the $\overline{10}$ bit (STATUS<4>) is set, the \overline{PD} bit (STATUS<3>) is cleared and the oscillator driver is turned off. The I/O ports maintain the status they had before the SLEEP instruction was executed (driving high, driving low, or hi-impedance).

It should be noted that a RESET generated by a WDT time-out does not drive the MCLR/VPP pin low.

For lowest current consumption while powered down, the T0CKI input should be at VDD or Vss and the $\overline{\text{MCLR}}/\text{VPP}$ pin must be at a logic high level $\overline{\text{(MCLR}} = \text{VIH)}$.

9.3.2 WAKE-UP FROM SLEEP

The device can wake up from SLEEP through one of the following events:

- 1. An external RESET input on MCLR/VPP pin.
- 2. A Watchdog Timer Time-out Reset (if WDT was enabled).

Both of these events cause a device RESET. The $\overline{\text{TO}}$ and $\overline{\text{PD}}$ bits can be used to determine the cause of device RESET. The $\overline{\text{TO}}$ bit is cleared if a WDT timeout occurred (and caused wake-up). The $\overline{\text{PD}}$ bit, which is set on power-up, is cleared when SLEEP is invoked.

The WDT is cleared when the device wakes from SLEEP, regardless of the wake-up source.

9.4 Program Verification/Code Protection

If the code protection bit(s) have not been programmed, the on-chip program memory can be read out for verification purposes.

Note: Microchip does not recommend code protecting windowed devices.

9.5 ID Locations

Four memory locations are designated as ID locations where the user can store checksum or other code-identification numbers. These locations are not accessible during normal execution but are readable and writable during program/verify.

Use only the lower 4 bits of the ID locations and always program the upper 8 bits as '1's.

Note: Microchip will assign a unique pattern number for QTP and SQTP requests and for ROM devices. This pattern number will be unique and traceable to the submitted code.

NOTES:

10.0 INSTRUCTION SET SUMMARY

Each PIC16C5X instruction is a 12-bit word divided into an OPCODE, which specifies the instruction type and one or more operands which further specify the operation of the instruction. The PIC16C5X instruction set summary in Table 10-2 groups the instructions into byte-oriented, bit-oriented, and literal and control operations. Table 10-1 shows the opcode field descriptions.

For **byte-oriented** instructions, 'f' represents a file register designator and 'd' represents a destination designator. The file register designator is used to specify which one of the 32 file registers in that bank is to be used by the instruction.

The destination designator specifies where the result of the operation is to be placed. If 'd' is '0', the result is placed in the W register. If 'd' is '1', the result is placed in the file register specified in the instruction.

For **bit-oriented** instructions, 'b' represents a bit field designator which selects the number of the bit affected by the operation, while 'f' represents the number of the file in which the bit is located.

For **literal and control** operations, 'k' represents an 8 or 9-bit constant or literal value.

TABLE 10-1: OPCODE FIELD DESCRIPTIONS

Field	Description
f	Register file address (0x00 to 0x1F)
W	Working register (accumulator)
b	Bit address within an 8-bit file register
k	Literal field, constant data or label
х	Don't care location (= 0 or 1)
	The assembler will generate code with $x = 0$.
	It is the recommended form of use for com-
	patibility with all Microchip software tools.
d	Destination select;
	d = 0 (store result in W)
	d = 1 (store result in file register 'f')
	Default is d = 1
label	Label name
TOS	Top of Stack
PC	Program Counter
WDT	Watchdog Timer Counter
TO	Time-out bit
PD	Power-down bit
dest	Destination, either the W register or the
	specified register file location
[]	Options
()	Contents
\rightarrow	Assigned to
< >	Register bit field
€	In the set of
italics	User defined term (font is courier)

All instructions are executed within one single instruction cycle, unless a conditional test is true or the program counter is changed as a result of an instruction. In this case, the execution takes two instruction cycles. One instruction cycle consists of four oscillator periods. Thus, for an oscillator frequency of 4 MHz, the normal instruction execution time would be 1 $\mu s.$ If a conditional test is true or the program counter is changed as a result of an instruction, the instruction execution time would be 2 $\mu s.$

Figure 10-1 shows the three general formats that the instructions can have. All examples in the figure use the following format to represent a hexadecimal number:

0xhhh

where 'h' signifies a hexadecimal digit.

FIGURE 10-1: GENERAL FORMAT FOR INSTRUCTIONS

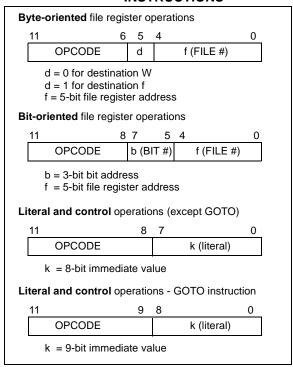


TABLE 10-2: INSTRUCTION SET SUMMARY

Mnemonic, Operands		Description		12-l	Bit Opc	ode	Status	Notes
				MSb		LSb	Affected	Notes
ADDWF	f,d	Add W and f	1	0001	11df	ffff	C,DC,Z	1,2,4
ANDWF	f,d	AND W with f	1	0001	01df	ffff	Z	2,4
CLRF	f	Clear f	1	0000	011f	ffff	Z	4
CLRW	_	Clear W	1	0000	0100	0000	Z	
COMF	f, d	Complement f	1	0010	01df	ffff	Z	
DECF	f, d	Decrement f	1	0000	11df	ffff	Z	2,4
DECFSZ	f, d	Decrement f, Skip if 0	1(2)	0010	11df	ffff	None	2,4
INCF	f, d	Increment f	1	0010	10df	ffff	Z	2,4
INCFSZ	f, d	Increment f, Skip if 0	1 ⁽²⁾	0011	11df	ffff	None	2,4
IORWF	f, d	Inclusive OR W with f	1	0001	00df	ffff	Z	2,4
MOVF	f, d	Move f	1	0010	00df	ffff	Z	2,4
MOVWF	f	Move W to f	1	0000	001f	ffff	None	1,4
NOP	_	No Operation	1	0000	0000	0000	None	
RLF	f, d	Rotate left f through Carry	1	0011	01df	ffff	С	2,4
RRF	f, d	Rotate right f through Carry	1	0011	00df	ffff	С	2,4
SUBWF	f, d	Subtract W from f	1	0000	10df	ffff	C,DC,Z	1,2,4
SWAPF	f, d	Swap f	1	0011	10df	ffff	None	2,4
XORWF	f, d	Exclusive OR W with f	1	0001	10df	ffff	Z	2,4
BIT-ORIEN	TED FIL	E REGISTER OPERATIONS						
BCF	f, b	Bit Clear f	1	0100	bbbf	ffff	None	2,4
BSF	f, b	Bit Set f	1	0101	bbbf	ffff	None	2,4
BTFSC	f, b	Bit Test f, Skip if Clear	1 (2)	0110	bbbf	ffff	None	
BTFSS	f, b	Bit Test f, Skip if Set	1 (2)	0111	bbbf	ffff	None	
LITERAL A	ND CON	ITROL OPERATIONS		•				
ANDLW	k	AND literal with W	1	1110	kkkk	kkkk	Z	
CALL	k	Call subroutine	2	1001	kkkk	kkkk	None	1
CLRWDT	k	Clear Watchdog Timer	1	0000	0000	0100	TO, PD	
GOTO	k	Unconditional branch	2	101k	kkkk	kkkk	None	
IORLW	k	Inclusive OR Literal with W	1	1101	kkkk	kkkk	Z	
MOVLW	k	Move Literal to W	1	1100	kkkk	kkkk	None	
OPTION	k	Load OPTION register	1	0000	0000	0010	None	
RETLW	k	Return, place Literal in W	2	1000	kkkk	kkkk	None	
SLEEP	_	Go into standby mode	1	0000	0000	0011	$\overline{TO}, \overline{PD}$	
TRIS	f	Load TRIS register	1	0000	0000	Offf	None	3
XORLW	k	Exclusive OR Literal to W	1	1111	kkkk	kkkk	Z	

- **Note 1:** The 9th bit of the program counter will be forced to a '0' by any instruction that writes to the PC except for GOTO (see Section 6.5 for more on program counter).
 - 2: When an I/O register is modified as a function of itself (e.g. MOVF PORTB, 1), the value used will be that value present on the pins themselves. For example, if the data latch is '1' for a pin configured as input and is driven low by an external device, the data will be written back with a '0'.
 - 3: The instruction TRIS f, where f = 5, 6 or 7 causes the contents of the W register to be written to the tristate latches of PORTA, B or C respectively. A '1' forces the pin to a hi-impedance state and disables the output buffers.
 - **4:** If this instruction is executed on the TMR0 register (and, where applicable, d = 1), the prescaler will be cleared (if assigned to TMR0).

ADDWF	Add W	and f	
Syntax:	[label]	ADDWF	f,d
Operands:	$0 \le f \le 3$ $d \in [0,1]$	· -	
Operation:	(W) + (f)	\rightarrow (dest)	
Status Affected:	C, DC,	Z	
Encoding:	0001	11df	ffff
Description:	ister 'f'. If 'din the W	of the W register d' is 0 the result register. If 'd' is red back in	
Words:	1		
Cycles:	1		
Example:	ADDWF	TEMP_R	EG, 0
Before Insti	ruction		
W	=	0x17	
_	REG =	0xC2	
After Instructure W TEMP_I	=	0xD9 0xC2	

ANDWF	AND W with f					
Syntax:	[label] ANDWF f,d					
Operands:	$0 \le f \le 31$ $d \in [0,1]$					
Operation:	(W) .AND. (f) \rightarrow (dest)					
Status Affected:	Z					
Encoding:	0001 01df ffff					
Description:	The contents of the W register are AND'ed with register 'f'. If 'd' is 0 the result is stored in the W register. If 'd' is '1' the result is stored back in register 'f'.					
Words:	1					
Cycles:	1					
Example:	ANDWF TEMP_REG, 1					
Before Instru W TEMP_I After Instruct W TEMP_I	= 0x17 REG = 0xC2 tion = 0x17					

ANDLW	AND literal with W						
Syntax:	[label] ANDLW k						
Operands:	$0 \leq k \leq 255$						
Operation:	(W).AND. (k) \rightarrow (W)						
Status Affected:	Z						
Encoding:	1110 kkkk kkkk						
Description:	The contents of the W register are AND'ed with the eight-bit literal 'k'. The result is placed in the W register.						
Words:	1						
Cycles:	1						
Example:	ANDLW H'5F'						
Before Instruction W = 0xA3 After Instruction W = 0x03							

BCF	Bit Clea	r f						
Syntax:	[label]	BCF f,b)					
Operands:	-	$\begin{array}{l} 0 \leq f \leq 31 \\ 0 \leq b \leq 7 \end{array}$						
Operation:	$0 \rightarrow (f < b >)$							
Status Affected:	None							
Encoding:	0100	bbbf	ffff					
Description:	Bit 'b' in	register 'f'	is cleare	d.				
Words:	1							
Cycles:	1							
Example:	BCF	FLAG_RE	EG, 7					
Before Instru FLAG_F After Instruct	REG =	0xC7						
FLAG_F		0x47						

BSF	Bit Set f							
Syntax:	[label]	BSF f,b						
Operands:	$0 \le f \le 31$ $0 \le b \le 7$	$\begin{array}{l} 0 \leq f \leq 31 \\ 0 \leq b \leq 7 \end{array}$						
Operation:	$1 \rightarrow (f < b)$	>)						
Status Affected:	None							
Encoding:	0101	bbbf	ffff					
Description:	Bit 'b' in r	egister 'f'	is set.					
Words:	1							
Cycles:	1							
Example:	BSF	FLAG_RE	EG, 7					
Before Instruction FLAG_REG = 0x0A After Instruction								
FLAG_F	REG = 0	A8x(

BTFSC	Bit Test f, Skip if Clear						
Syntax:	[label] BTFSC f,b						
Operands:	$\begin{array}{l} 0 \leq f \leq 31 \\ 0 \leq b \leq 7 \end{array}$						
Operation:	skip if $(f < b >) = 0$						
Status Affected:	None						
Encoding:	0110 bbbf ffff						
Description:	If bit 'b' in register 'f' is 0 then the next instruction is skipped. If bit 'b' is 0 then the next instruction fetched during the current instruction execution is discarded, and a NOP is executed instead, making this a 2-cycle instruction.						
Words:	1						
Cycles:	1(2)						
Example:	HERE BTFSC FLAG,1 FALSE GOTO PROCESS_CODE TRUE • • •	E					
Before Instru PC After Instruct	= address (HERE)						
if FLAG PC if FLAG PC	= address (TRUE);						

BTFSS	Bit Test f, Skip if Set				
Syntax:	[label] BTFSS f,b				
Operands:	$0 \le f \le 31$ $0 \le b < 7$				
Operation:	skip if $(f < b >) = 1$				
Status Affected:	None				
Encoding:	0111 bbbf ffff				
Description:	If bit 'b' in register 'f' is '1' then the next instruction is skipped. If bit 'b' is '1', then the next instruction fetched during the current instruction execution, is discarded and a NOP is executed instead, making this a 2-cycle instruction.				
Words:	1				
Cycles:	1(2)				
Example:	HERE BTFSS FLAG,1 FALSE GOTO PROCESS_CODE TRUE • •	:			
Before Instru PC After Instruc If FLAG- PC if FLAG- PC	= address (HERE) ction <1> = 0,				

CALL	Subroutine Call	CLRW	Clear W
Syntax:	[label] CALL k	Syntax:	[label] CLRW
Operands:	$0 \leq k \leq 255$	Operands:	None
Operation:	(PC) + 1→ TOS; k → PC<7:0>;	Operation:	$00h \rightarrow (W);$ $1 \rightarrow Z$
	(STATUS<6:5>) → PC<10:9>; 0 → PC<8>	Status Affected:	Z
Status Affected:	None	Encoding:	0000 0100 0000
Encoding:	1001 kkkk kkkk	Description:	The W register is cleared. Zero bit (Z) is set.
Description:	Subroutine call. First, return address (PC+1) is pushed onto the	Words:	1
	stack. The eight bit immediate	Cycles:	1
	address is loaded into PC bits	Example:	CLRW
	<7:0>. The upper bits PC<10:9> are loaded from STATUS<6:5>, PC<8> is cleared. CALL is a two-cycle instruction.	After Instruc	= 0x5A
Words:	1	Z =	
Cycles:	2		
_			
Example:	HERE CALL THERE	CLRWDT	Clear Watchdog Timer
Before Instr	uction	CLRWDT	Clear Watchdog Timer
	uction = address (HERE)	Syntax:	[label] CLRWDT
Before Instr PC = After Instruc PC = TOS =	uction = address (HERE) ction = address (THERE) = address (HERE + 1)	_	
Before Instr PC = After Instruc PC =	uction = address (HERE) ction = address (THERE) = address (HERE + 1) Clear f	Syntax: Operands:	[label] CLRWDT None $00h \rightarrow WDT;$ $0 \rightarrow WDT$ prescaler (if assigned); $1 \rightarrow \overline{10};$
Before Instruction PC = After Instruction PC = TOS = CLRF Syntax:	uction = address (HERE) ction = address (THERE) = address (HERE + 1) Clear f [label] CLRF f	Syntax: Operands: Operation:	[label] CLRWDT None $00h \rightarrow WDT;$ $0 \rightarrow \frac{WD}{T}$ prescaler (if assigned); $1 \rightarrow \frac{TO}{PD};$ $1 \rightarrow \overline{PD}$
Before Instruction PC = After Instruction PC = TOS = CLRF Syntax: Operands:	uction = address (HERE) ction = address (THERE) = address (HERE + 1) Clear f [label] CLRF f 0 \le f \le 31	Syntax: Operands: Operation: Status Affected:	[label] CLRWDT None $00h \rightarrow WDT$; $0 \rightarrow WDT$ prescaler (if assigned); $1 \rightarrow \overline{TO}$; $1 \rightarrow \overline{PD}$ \overline{TO} , \overline{PD}
Before Instruction PC = After Instruction PC = TOS = CLRF Syntax:	uction = address (HERE) ction = address (THERE) = address (HERE + 1) Clear f [$label$] CLRF f $0 \le f \le 31$ $00h \rightarrow (f)$;	Syntax: Operands: Operation: Status Affected: Encoding:	[label] CLRWDT None $00h \rightarrow WDT;$ $0 \rightarrow WDT$ prescaler (if assigned); $1 \rightarrow \overline{TO};$ $1 \rightarrow \overline{PD}$ $\overline{TO}, \overline{PD}$ $0000 0000 0100$ The CLRWDT instruction resets the WDT. It also resets the prescaler, if
Before Instruction PC = After Instruction PC = TOS = CLRF Syntax: Operands: Operation: Status Affected:	uction = address (HERE) ction = address (THERE) = address (HERE + 1) Clear f [label] CLRF f $0 \le f \le 31$ $00h \rightarrow (f);$ $1 \rightarrow Z$ Z	Syntax: Operands: Operation: Status Affected: Encoding:	[label] CLRWDT None $00h \rightarrow WDT;$ $0 \rightarrow WDT$ prescaler (if assigned); $1 \rightarrow \overline{TO};$ $1 \rightarrow \overline{PD}$ $\overline{TO}, \overline{PD}$ $0000 0000 0100$ The CLRWDT instruction resets the
Before Instruction PC = After Instruction PC = TOS = TOS = CLRF Syntax: Operands: Operands: Operation: Status Affected: Encoding:	uction = address (HERE) etion = address (THERE) = address (HERE + 1) Clear f [label] CLRF f $0 \le f \le 31$ $00h \rightarrow (f);$ $1 \rightarrow Z$ Z	Syntax: Operands: Operation: Status Affected: Encoding:	[label] CLRWDT None $00h \rightarrow WDT$; $0 \rightarrow WDT$ prescaler (if assigned); $1 \rightarrow \overline{10}$; $1 \rightarrow \overline{PD}$ \overline{TO} , \overline{PD} $0000 0000 0100$ The CLRWDT instruction resets the WDT. It also resets the prescaler, if the prescaler is assigned to the WDT and not Timer0. Status bits
Before Instruction PC = After Instruction PC = TOS = CLRF Syntax: Operands: Operation: Status Affected:	uction = address (HERE) ction = address (THERE) = address (HERE + 1) Clear f [label] CLRF f $0 \le f \le 31$ $00h \rightarrow (f);$ $1 \rightarrow Z$ Z	Syntax: Operands: Operation: Status Affected: Encoding: Description:	[label] CLRWDT None $00h \rightarrow WDT$; $0 \rightarrow WDT$ prescaler (if assigned); $1 \rightarrow \overline{TO}$; $1 \rightarrow \overline{PD}$ \overline{TO} , \overline{PD} $0000 0000 0100$ The CLRWDT instruction resets the WDT. It also resets the prescaler, if the prescaler is assigned to the WDT and not Timer0. Status bits \overline{TO} and \overline{PD} are set.

Before Instruction

After Instruction

TO

 $\overline{\mathsf{PD}}$

WDT counter =

WDT counter =

WDT prescaler =

0x00

0

1

1

Before Instruction

After Instruction

Ζ

FLAG_REG =

FLAG_REG =

CLRF

FLAG_REG

0x5A

0x00

1

Cycles:

Example:

COMF	Complement f			
Syntax:	[label]	COMF	f,d	
Operands:	$0 \le f \le 31$ $d \in [0,1]$			
Operation:	$(\overline{f}) \rightarrow (de$	est)		
Status Affected:	Z			
Encoding:	0010	01df	ffff	
Description:	complent is stored the result register.	nented. If in the W It is store	egister 'f' are 'd' is 0 the result register. If 'd' is 1 d back in	
Words:	1			
Cycles:	1			
Example:	COMF	REG1,0		
Before Instru REG1 After Instruct REG1 W	= 02 ion = 02	x13 x13 xEC		

DECF	Decrement f			
Syntax:	[label] DECF f,d			
Operands:	$0 \le f \le 31$ $d \in [0,1]$			
Operation:	$(f) - 1 \rightarrow$	(dest)		
Status Affected:	Z			
Encoding:	0000	11df	ffff	
Description:	Decrement register 'f'. If 'd' is 0 the result is stored in the W register. If 'd' is 1 the result is stored back in register 'f'.			
Words:	1			
Cycles:	1			
Example:	DECF	CNT,	1	
Before Instru CNT Z After Instruct CNT Z	= 0x = 0 tion	k01 k00		

DECFSZ	Decrement f, Skip if 0			
Syntax:	[label] DECFSZ f,d			
Operands:	$0 \le f \le 31$ $d \in [0,1]$			
Operation:	$(f) - 1 \rightarrow d$; skip if result = 0			
Status Affected:	None			
Encoding:	0010 l1df ffff			
Description:	The contents of register 'f' are decremented. If 'd' is 0 the result is placed in the W register. If 'd' is 1 the result is placed back in register 'f'. If the result is 0, the next instruction, which is already fetched, is discarded and a NOP is executed instead making it a two-cycle instruction.			
Words:	1			
Cycles:	1(2)			
Example:	HERE DECFSZ CNT, 1 GOTO LOOP			
	CONTINUE •			
Before Instru				
PC After Instruct	= address (HERE)			
CNT	= CNT - 1;			
if CNT	= 0,			
PC if CNT	<pre>= address (CONTINUE); ≠ 0,</pre>			
PC	= address (HERE+1)			

GOTO	Unconditional Branch			
Syntax:	[label] GOTO k			
Operands:	$0 \leq k \leq 511$			
Operation:	$k \rightarrow PC<8:0>$; STATUS<6:5> $\rightarrow PC<10:9>$			
Status Affected:	None			
Encoding:	101k kkkk kkkk			
Description:	GOTO is an unconditional branch. The 9-bit immediate value is loaded into PC bits <8:0>. The upper bits of PC are loaded from STATUS<6:5>. GOTO is a two-cycle instruction.			
Words:	1			
Cycles:	2			
Example:	GOTO THERE			
After Instruct PC =	ion address (THERE)			

INCF	Increment f			
Syntax:	[label] INCF f,d			
Operands:	$0 \le f \le 31$ $d \in [0,1]$			
Operation:	$(f) + 1 \rightarrow (dest)$			
Status Affected:	Z			
Encoding:	0010 10df ffff			
Description:	The contents of register 'f' are incremented. If 'd' is 0 the result is placed in the W register. If 'd' is 1 the result is placed back in register 'f'.			
Words:	1			
Cycles:	1			
Example:	INCF CNT, 1			
Before Instru CNT Z After Instruct CNT Z	= 0xFF = 0			

INCFSZ	Increment f, Skip if 0		
Syntax:	[label] INCFSZ f,d		
Operands:	$0 \le f \le 31$ $d \in [0,1]$		
Operation:	(f) + 1 \rightarrow (dest), skip if result = 0		
Status Affected:	None		
Encoding:	0011 11df ffff		
Description:	The contents of register 'f' are incremented. If 'd' is 0 the result is placed in the W register. If 'd' is 1 the result is placed back in register 'f'. If the result is 0, then the next instruction, which is already fetched, is discarded and a NOP is executed instead making it a two-cycle instruction.		
Words:	1		
Cycles:	1(2)		
Example:	HERE INCFSZ CNT, 1 GOTO LOOP		
	CONTINUE •		
Before Instru	ction		
PC	= address (HERE)		
After Instructi CNT	on = CNT + 1;		
if CNT	= 0,		
PC	<pre>= address (CONTINUE);</pre>		
if CNT	≠ 0,		
PC	= address (HERE +1)		

IORLW	Inclusive OR literal with W			
Syntax:	[label] IORLW k			
Operands:	$0 \leq k \leq 255$			
Operation:	(W) .OR. $(k) \rightarrow (W)$			
Status Affected:	Z			
Encoding:	1101 kkkk kkkk			
Description:	The contents of the W register are OR'ed with the eight bit literal 'k'. The result is placed in the W register.			
Words:	1			
Cycles:	1			
Example:	IORLW 0x35			
Before Instru	uction			
W =				
After Instruc				
W =	0xBF			
Z =	0			

IORWF	Inclusive OR W with f			
Syntax:	[label] IORWF f,d			
Operands:	$0 \le f \le 31$ $d \in [0,1]$			
Operation:	(W).OR. (f) \rightarrow (dest)			
Status Affected:	Z			
Encoding:	0001 00df ffff			
Description:	Inclusive OR the W register with register 'f'. If 'd' is 0 the result is placed in the W register. If 'd' is 1 the result is placed back in register 'f'.			
Words:	1			
Cycles:	1			
Example:	IORWF RESULT, 0			
Before Instru RESUL ⁻ W After Instruct RESUL ⁻ W Z	$\Gamma = 0x13$ = 0x91 tion			

MOVF	Move f		
Syntax:	[label] MOVF f,d		
Operands:	$0 \le f \le 31$ $d \in [0,1]$		
Operation:	$(f) \rightarrow (dest)$		
Status Affected:	Z		
Encoding:	0010 00df ffff		
Description:	The contents of register 'f' is moved to destination 'd'. If 'd' is 0, destination is the W register. If 'd' is 1, the destination is file register 'f'. 'd' is 1 is useful to test a file register since status flag Z is affected.		
Words:	1		
Cycles:	1		
Example:	MOVF FSR, 0		
After Instruc W =	tion - value in FSR register		

MOVLW	Move Literal to W		
Syntax:	[label]	MOVLW	k
Operands:	$0 \le k \le 2$	55	
Operation:	$k \rightarrow (W)$		
Status Affected:	None		
Encoding:	1100	kkkk	kkkk
Description:	The eighthe W re		'k' is loaded into
Words:	1		
Cycles:	1		
Example:	MOVLW	0x5A	
After Instruction W = 0x5A			

MOVWF	Move W	to f		
Syntax:	[label]	MOVWF	f	
Operands:	$0 \le f \le 31$			
Operation:	$(W) \rightarrow (f)$)		
Status Affected:	None			
Encoding:	0000	001f	ffff	
Description:	Move da	ta from th	e W regis	ster to
	register '	f'.		
Words:	1			
Cycles:	1			
Example:	MOVWF	TEMP_RE	:G	
Before Instru	ıction			
TEMP_I	REG =	0xFF		
W	=	0x4F		
After Instruct	tion			
TEMP_I	REG =	0x4F		
W	=	0x4F		

NOP	No Oper	ation			
Syntax:	[label]	NOP			
Operands:	None				
Operation:	No operation				
Status Affected:	None				
Encoding:	0000	0000	0000]	
Description:	No opera	ition.		-	
Words:	1				
Cycles:	1				
Example:	NOP				

OPTION	Load Of	PTION R	egister	
Syntax:	[label]	OPTIO	N	
Operands:	None			
Operation:	$(W) \rightarrow C$	PTION		
Status Affected:	None			
Encoding:	0000	0000	0010	
Description:			e W regis	
	loaded ir	nto the O	PTION re	egister.
Words:	1			
Cycles:	1			
Example	OPTION			
Before Instru	ction			
W	= 0x	07		
After Instructi	on			
OPTION	= 0x	07		

RETLW	Return with Literal in W					
Syntax:	[label] RETLW k					
Operands:	$0 \leq k \leq 255$					
Operation:	$k \rightarrow (W);$ TOS \rightarrow PC					
Status Affected:	None					
Encoding:	1000 kkkk kkkk					
Description:	The W register is loaded with the eight bit literal 'k'. The program counter is loaded from the top of the stack (the return address). This is a two-cycle instruction.					
Words:	1					
Cycles:	2					
Example:	CALL TABLE ;W contains ;table offset ;value. • ;W now has table ;value.					
TABLE	ADDWF PC ;W = offset RETLW k1 ;Begin table RETLW k2 ;					
Before Instru	uction					
W	= 0x07					
After Instruc						
W	= value of k8					

RLF	Rotate	e Left f	thro	ugh Carry
Syntax:	[label] RLF	f,c	I
Operands:	$0 \le f \le d \in [0]$			
Operation:	See de	escripti	on be	elow
Status Affected:	С			
Encoding:	0011	010	df	ffff
Description:	rotated the Ca is 0 the registe	d one b arry Fla e resuli er. If 'd' back i	oit to t g (ST t is pl is 1 t n	egister 'f' are the left through TATUS<0>). If 'd' aced in the W he result is
Words:	1			
Cycles:	1			
Example:	RLF	REG	1,0	
Before Instru REG1 C After Instruc	=	1110 0	0110	0
REG1 W	=	1110 1100	0110	-
C	=	1	1100	U

RRF	Rotate	e Righ	t f thi	rough Carry
Syntax:	[label	'] RF	RF f,	d
Operands:	$0 \le f \le d \in [0]$			
Operation:	See d	escript	ion be	elow
Status Affected:	С			
Encoding:	0011	. 00	df	ffff
Description:	rotated the Ca is 0 th registe	d one barry Fla e resul er. If 'd' d back	oit to t ag (S7 It is pl is 1 t in	egister 'f' are the right through (ATUS<0>). If 'd' laced in the W the result is
Words:	1			
Cycles:	1			
Example:	RRF	REC	31,0	
Before Instru REG1 C After Instruct REG1	= =	1110 0	0110	
W C	=	0111 0	001	1

SLEEP	Enter SL	EEP Mo	de	
Syntax:	[label]	SLEEP		
Operands:	None			
Operation:	$00h \rightarrow W$ $0 \rightarrow \underline{WD}$ $1 \rightarrow \underline{TO}$ $0 \rightarrow PD$,	er; if assi	gned
Status Affected:	$\overline{TO}, \overline{PD}$			
Encoding:	0000	0000	0011	
Description:	Time-out power-do cleared. caler are The proc mode wit See sect details.	own statu The WDT cleared. essor is p	s bit (PD) and its pout into Sillator sto	is pres- LEEP opped.
Words:	1			
Cycles:	1			
Example:	SLEEP			

SUBWF	Subtract W from f	SWAPF	Swap Nibbles in f
Syntax:	[<i>label</i>] SUBWF f,d	Syntax:	[label] SWAPF f,d
Operands:	$0 \le f \le 31$ $d \in [0,1]$	Operands:	$0 \le f \le 31$ $d \in [0,1]$
Operation: Status Affected:	$(f) - (W) \rightarrow (dest)$ C, DC, Z	Operation:	$(f<3:0>) \rightarrow (dest<7:4>);$ $(f<7:4>) \rightarrow (dest<3:0>)$
		Status Affected:	None
Encoding:	0000 10df ffff	Encoding:	0011 10df ffff
Description:	Subtract (2's complement method) the W register from register 'f'. If 'd' is 0 the result is stored in the W register. If 'd' is 1 the result is stored back in register 'f'.	Description:	The upper and lower nibbles of register 'f' are exchanged. If 'd' is 0 the result is placed in W register. If 'd' is 1 the result is placed in
Words:	1		register 'f'.
Cycles:	1	Words:	1
Example 1:	SUBWF REG1, 1	Cycles:	1
Before Instru	uction	Example	SWAPF REG1, 0
REG1 W C After Instruc REG1	= 3 = 2 = ? ition = 1	Before Instr REG1 After Instruc REG1 W	= 0xA5
W	= 2		
C Evernle 2:	= 1 ; result is positive		
Example 2: Before Instru	uction	TRIS	Load TRIS Register
REG1	= 2	Syntax:	[label] TRIS f
W	= 2	Operands:	f = 5, 6 or 7
С	= ?	Operation:	$(W) \rightarrow TRIS$ register f
After Instruc		Status Affected:	• ,
REG1	= 0		
W	= 2	Encoding:	0000 0000 Offf
C Example 3: Before Ins		Description:	TRIS register 'f' (f = 5, 6, or 7) is loaded with the contents of the W register.
REG1	= 1	Words:	1
W	= 2	Cycles:	1
C	= ?	•	
After Instruc REG1	· ·	Example	TRIS PORTB
W	= 0xFF = 2	Before Instru	
C	= 0 ; result is negative	W After Instruc TRISB	= 0xA5 tion = 0xA5

XORLW Exclusive OR literal with W

Syntax: [label] XORLW k

Operands: $0 \le k \le 255$

Operation: (W) .XOR. $k \rightarrow (W)$

Status Affected: Z

Encoding: 1111 kkkk kkkk

Description: The contents of the W register are

XOR'ed with the eight bit literal 'k'. The result is placed in the W regis-

ter.

Words: 1 Cycles: 1

Example: XORLW 0xAF

Before Instruction

W = 0xB5

After Instruction

W = 0x1A

XORWF Exclusive OR W with f

Syntax: [label] XORWF f,d

Operands: $0 \le f \le 31$

 $d \in [0,1]$

Operation: (W) .XOR. (f) \rightarrow (dest)

Status Affected: Z

Encoding: 0001 10df ffff

Description: Exclusive OR the contents of the

W register with register 'f'. If 'd' is 0 the result is stored in the W register. If 'd' is 1 the result is stored

back in register 'f'.

Words: 1 Cycles: 1

Example XORWF REG, 1

Before Instruction

 $\begin{array}{rcl}
\mathsf{REG} & = & \mathsf{0xAF} \\
\mathsf{W} & = & \mathsf{0xB5}
\end{array}$

After Instruction

 $\begin{array}{rcl} REG & = & 0x1A \\ W & = & 0xB5 \end{array}$

11.0 DEVELOPMENT SUPPORT

The PIC[®] microcontrollers are supported with a full range of hardware and software development tools:

- Integrated Development Environment
 - MPLAB® IDE Software
- · Assemblers/Compilers/Linkers
 - MPASM™ Assembler
 - MPLAB C17 and MPLAB C18 C Compilers
 - MPLINK™ Object Linker/ MPLIB™ Object Librarian
- Simulators
 - MPLAB SIM Software Simulator
- Emulators
 - MPLAB ICE 2000 In-Circuit Emulator
 - ICEPIC™ In-Circuit Emulator
- · In-Circuit Debugger
 - MPLAB ICD
- · Device Programmers
 - PRO MATE® II Universal Device Programmer
 - PICSTART® Plus Entry-Level Development Programmer
- · Low Cost Demonstration Boards
 - PICDEM™ 1 Demonstration Board
 - PICDEM 2 Demonstration Board
 - PICDEM 3 Demonstration Board
 - PICDEM 17 Demonstration Board
 - KEELOQ® Demonstration Board

11.1 MPLAB Integrated Development Environment Software

The MPLAB IDE software brings an ease of software development previously unseen in the 8-bit microcontroller market. The MPLAB IDE is a Windows®-based application that contains:

- · An interface to debugging tools
 - simulator
 - programmer (sold separately)
 - emulator (sold separately)
 - in-circuit debugger (sold separately)
- · A full-featured editor
- · A project manager
- Customizable toolbar and key mapping
- · A status bar
- · On-line help

The MPLAB IDE allows you to:

- Edit your source files (either assembly or 'C')
- One touch assemble (or compile) and download to PIC MCU emulator and simulator tools (automatically updates all project information)
- · Debug using:
 - source files
 - absolute listing file
 - machine code

The ability to use MPLAB IDE with multiple debugging tools allows users to easily switch from the cost-effective simulator to a full-featured emulator with minimal retraining.

11.2 MPASM Assembler

The MPASM assembler is a full-featured universal macro assembler for all PIC MCUs.

The MPASM assembler has a command line interface and a Windows shell. It can be used as a stand-alone application on a Windows 3.x or greater system, or it can be used through MPLAB IDE. The MPASM assembler generates relocatable object files for the MPLINK object linker, Intel[®] standard HEX files, MAP files to detail memory usage and symbol reference, an absolute LST file that contains source lines and generated machine code, and a COD file for debugging.

The MPASM assembler features include:

- · Integration into MPLAB IDE projects.
- User-defined macros to streamline assembly code.
- Conditional assembly for multi-purpose source files
- Directives that allow complete control over the assembly process.

11.3 MPLAB C17 and MPLAB C18 C Compilers

The MPLAB C17 and MPLAB C18 Code Development Systems are complete ANSI 'C' compilers for Microchip's PIC17CXXX and PIC18CXXX family of microcontrollers, respectively. These compilers provide powerful integration capabilities and ease of use not found with other compilers.

For easier source level debugging, the compilers provide symbol information that is compatible with the MPLAB IDE memory display.

11.4 MPLINK Object Linker/ MPLIB Object Librarian

The MPLINK object linker combines relocatable objects created by the MPASM assembler and the MPLAB C17 and MPLAB C18 C compilers. It can also link relocatable objects from pre-compiled libraries, using directives from a linker script.

The MPLIB object librarian is a librarian for precompiled code to be used with the MPLINK object linker. When a routine from a library is called from another source file, only the modules that contain that routine will be linked in with the application. This allows large libraries to be used efficiently in many different applications. The MPLIB object librarian manages the creation and modification of library files.

The MPLINK object linker features include:

- Integration with MPASM assembler and MPLAB C17 and MPLAB C18 C compilers.
- Allows all memory areas to be defined as sections to provide link-time flexibility.

The MPLIB object librarian features include:

- Easier linking because single libraries can be included instead of many smaller files.
- Helps keep code maintainable by grouping related modules together.
- Allows libraries to be created and modules to be added, listed, replaced, deleted or extracted.

11.5 MPLAB SIM Software Simulator

The MPLAB SIM software simulator allows code development in a PC-hosted environment by simulating the PIC series microcontrollers on an instruction level. On any given instruction, the data areas can be examined or modified and stimuli can be applied from a file, or user-defined key press, to any of the pins. The execution can be performed in single step, execute until break, or trace mode.

The MPLAB SIM simulator fully supports symbolic debugging using the MPLAB C17 and the MPLAB C18 C compilers and the MPASM assembler. The software simulator offers the flexibility to develop and debug code outside of the laboratory environment, making it an excellent multiproject software development tool.

11.6 MPLAB ICE High Performance Universal In-Circuit Emulator with MPLAB IDE

The MPLAB ICE universal in-circuit emulator is intended to provide the product development engineer with a complete microcontroller design tool set for PIC microcontrollers (MCUs). Software control of the MPLAB ICE in-circuit emulator is provided by the MPLAB Integrated Development Environment (IDE), which allows editing, building, downloading and source debugging from a single environment.

The MPLAB ICE 2000 is a full-featured emulator system with enhanced trace, trigger and data monitoring features. Interchangeable processor modules allow the system to be easily reconfigured for emulation of different processors. The universal architecture of the MPLAB ICE in-circuit emulator allows expansion to support new PIC microcontrollers.

The MPLAB ICE in-circuit emulator system has been designed as a real-time emulation system, with advanced features that are generally found on more expensive development tools. The PC platform and Microsoft® Windows environment were chosen to best make these features available to you, the end user.

11.7 ICEPIC In-Circuit Emulator

The ICEPIC low cost, in-circuit emulator is a solution for the Microchip Technology PIC16C5X, PIC16C6X, PIC16C7X and PIC16CXXX families of 8-bit One-Time-Programmable (OTP) microcontrollers. The modular system can support different subsets of PIC16C5X or PIC16CXXX products through the use of interchangeable personality modules, or daughter boards. The emulator is capable of emulating without target application circuitry being present.

11.8 MPLAB ICD In-Circuit Debugger

Microchip's In-Circuit Debugger, MPLAB ICD, is a powerful, low cost, run-time development tool. This tool is based on the FLASH PIC MCUs and can be used to develop for this and other PIC microcontrollers. The MPLAB ICD utilizes the in-circuit debugging capability built into the FLASH devices. This feature, along with Microchip's In-Circuit Serial Programming™ protocol, offers cost-effective in-circuit FLASH debugging from the graphical user interface of the MPLAB Integrated Development Environment. This enables a designer to develop and debug source code by watching variables, single-stepping and setting break points. Running at full speed enables testing hardware in real-time.

11.9 PRO MATE II Universal Device Programmer

The PRO MATE II universal device programmer is a full-featured programmer, capable of operating in Stand-alone mode, as well as PC-hosted mode. The PRO MATE II device programmer is CE compliant.

The PRO MATE II device programmer has programmable VDD and VPP supplies, which allow it to verify programmed memory at VDD min and VDD max for maximum reliability. It has an LCD display for instructions and error messages, keys to enter commands and a modular detachable socket assembly to support various package types. In Stand-alone mode, the PRO MATE II device programmer can read, verify, or program PIC devices. It can also set code protection in this mode.

11.10 PICSTART Plus Entry Level Development Programmer

The PICSTART Plus development programmer is an easy-to-use, low cost, prototype programmer. It connects to the PC via a COM (RS-232) port. MPLAB Integrated Development Environment software makes using the programmer simple and efficient.

The PICSTART Plus development programmer supports all PIC devices with up to 40 pins. Larger pin count devices, such as the PIC16C92X and PIC17C76X, may be supported with an adapter socket. The PICSTART Plus development programmer is CE compliant.

11.11 PICDEM 1 Low Cost PIC MCU Demonstration Board

The PICDEM 1 demonstration board is a simple board which demonstrates the capabilities of several of Microchip's microcontrollers. The microcontrollers supported are: PIC16C5X (PIC16C54 to PIC16C58A). PIC16C61, PIC16C62X, PIC16C71, PIC16C8X, PIC17C42, PIC17C43 and PIC17C44. All necessary hardware and software is included to run basic demo programs. The user can program the sample microcontrollers provided with the PICDEM 1 demonstration board on a PRO MATE II device programmer, or a PICSTART Plus development programmer, and easily test firmware. The user can also connect the PICDEM 1 demonstration board to the MPLAB ICE incircuit emulator and download the firmware to the emulator for testing. A prototype area is available for the user to build some additional hardware and connect it to the microcontroller socket(s). Some of the features include an RS-232 interface, a potentiometer for simulated analog input, push button switches and eight LEDs connected to PORTB.

11.12 PICDEM 2 Low Cost PIC16CXX Demonstration Board

The PICDEM 2 demonstration board is a simple demonstration board that supports the PIC16C62, PIC16C64, PIC16C65, PIC16C73 and PIC16C74 microcontrollers. All the necessary hardware and software is included to run the basic demonstration programs. The user can program the sample microcontrollers provided with the PICDEM 2 demonstration board on a PRO MATE II device programmer, or a PICSTART Plus development programmer, and easily test firmware. The MPLAB ICE in-circuit emulator may also be used with the PICDEM 2 demonstration board to test firmware. A prototype area has been provided to the user for adding additional hardware and connecting it to the microcontroller socket(s). Some of the features include a RS-232 interface, push button switches, a potentiometer for simulated analog input, a serial EEPROM to demonstrate usage of the I²CTM bus and separate headers for connection to an LCD module and a keypad.

11.13 PICDEM 3 Low Cost PIC16CXXX Demonstration Board

The PICDEM 3 demonstration board is a simple demonstration board that supports the PIC16C923 and PIC16C924 in the PLCC package. It will also support future 44-pin PLCC microcontrollers with an LCD Module. All the necessary hardware and software is included to run the basic demonstration programs. The user can program the sample microcontrollers provided with the PICDEM 3 demonstration board on a PRO MATE II device programmer, or a PICSTART Plus development programmer with an adapter socket, and easily test firmware. The MPLAB ICE in-circuit emulator may also be used with the PICDEM 3 demonstration board to test firmware. A prototype area has been provided to the user for adding hardware and connecting it to the microcontroller socket(s). Some of the features include a RS-232 interface, push button switches, a potentiometer for simulated analog input, a thermistor and separate headers for connection to an external LCD module and a keypad. Also provided on the PICDEM 3 demonstration board is a LCD panel, with 4 commons and 12 segments, that is capable of displaying time, temperature and day of the week. The PICDEM 3 demonstration board provides an additional RS-232 interface and Windows software for showing the demultiplexed LCD signals on a PC. A simple serial interface allows the user to construct a hardware demultiplexer for the LCD signals.

11.14 PICDEM 17 Demonstration Board

The PICDEM 17 demonstration board is an evaluation board that demonstrates the capabilities of several Microchip microcontrollers, including PIC17C752, PIC17C756A, PIC17C762 and PIC17C766. All necessary hardware is included to run basic demo programs, which are supplied on a 3.5-inch disk. A programmed sample is included and the user may erase it and program it with the other sample programs using the PRO MATE II device programmer, or the PICSTART Plus development programmer, and easily debug and test the sample code. In addition, the PICDEM 17 demonstration board supports downloading of programs to and executing out of external FLASH memory on board. The PICDEM 17 demonstration board is also usable with the MPLAB ICE in-circuit emulator, or the PICMASTER emulator and all of the sample programs can be run and modified using either emulator. Additionally, a generous prototype area is available for user hardware.

11.15 KEELOQ Evaluation and Programming Tools

KEELOQ evaluation and programming tools support Microchip's HCS Secure Data Products. The HCS evaluation kit includes a LCD display to show changing codes, a decoder to decode transmissions and a programming interface to program test transmitters.

TABLE 11-1: DEVELOPMENT TOOLS FROM MICROCHIP

MPLAB® Integrated	> >	S S S S S S	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	5 5 5 5 5	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	S S S S S S	, , , , , , , , , , , , , , , , , , ,		
MPLAB® C17 C Compiler MPLAB® C18 C Compiler		\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \		S S S S S	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \				
MPLAB® C18 C Compiler		\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \		S S S S			
MPASM™ Assembler/ MPLINK™ Object Linker ✓		>> > > >	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	> > > >	> > > >	S S S S			
MPLAB® ICE In-Circuit Emulator	> > > >	> > >	> > > >	\$ \$	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	, , ,	\ \ \ \ \ \		
ICEPIC™ In-Circuit Emulator	> > >	> > >	\ \\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\	\ \ \ \ \ \	\ \ \ \ \ \ \	\	, ,		
MPLAB® ICD In-Circuit Debugger PICSTART® Plus Entry Level Development Programmer PRO MATE® II Universal Device Programmer PICDEM™ 1 Demonstration Board PICDEM™ 2 Demonstration Board PICDEM™ 3 Demonstration Board PICDEM™ 14A Demonstration Board PICDEM™ 14A Demonstration PICDEM™ 15	> >	· · ·	> >	\ \ \ \	> >	, ,	> >		
PICSTART® Plus Entry Level Development Programmer PRO MATE® II Universal Device Programmer PICDEM™ 1 Demonstration Board PICDEM™ 2 Demonstration Board PICDEM™ 3 Demonstration Board PICDEM™ 3 Demonstration Board PICDEM™ 4A Demonstration PICDEM™ 4A Demonstration PICDEM™ 4A Demonstration	> >	> >	> >	> >	> >	, ,	>		
PRO MATE® II Universal Device Programmer PICDEM™ 1 Demonstration Board PICDEM™ 2 Demonstration Board PICDEM™ 3 Demonstration Board PICDEM™ 4A Demonstration Board PICDEM™ 4A Demonstration Board PICDEM™ 4A Demonstration	>	>	>	`	>	``			
W TM 1 Demonstration W TM 2 Demonstration W TM 3 Demonstration					_		`	<u>`</u>	
PICDEM™ 2 Demonstration Board PICDEM™ 3 Demonstration Board PICDEM™ 14A Demonstration	+			>					
PICDEM™ 3 Demonstration Board PICDEM™ 14A Demonstration Board						>	`		
PICDEM™ 14A Demonstration Board			>						
PICDEM™ 17 Demonstration Board					>				
								>	
								>	
microID™ Programmer's Kit									>
5 125 kHz microID™ Developer's Kit									>
125 kHz Anticollision microlD TM Developer's Kit									>
13.56 MHz Anticollision microlD™ Developer's Kit									>
MCP2510 CAN Developer's Kit									

NOTES:

12.0 ELECTRICAL CHARACTERISTICS - PIC16C54A

Absolute Maximum Ratings(†)

Ambient Temperature under bias	
Storage Temperature	65°C to +150°C
Voltage on VDD with respect to Vss	
Voltage on MCLR with respect to Vss ⁽¹⁾	0V to +14V
Voltage on all other pins with respect to Vss	0.6V to (VDD + 0.6V)
Total power dissipation ⁽²⁾	800 mW
Max. current out of Vss pin	150 mA
Max. current into VDD pin	
Max. current into an input pin (T0CKI only)	±500 μA
Input clamp current, IiK (VI < 0 or VI > VDD)	±20 mA
Output clamp current, IOK (VO < 0 or VO > VDD)	±20 mA
Max. output current sunk by any I/O pin	25 mA
Max. output current sourced by any I/O pin	20 mA
Max. output current sourced by a single I/O port (PORTA, B or C)	40 mA
Max. output current sunk by a single I/O port (PORTA, B or C)	50 mA
Note 1: Voltage spikes below Vss at the MCLR pin_inducing currents greater than 80) mA may cause latch-u

Note 1: Voltage spikes below Vss at the $\overline{\text{MCLR}}$ pin, inducing currents greater than 80 mA, may cause latch-up. Thus, a series resistor of 50 to 100 Ω should be used when applying a "low" level to the $\overline{\text{MCLR}}$ pin rather than pulling this pin directly to Vss.

^{2:} Power Dissipation is calculated as follows: Pdis = VDD x {IDD - Σ IOH} + Σ {(VDD - VOH) x IOH} + Σ (VOL x IOL)

[†] NOTICE: Stresses above those listed under "Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operation listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

12.1 DC Characteristics: PIC16C54/55/56/57-RC, XT, 10, HS, LP (Commercial)

PIC16C54/55/56/57-RC, XT, 10, HS, LP (Commercial)		Standard Operating Conditions (unless otherwise specified) Operating Temperature $0^{\circ}C \le TA \le +70^{\circ}C$ for commercial					
Param No.	Symbol	Characteristic/Device	Min	Тур†	Max	Units	Conditions
D001	VDD	Supply Voltage PIC16C5X-RC PIC16C5X-XT PIC16C5X-10 PIC16C5X-HS PIC16C5X-LP	3.0 3.0 4.5 4.5 2.5		6.25 6.25 5.5 5.5 6.25	V V V	
D002	Vdr	RAM Data Retention Voltage ⁽¹⁾		1.5*	_	V	Device in SLEEP Mode
D003	VPOR	VDD Start Voltage to ensure Power-on Reset		Vss	_	V	See Section 5.1 for details on Power-on Reset
D004	SVDD	VDD Rise Rate to ensure Power-on Reset	0.05*	_	_	V/ms	See Section 5.1 for details on Power-on Reset
D010	IDD	Supply Current ⁽²⁾ PIC16C5X-RC ⁽³⁾ PIC16C5X-XT PIC16C5X-10 PIC16C5X-HS PIC16C5X-HS PIC16C5X-LP		1.8 1.8 4.8 4.8 9.0	3.3 3.3 10 10 20 32	mA mA mA mA mA	FOSC = 4 MHz, VDD = 5.5V FOSC = 4 MHz, VDD = 5.5V FOSC = 10 MHz, VDD = 5.5V FOSC = 10 MHz, VDD = 5.5V FOSC = 20 MHz, VDD = 5.5V FOSC = 32 kHz, VDD = 3.0V, WDT disabled
D020	IPD	Power-down Current ⁽²⁾	_	4.0 0.6	12 9	μA μA	VDD = 3.0V, WDT enabled VDD = 3.0V, WDT disabled

^{*} These parameters are characterized but not tested.

- Note 1: This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.
 - 2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.
 - a) The test conditions for all IDD measurements in active Operation mode are: OSC1 = external square wave, from rail-to-rail; all I/O pins tristated, pulled to Vss, TOCKI = VDD, $\overline{MCLR} = VDD$; WDT enabled/disabled as specified.
 - b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.
 - 3: Does not include current through REXT. The current through the resistor can be estimated by the formula: IR = VDD/2REXT (mA) with REXT in $k\Omega$.

[†] Data in "Typ" column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

12.2 DC Characteristics: PIC16C54/55/56/57-RCI, XTI, 10I, HSI, LPI (Industrial)

PIC16C54/55/56/57-RCI, XTI, 10I, HSI, LPI (Industrial)			Standard Operating Conditions (unless otherwise specified) Operating Temperature $-40^{\circ}\text{C} \leq \text{Ta} \leq +85^{\circ}\text{C}$ for industrial				
Param No.	Symbol	Characteristic/Device	Min	Тур†	Max	Units	Conditions
D001	VDD	Supply Voltage PIC16C5X-RCI PIC16C5X-XTI PIC16C5X-10I PIC16C5X-HSI PIC16C5X-LPI	3.0 3.0 4.5 4.5 2.5		6.25 6.25 5.5 5.5 6.25	V V V V	
D002	VDR	RAM Data Retention Voltage ⁽¹⁾	_	1.5*	_	V	Device in SLEEP mode
D003	VPOR	VDD Start Voltage to ensure Power-on Reset	_	Vss	_	V	See Section 5.1 for details on Power-on Reset
D004	SVDD	VDD Rise Rate to ensure Power-on Reset	0.05*	_	_	V/ms	See Section 5.1 for details on Power-on Reset
D010	IDD	Supply Current ⁽²⁾ PIC16C5X-RCI ⁽³⁾ PIC16C5X-XTI PIC16C5X-10I PIC16C5X-HSI PIC16C5X-HSI PIC16C5X-LPI	_ _ _ _	1.8 1.8 4.8 4.8 9.0	3.3 3.3 10 10 20 40	mA mA mA mA μA	Fosc = 4 MHz, VDD = 5.5V Fosc = 4 MHz, VDD = 5.5V Fosc = 10 MHz, VDD = 5.5V Fosc = 10 MHz, VDD = 5.5V Fosc = 20 MHz, VDD = 5.5V Fosc = 32 kHz, VDD = 3.0V, WDT disabled
D020	IPD	Power-down Current ⁽²⁾	_ _	4.0 0.6	14 12	μ Α μ Α	VDD = 3.0V, WDT enabled VDD = 3.0V, WDT disabled

^{*} These parameters are characterized but not tested.

- Note 1: This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.
 - 2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.
 - a) The test conditions for all IDD measurements in active Operation mode are: OSC1 = external square wave, from rail-to-rail; all I/O pins tristated, pulled to Vss, TOCKI = VDD, $\overline{MCLR} = VDD$; WDT enabled/disabled as specified.
 - b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.
 - 3: Does not include current through REXT. The current through the resistor can be estimated by the formula: IR = VDD/2REXT (mA) with REXT in kΩ.

[†] Data in "Typ" column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

12.3 DC Characteristics: PIC16C54/55/56/57-RCE, XTE, 10E, HSE, LPE (Extended)

PIC16C54/55/56/57-RCE, XTE, 10E, HSE, LPE (Extended)			Standard Operating Conditions (unless otherwise specified) Operating Temperature $-40^{\circ}\text{C} \le \text{TA} \le +125^{\circ}\text{C}$ for extended					
Param No.	Symbol	Characteristic/Device	Min	Тур†	Max	Units	Conditions	
D001	VDD	Supply Voltage PIC16C5X-RCE PIC16C5X-XTE PIC16C5X-10E PIC16C5X-HSE PIC16C5X-LPE	3.25 3.25 4.5 4.5 2.5		6.0 6.0 5.5 5.5 6.0	V V V		
D002	Vdr	RAM Data Retention Voltage ⁽¹⁾	_	1.5*	_	V	Device in SLEEP mode	
D003	VPOR	VDD Start Voltage to ensure Power-on Reset	_	Vss	_	V	See Section 5.1 for details on Power-on Reset	
D004	SVDD	VDD Rise Rate to ensure Power-on Reset	0.05*	_	_	V/ms	See Section 5.1 for details on Power-on Reset	
D010	IDD	Supply Current ⁽²⁾ PIC16C5X-RCE ⁽³⁾ PIC16C5X-XTE PIC16C5X-10E PIC16C5X-HSE PIC16C5X-HSE PIC16C5X-LPE		1.8 1.8 4.8 4.8 9.0	3.3 3.3 10 10 20 55	mA mA mA mA mA	FOSC = 4 MHz, VDD = 5.5V FOSC = 4 MHz, VDD = 5.5V FOSC = 10 MHz, VDD = 5.5V FOSC = 10 MHz, VDD = 5.5V FOSC = 16 MHz, VDD = 5.5V FOSC = 32 kHz, VDD = 3.25V, WDT disabled	
D020	IPD	Power-down Current ⁽²⁾	_ _	5.0 0.8	22 18	μA μA	VDD = 3.25V, WDT enabled VDD = 3.25V, WDT disabled	

^{*} These parameters are characterized but not tested.

- Note 1: This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.
 - 2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.
 - a) The test conditions for all IDD measurements in active Operation mode are: OSC1 = external square wave, from rail-to-rail; all I/O pins tristated, pulled to Vss, T0CKI = VDD, MCLR = VDD; WDT enabled/disabled as specified.
 - b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.
 - 3: Does not include current through REXT. The current through the resistor can be estimated by the formula: IR = VDD/2REXT (mA) with REXT in $k\Omega$.

[†] Data in "Typ" column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

12.4 DC Characteristics: PIC16C54/55/56/57-RC, XT, 10, HS, LP (Commercial) PIC16C54/55/56/57-RCI, XTI, 10I, HSI, LPI (Industrial)

DC CHARACTERISTICS			Standard Operating Conditions (unless otherwise specified) Operating Temperature $0^{\circ}C \le TA \le +70^{\circ}C$ for commercial $-40^{\circ}C \le TA \le +85^{\circ}C$ for industrial					
Param No.	Symbol	Characteristic/Device	Min	Тур†	Max	Units	Conditions	
D030	VIL	Input Low Voltage I/O ports MCLR (Schmitt Trigger) T0CKI (Schmitt Trigger) OSC1 (Schmitt Trigger) OSC1 (Schmitt Trigger)	Vss Vss Vss Vss Vss	_ _ _ _	0.2 VDD 0.15 VDD 0.15 VDD 0.15 VDD 0.3 VDD	V V V V	Pin at hi-impedance PIC16C5X-RC only ⁽³⁾ PIC16C5X-XT, 10, HS, LP	
D040	ViH	Input High Voltage I/O ports I/O ports I/O ports MCLR (Schmitt Trigger) TOCKI (Schmitt Trigger) OSC1 (Schmitt Trigger) OSC1 (Schmitt Trigger)	0.45 VDD 2.0 0.36 VDD 0.85 VDD 0.85 VDD 0.85 VDD 0.7 VDD		VDD VDD VDD VDD VDD VDD	V V V V V	For all VDD ⁽⁴⁾ 4.0V < VDD ≤ 5.5V ⁽⁴⁾ VDD > 5.5V PIC16C5X-RC only ⁽³⁾ PIC16C5X-XT, 10, HS, LP	
D050	VHYS	Hysteresis of Schmitt Trigger inputs	0.15 VDD*	_	_	V		
D060	IIL	Input Leakage Current ^(1,2) I/O ports MCLR MCLR TOCKI OSC1	-1 -5 -3 -3	0.5 — 0.5 0.5 0.5	+1 +5 +3 +3	μΑ μΑ μΑ μΑ μΑ	For Vdd \leq 5.5V: VSS \leq VPIN \leq VDD, pin at hi-impedance VPIN = VSS + 0.25V VPIN = VDD VSS \leq VPIN \leq VDD VSS \leq VPIN \leq VDD, PIC16C5X-XT, 10, HS, LP	
D080	Vol	Output Low Voltage I/O ports OSC2/CLKOUT	_	_	0.6 0.6	V V	IOL = 8.7 mA, VDD = 4.5V IOL = 1.6 mA, VDD = 4.5V, PIC16C5X-RC	
D090	Voн	Output High Voltage ⁽²⁾ I/O ports OSC2/CLKOUT	VDD - 0.7 VDD - 0.7	_ _		V V	IOH = -5.4 mA, VDD = 4.5V IOH = -1.0 mA, VDD = 4.5V, PIC16C5X-RC	

^{*} These parameters are characterized but not tested.

- 2: Negative current is defined as coming out of the pin.
- **3:** For PIC16C5X-RC devices, the OSC1/CLKIN pin is a Schmitt Trigger input. It is not recommended that the PIC16C5X be driven with external clock in RC mode.
- 4: The user may use the better of the two specifications.

[†] Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

Note 1: The leakage current on the MCLR/VPP pin is strongly dependent on the applied voltage level. The specified levels represent normal operating conditions. Higher leakage current may be measured at different input voltage.

12.5 DC Characteristics: PIC16C54/55/56/57-RCE, XTE, 10E, HSE, LPE (Extended)

DC CHARACTERISTICS			Standard Operating Conditions (unless otherwise specified) Operating Temperature $-40^{\circ}\text{C} \le \text{TA} \le +125^{\circ}\text{C}$ for extended					
Param No.	Symbol	Characteristic	Min	Typ†	Max	Units	Conditions	
D030	VIL	Input Low Voltage I/O ports MCLR (Schmitt Trigger) TOCKI (Schmitt Trigger) OSC1 (Schmitt Trigger) OSC1 (Schmitt Trigger)	Vss Vss Vss Vss Vss	11111	0.15 VDD 0.15 VDD 0.15 VDD 0.15 VDD 0.3 VDD	>>>>>	Pin at hi-impedance PIC16C5X-RC only ⁽³⁾ PIC16C5X-XT, 10, HS, LP	
D040	VHYS	Input High Voltage I/O ports I/O ports I/O ports MCLR (Schmitt Trigger) TOCKI (Schmitt Trigger) OSC1 (Schmitt Trigger) OSC1 (Schmitt Trigger) Hysteresis of Schmitt	0.45 VDD 2.0 0.36 VDD 0.85 VDD 0.85 VDD 0.85 VDD 0.7 VDD		VDD VDD VDD VDD VDD VDD VDD	V V V V V	For all VDD ⁽⁴⁾ 4.0V < VDD ≤ 5.5V ⁽⁴⁾ VDD > 5.5 V PIC16C5X-RC only ⁽³⁾ PIC16C5X-XT, 10, HS, LP	
D060	lıL	Trigger inputs Input Leakage Current (1,2) I/O ports MCLR MCLR TOCKI OSC1	-1 -5 -3 -3	0.5 0.5 0.5 0.5	+1 +5 +3 +3	μΑ μΑ μΑ μΑ μΑ	For VDD \leq 5.5 V: VSS \leq VPIN \leq VDD, pin at hi-impedance VPIN = VSS + 0.25V VPIN = VDD VSS \leq VPIN \leq VDD VSS \leq VPIN \leq VDD, PIC16C5X-XT, 10, HS, LP	
D080	Vol	Output Low Voltage I/O ports OSC2/CLKOUT	_	_	0.6 0.6	V V	IOL = 8.7 mA, VDD = 4.5V IOL = 1.6 mA, VDD = 4.5V, PIC16C5X-RC	
D090	Voн	Output High Voltage ⁽²⁾ I/O ports OSC2/CLKOUT	VDD - 0.7 VDD - 0.7	_		V V	IOH = -5.4 mA, VDD = 4.5V IOH = -1.0 mA, VDD = 4.5V, PIC16C5X-RC	

^{*} These parameters are characterized but not tested.

[†] Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

Note 1: The leakage current on the MCLR/VPP pin is strongly dependent on the applied voltage level. The specified levels represent normal operating conditions. Higher leakage current may be measured at different input voltage.

^{2:} Negative current is defined as coming out of the pin.

^{3:} For PIC16C5X-RC devices, the OSC1/CLKIN pin is a Schmitt Trigger input. It is not recommended that the PIC16C5X be driven with external clock in RC mode.

^{4:} The user may use the better of the two specifications.

12.6 Timing Parameter Symbology and Load Conditions

The timing parameter symbols have been created with one of the following formats:

- 1. TppS2ppS
- 2. TppS

T	
F Frequency	T Time
Lowercase letters (pp) and their meanings:	
рр	
2 to	mc MCLR
ck CLKOUT	osc oscillator
cy cycle time	os OSC1

t0 T0CKI

wdt watchdog timer

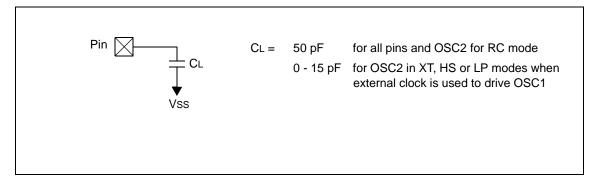
Uppercase letters and their meanings:

drt device reset timer

io I/O port

OPP	stoadd tottord arra trion trioarmigo.		
S			
F	Fall	Р	Period
Н	High	R	Rise
ı	Invalid (Hi-impedance)	V	Valid
L	Low	Z	Hi-impedance

FIGURE 12-1: LOAD CONDITIONS FOR DEVICE TIMING SPECIFICATIONS - PIC16C54/55/56/57



12.7 Timing Diagrams and Specifications

FIGURE 12-2: EXTERNAL CLOCK TIMING - PIC16C54/55/56/57

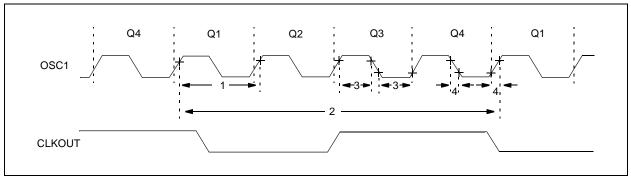


TABLE 12-1: EXTERNAL CLOCK TIMING REQUIREMENTS - PIC16C54/55/56/57

AC Chara	cteristics	Standard Operating Conditions (unless otherwise specified) Operating Temperature $0^{\circ}C \le TA \le +70^{\circ}C$ for commercial $-40^{\circ}C \le TA \le +85^{\circ}C$ for industrial $-40^{\circ}C \le TA \le +125^{\circ}C$ for extended							
Param No.	Symbol	Characteristic Min Typ† Max Units Conditions							
1A	Fosc	External CLKIN Frequency ⁽¹⁾	DC	_	4.0	MHz	XT osc mode		
			DC	_	10	MHz	10 MHz mode		
			DC	_	20	MHz	HS osc mode (Comm/Ind)		
			DC	_	16	MHz	HS osc mode (Ext)		
			DC	_	40	kHz	LP osc mode		
		Oscillator Frequency ⁽¹⁾	DC	_	4.0	MHz	RC osc mode		
			0.1	_	4.0	MHz	XT osc mode		
			4.0	_	10	MHz	10 MHz mode		
			4.0	_	20	MHz	HS osc mode (Comm/Ind)		
			4.0	_	16	MHz	HS osc mode (Ext)		
			DC	_	40	kHz	LP osc mode		

^{*} These parameters are characterized but not tested.

- Note 1: All specified values are based on characterization data for that particular oscillator type under standard operating conditions with the device executing code. Exceeding these specified limits may result in an unstable oscillator operation and/or higher than expected current consumption.

 When an external clock input is used, the "max" cycle time limit is "DC" (no clock) for all devices.
 - 2: Instruction cycle period (Tcy) equals four times the input oscillator time base period.

[†] Data in the Typical ("Typ") column is at 5.0V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

TABLE 12-1: EXTERNAL CLOCK TIMING REQUIREMENTS - PIC16C54/55/56/57

AC Characteristics Standard Operating Conditions (unless otherwise specified)
Operating Temperature $0^{\circ}\text{C} \le \text{TA} \le +70^{\circ}\text{C}$ for commercial $-40^{\circ}\text{C} \le \text{TA} \le +85^{\circ}\text{C}$ for industrial $-40^{\circ}\text{C} \le \text{TA} \le +125^{\circ}\text{C}$ for extended

Param No.	Symbol	Characteristic	Min	Typ†	Max	Units	Conditions
1	Tosc	External CLKIN Period ⁽¹⁾	250	_	_	ns	XT osc mode
			100	_	_	ns	10 MHz mode
			50	_	_	ns	HS osc mode (Comm/Ind)
			62.5	_	_	ns	HS osc mode (Ext)
			25	_	_	μS	LP osc mode
		Oscillator Period ⁽¹⁾	250	_	_	ns	RC osc mode
			250	_	10,000	ns	XT osc mode
			100	_	250	ns	10 MHz mode
			50	_	250	ns	HS osc mode (Comm/Ind)
			62.5	_	250	ns	HS osc mode (Ext)
			25	_	_	μS	LP osc mode
2	Tcy	Instruction Cycle Time ⁽²⁾	_	4/Fosc		_	
3	TosL,	Clock in (OSC1) Low or High	85*		_	ns	XT oscillator
	TosH	Time	20*	_	_	ns	HS oscillator
			2.0*	_	_	μS	LP oscillator
4	TosR,	Clock in (OSC1) Rise or Fall	_	_	25*	ns	XT oscillator
	TosF	Time	_	_	25*	ns	HS oscillator
			_		50*	ns	LP oscillator

^{*} These parameters are characterized but not tested.

Note 1: All specified values are based on characterization data for that particular oscillator type under standard operating conditions with the device executing code. Exceeding these specified limits may result in an unstable oscillator operation and/or higher than expected current consumption. When an external clock input is used, the "max" cycle time limit is "DC" (no clock) for all devices.

2: Instruction cycle period (TcY) equals four times the input oscillator time base period.

[†] Data in the Typical ("Typ") column is at 5.0V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

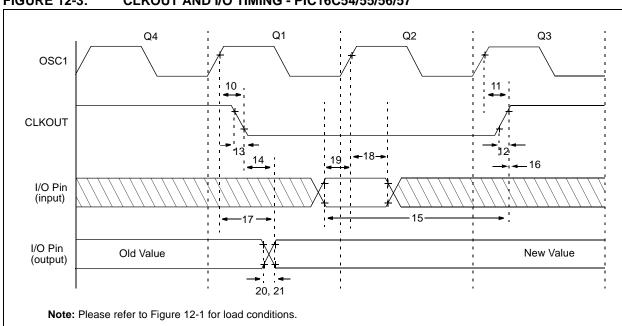


FIGURE 12-3: CLKOUT AND I/O TIMING - PIC16C54/55/56/57

TABLE 12-2: CLKOUT AND I/O TIMING REQUIREMENTS - PIC16C54/55/56/57

AC Chara	acteristics	Standard Operating Conditions (unless otherwise specified) Operating Temperature $0^{\circ}\text{C} \leq \text{TA} \leq +70^{\circ}\text{C}$ for commercial $-40^{\circ}\text{C} \leq \text{TA} \leq +85^{\circ}\text{C}$ for industrial $-40^{\circ}\text{C} \leq \text{TA} \leq +125^{\circ}\text{C}$ for extended								
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units				
10	TosH2ckL	OSC1↑ to CLKOUT↓ ⁽¹⁾	_	15	30**	ns				
11	TosH2ckH	OSC1 [↑] to CLKOUT ^{↑(1)}	_	15	30**	ns				
12	TckR	CLKOUT rise time ⁽¹⁾	_	5.0	15**	ns				
13	TckF	CLKOUT fall time ⁽¹⁾	_	5.0	15**	ns				
14	TckL2ioV	CLKOUT↓ to Port out valid ⁽¹⁾	_	_	40**	ns				
15	TioV2ckH	Port in valid before CLKOUT ⁽¹⁾	0.25 TCY+30*	_	_	ns				
16	TckH2ioI	Port in hold after CLKOUT ⁽¹⁾	0*	_	_	ns				
17	TosH2ioV	OSC1 [↑] (Q1 cycle) to Port out valid ⁽²⁾	_	_	100*	ns				
18	TosH2ioI	OSC1 [↑] (Q2 cycle) to Port input invalid (I/O in hold time)	TBD	_	_	ns				
19	TioV2osH	Port input valid to OSC1↑ (I/O in setup time)	TBD	_	_	ns				
20	TioR	Port output rise time ⁽²⁾	_	10	25**	ns				
21	TioF	Port output fall time ⁽²⁾	_	10	25**	ns				

^{*} These parameters are characterized but not tested.

Note 1: Measurements are taken in RC Mode where CLKOUT output is 4 x Tosc.

2: Please refer to Figure 12-1 for load conditions.

^{**} These parameters are design targets and are not tested. No characterization data available at this time.

[†] Data in the Typical ("Typ") column is at 5.0V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

FIGURE 12-4: RESET, WATCHDOG TIMER, AND DEVICE RESET TIMER TIMING - PIC16C54/55/56/57

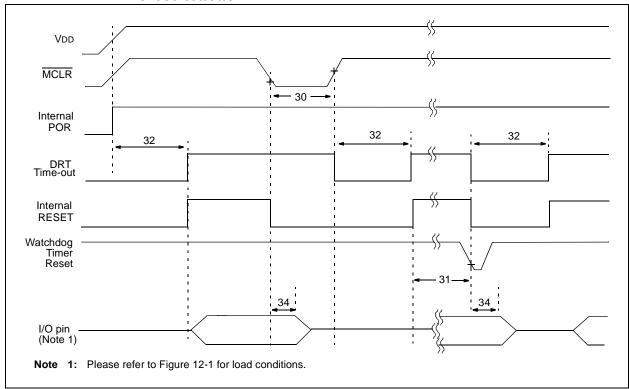


TABLE 12-3: RESET, WATCHDOG TIMER, AND DEVICE RESET TIMER - PIC16C54/55/56/57

AC Chara	cteristics	Standard Operating Conditions (unless otherwise specified) Operating Temperature $0^{\circ}C \leq TA \leq +70^{\circ}C$ for commercial $-40^{\circ}C \leq TA \leq +85^{\circ}C$ for industrial $-40^{\circ}C \leq TA \leq +125^{\circ}C$ for extended								
Param No. Symbol		Characteristic		Тур†	Max	Units	Conditions			
30	TmcL	MCLR Pulse Width (low)	100*	_	_	ns	VDD = 5.0V			
31	Twdt	Watchdog Timer Time-out Period (No Prescaler)	9.0*	18*	30*	ms	VDD = 5.0V (Comm)			
32	TDRT	Device Reset Timer Period	9.0*	18*	30*	ms	VDD = 5.0V (Comm)			
34	Tioz	I/O Hi-impedance from MCLR Low	_	_	100*	ns				

^{*} These parameters are characterized but not tested.

[†] Data in the Typical ("Typ") column is at 5.0V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

FIGURE 12-5: TIMER0 CLOCK TIMINGS - PIC16C54/55/56/57

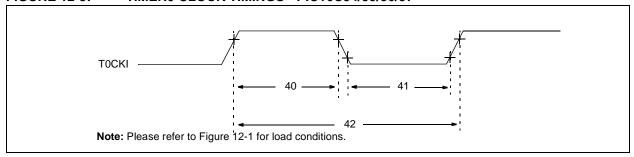


TABLE 12-4: TIMERO CLOCK REQUIREMENTS - PIC16C54/55/56/57

AC Characteristics Standard Operating Conditions (unless otherwise specified) Operating Temperature $0^{\circ}C \le TA \le +70^{\circ}C$ for commercial $-40^{\circ}C \le TA \le +85^{\circ}C$ for industrial $-40^{\circ}C \le TA \le +125^{\circ}C$ for extended									
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units	Conditions		
40	Tt0H	TOCKI High Pulse Width - No Prescaler - With Prescaler	0.5 Tcy + 20* 10*			ns ns			
41	Tt0L	Tocki Low Pulse Width - No Prescaler - With Prescaler	0.5 TcY + 20* 10*	_	_	ns ns			
42	Tt0P	T0CKI Period	20 or <u>Tcy + 40</u> * N	_	_	ns	Whichever is greater. N = Prescale Value (1, 2, 4,, 256)		

These parameters are characterized but not tested.

[†] Data in the Typical ("Typ") column is at 5.0V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

13.0 ELECTRICAL CHARACTERISTICS - PIC16CR54A

Absolute Maximum Ratings(†)

Ambient Temperature under bias	55°C to +125°C
Storage Temperature	65°C to +150°C
Voltage on VDD with respect to Vss	0 to +7.5V
Voltage on MCLR with respect to Vss ⁽¹⁾	0 to +14V
Voltage on all other pins with respect to Vss	0.6V to (VDD + 0.6V)
Total power dissipation ⁽²⁾	800 mW
Max. current out of Vss pin	150 mA
Max. current into VDD pin	50 mA
Max. current into an input pin (T0CKI only)	±500 μA
Input clamp current, Iik (VI < 0 or VI > VDD)	±20 mA
Output clamp current, IOK (V0 < 0 or V0 > VDD)	±20 mA
Max. output current sunk by any I/O pin	25 mA
Max. output current sourced by any I/O pin	20 mA
Max. output current sourced by a single I/O port (PORTA or B)	40 mA
Max. output current sunk by a single I/O port (PORTA or B)	50 mA

- **Note 1:** Voltage spikes below Vss at the \overline{MCLR} pin, inducing currents greater than 80 mA may cause latch-up. Thus, a series resistor of 50 to 100 Ω should be used when applying a low level to the \overline{MCLR} pin rather than pulling this pin directly to Vss.
 - 2: Power Dissipation is calculated as follows: PDIS = VDD x {IDD \sum IOH} + \sum {(VDD-VOH) x IOH} + \sum (VOL x IOL)

† NOTICE: Stresses above those listed under "Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operation listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

13.1 DC Characteristics: PIC16CR54A-04, 10, 20, PIC16LCR54A-04 (Commercial) PIC16CR54A-04I, 10I, 20I, PIC16LCR54A-04I (Industrial)

PIC16LCR54A-04 PIC16LCR54A-04I (Commercial, Industrial)										
PIC16CR54A-04, 10, 20 PIC16CR54A-04I, 10I, 20I (Commercial, Industrial)				Standard Operating Conditions (unless otherwise specified) Operating Temperature $0^{\circ}C \leq TA \leq +70^{\circ}C \text{ for commercial} \\ -40^{\circ}C \leq TA \leq +85^{\circ}C \text{ for industrial}$						
Param No.	Symbol	Characteristic/Device	Min	Тур†	Max	Units	Conditions			
	VDD	Supply Voltage								
D001		PIC16LCR54A	2.0		6.25	V				
D001 D001A		PIC16CR54A	2.5 4.5		6.25 5.5	> >	RC and XT modes HS mode			
D002	VDR	RAM Data Retention Voltage ⁽¹⁾		1.5*	_	V	Device in SLEEP mode			
D003	VPOR	VDD Start Voltage to ensure Power-on Reset	_	Vss	_	V	See Section 5.1 for details on Power-on Reset			
D004	SVDD	VDD Rise Rate to ensure Power-on Reset	0.05*	_	_	V/ms	See Section 5.1 for details on Power-on Reset			
	IDD	Supply Current ⁽²⁾								
D005		PICLCR54A		10 —	20 70	μA μA	Fosc = 32 kHz, VDD = 2.0V Fosc = 32 kHz, VDD = 6.0V			
D005A							RC ⁽³⁾ and XT modes:			
		PIC16CR54A	_	2.0	3.6	mA	Fosc = 4.0 MHz, VDD = 6.0V			
				0.8 90	1.8 350	mA μA	FOSC = 4.0 MHz, VDD = 3.0V FOSC = 200 kHz, VDD = 2.5V			
				30	330	μΛ	HS mode:			
			_	4.8	10	mA	Fosc = 10 MHz, VDD = 5.5V			
			_	9.0	20	mA	Fosc = 20 MHz, VDD = 5.5V			

- * These parameters are characterized but not tested.
- † Data in "Typ" column is at 5V, 25°C, unless otherwise stated. These parameters are for design guidance only, and are not tested.
- Note 1: This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.
 - 2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.
 - a) The test conditions for all IDD measurements in active Operation mode are: OSC1 = external square wave, from rail-to-rail; all I/O pins tristated, pulled to Vss, T0CKI = VDD, MCLR = VDD; WDT enabled/disabled as specified.
 - b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.
 - 3: Does not include current through REXT. The current through the resistor can be estimated by the formula: IR = VDD/2REXT (mA) with REXT in $k\Omega$.

13.1 DC Characteristics: PIC16CR54A-04, 10, 20, PIC16LCR54A-04 (Commercial) PIC16CR54A-04I, 10I, 20I, PIC16LCR54A-04I (Industrial)

PIC16LC	PIC16LCR54A-04 PIC16LCR54A-04I (Commercial, Industrial)				Standard Operating Conditions (unless otherwise specified) Operating Temperature $0^{\circ}C \leq TA \leq +70^{\circ}C \text{ for commercial} \\ -40^{\circ}C \leq TA \leq +85^{\circ}C \text{ for industrial}$						
PIC16CR54A-04, 10, 20 PIC16CR54A-04I, 10I, 20I (Commercial, Industrial)											
Param No.	Symbol	Characteristic/Device	Min	Тур†	Max	Units	Conditions				
	IPD	Power-down Current ⁽²⁾									
D006		PIC16LCR54A-Commercial	_ _ _	1.0 2.0 3.0 5.0	6.0 8.0* 15 25	μΑ μΑ μΑ μΑ	VDD = 2.5V, WDT disabled VDD = 4.0V, WDT disabled VDD = 6.0V, WDT disabled VDD = 6.0V, WDT enabled				
D006A		PIC16CR54A-Commercial	_ _ _ _	1.0 2.0 3.0 5.0	6.0 8.0* 15 25	μΑ μΑ μΑ μΑ	VDD = 2.5V, WDT disabled VDD = 4.0V, WDT disabled VDD = 6.0V, WDT disabled VDD = 6.0V, WDT enabled				
D007		PIC16LCR54A-Industrial		1.0 2.0 3.0 3.0 5.0	8.0 10* 20* 18 45	μΑ μΑ μΑ μΑ μΑ	VDD = 2.5V, WDT disabled VDD = 4.0V, WDT disabled VDD = 4.0V, WDT enabled VDD = 6.0V, WDT disabled VDD = 6.0V, WDT enabled				
D007A		PIC16CR54A-Industrial	_ _ _ _	1.0 2.0 3.0 3.0 5.0	8.0 10* 20* 18 45	μΑ μΑ μΑ μΑ μΑ	VDD = 2.5V, WDT disabled VDD = 4.0V, WDT disabled VDD = 4.0V, WDT enabled VDD = 6.0V, WDT disabled VDD = 6.0V, WDT enabled				

- * These parameters are characterized but not tested.
- † Data in "Typ" column is at 5V, 25°C, unless otherwise stated. These parameters are for design guidance only, and are not tested.
- Note 1: This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.
 - 2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.
 - a) The test conditions for all IDD measurements in active Operation mode are: OSC1 = external square wave, from rail-to-rail; all I/O pins tristated, pulled to Vss, T0CKI = VDD, MCLR = VDD; WDT enabled/disabled as specified.
 - b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.
 - 3: Does not include current through REXT. The current through the resistor can be estimated by the formula: IR = VDD/2REXT (mA) with REXT in $k\Omega$.

13.2 DC Characteristics: PIC16CR54A-04E, 10E, 20E (Extended)

PIC16CR54A-04E, 10E, 20E (Extended)				Standard Operating Conditions (unless otherwise specified) Operating Temperature −40°C ≤ TA ≤ +125°C for extended					
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units	Conditions		
D001	VDD	Supply Voltage RC, XT and LP modes HS mode	3.25 4.5	_	6.0 5.5	> >			
D002	Vdr	RAM Data Retention Voltage ⁽¹⁾	_	1.5*	_	V	Device in SLEEP mode		
D003	VPOR	VDD Start Voltage to ensure Power-on Reset	_	Vss	_	V	See Section 5.1 for details on Power-on Reset		
D004	SVDD	VDD Rise Rate to ensure Power- on Reset	0.05*	_	_	V/ms	See Section 5.1 for details on Power-on Reset		
D010	IDD	Supply Current ⁽²⁾ RC ⁽³⁾ and XT modes HS mode HS mode		1.8 4.8 9.0	3.3 10 20	mA mA mA	Fosc = 4.0 MHz, VDD = 5.5V Fosc = 10 MHz, VDD = 5.5V Fosc = 16 MHz, VDD = 5.5V		
D020	IPD	Power-down Current ⁽²⁾	_	5.0 0.8	22 18	μ Α μ Α	VDD = 3.25V, WDT enabled VDD = 3.25V, WDT disabled		

These parameters are characterized but not tested.

- Note 1: This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.
 - 2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.
 - a) The test conditions for all IDD measurements in active Operation mode are: OSC1 = external square wave, from rail-to-rail; all I/O pins tristated, pulled to Vss, T0CKI = VDD, MCLR = VDD; WDT enabled/disabled as specified.
 - b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.
 - 3: Does not include current through REXT. The current through the resistor can be estimated by the formula: IR = VDD/2REXT (mA) with REXT in kΩ.

[†] Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

13.3 DC Characteristics: PIC16CR54A-04, 10, 20, PIC16LCR54A-04 (Commercial) PIC16CR54A-04I, 10I, 20I, PIC16LCR54A-04I (Industrial)

DC CH	ARACTE	RISTICS	Standard Operating Conditions (unless otherwise specified) Operating Temperature $0^{\circ}C \leq TA \leq +70^{\circ}C$ for commercial $-40^{\circ}C \leq TA \leq +85^{\circ}C$ for industrial					
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units	Conditions	
D030	VIL	Input Low Voltage I/O ports MCLR (Schmitt Trigger) TOCKI (Schmitt Trigger) OSC1 (Schmitt Trigger) OSC1	Vss Vss Vss Vss Vss	_ _ _ _	0.2 VDD 0.15 VDD 0.15 VDD 0.15 VDD 0.15 VDD	V V V	Pin at hi-impedance RC mode only ⁽³⁾ XT, HS and LP modes	
D040	VIH	Input High Voltage I/O ports I/O ports MCLR (Schmitt Trigger) T0CKI (Schmitt Trigger) OSC1 (Schmitt Trigger) OSC1	2.0 0.6 VDD 0.85 VDD 0.85 VDD 0.85 VDD	_ _ _ _	VDD VDD VDD VDD VDD VDD	V V V V	VDD = 3.0V to 5.5V ⁽⁴⁾ Full VDD range ⁽⁴⁾ RC mode only ⁽³⁾ XT, HS and LP modes	
D050	VHYS	Hysteresis of Schmitt Trigger inputs	0.15 VDD*	_	_	V		
D060	lı∟	Input Leakage Current ^(1,2) I/O ports MCLR MCLR	-1.0 -5.0 	— — 0.5	+1.0 — +5.0	μΑ μΑ μΑ	For VDD \leq 5.5V: VSS \leq VPIN \leq VDD, pin at hi-impedance VPIN = VSS + 0.25V VPIN = VDD	
		T0CKI OSC1	-3.0 -3.0	0.5 0.5	+3.0 +3.0	μΑ μΑ	$\label{eq:VSS} \begin{array}{l} \text{VSS} \leq \text{VPIN} \leq \text{VDD} \\ \text{VSS} \leq \text{VPIN} \leq \text{VDD}, \\ \text{XT, HS and LP modes} \end{array}$	
D080	Vol	Output Low Voltage I/O ports OSC2/CLKOUT			0.5 0.5	V V	IOL = 10 mA, VDD = 6.0V IOL = 1.9 mA, VDD = 6.0V, RC mode only	
D090	Voн	Output High Voltage ⁽²⁾ I/O ports OSC2/CLKOUT	VDD - 0.5 VDD - 0.5			V V	IOH = -4.0 mA, $VDD = 6.0VIOH = -0.8$ mA, $VDD = 6.0V$, RC mode only	

^{*} These parameters are characterized but not tested.

- 2: Negative current is defined as coming out of the pin.
- **3:** For the RC mode, the OSC1/CLKIN pin is a Schmitt Trigger input. It is not recommended that the PIC16C5X be driven with external clock in RC mode.
- 4: The user may use the better of the two specifications.

[†] Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

Note 1: The leakage current on the MCLR/VPP pin is strongly dependent on the applied voltage level. The specified levels represent normal operating conditions. Higher leakage current may be measured at different input voltage.

13.4 DC Characteristics: PIC16CR54A-04E, 10E, 20E (Extended)

DC CHARACTERISTICS			Standard Operating Conditions (unless otherwise specified) Operating Temperature $-40^{\circ}\text{C} \le \text{Ta} \le +125^{\circ}\text{C}$ for extended						
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units	Conditions		
D030	VIL	Input Low Voltage I/O ports MCLR (Schmitt Trigger) T0CKI (Schmitt Trigger) OSC1 (Schmitt Trigger) OSC1	Vss Vss Vss Vss Vss		0.15 VDD 0.15 VDD 0.15 VDD 0.15 VDD 0.3 VDD	> > > > > > > > > > > > > > > > > > >	Pin at hi-impedance RC mode only ⁽³⁾ XT, HS and LP modes		
D040	VIH	Input High Voltage I/O ports I/O ports I/O ports I/O ports MCLR (Schmitt Trigger) T0CKI (Schmitt Trigger) OSC1 (Schmitt Trigger) OSC1 Hysteresis of Schmitt Trigger inputs	0.45 VDD 2.0 0.36 VDD 0.85 VDD 0.85 VDD 0.85 VDD 0.7 VDD		VDD VDD VDD VDD VDD VDD VDD	V V V V V	For all $VDD^{(4)}$ $4.0V < VDD \le 5.5V^{(4)}$ VDD > 5.5V RC mode only ⁽³⁾ XT, HS and LP modes		
D060	lıL	Input Leakage Current ^(1,2) I/O ports MCLR MCLR TOCKI OSC1	-1.0 -5.0 -3.0 -3.0	0.5 — 0.5 0.5 0.5	+1.0 +5.0 +3.0 +3.0	μΑ μΑ μΑ μΑ μΑ	For VDD ≤ 5.5V: VSS ≤ VPIN ≤ VDD, pin at hi-impedance VPIN = VSS + 0.25V VPIN = VDD VSS ≤ VPIN ≤ VDD VSS ≤ VPIN ≤ VDD, XT, HS and LP modes		
D080	Vol	Output Low Voltage I/O ports OSC2/CLKOUT		_ _	0.6 0.6	V V	IOL = 8.7 mA, VDD = 4.5V IOL = 1.6 mA, VDD = 4.5V, RC mode only		
D090	Voн	Output High Voltage ⁽²⁾ I/O ports OSC2/CLKOUT	VDD - 0.7 VDD - 0.7	_ _		V V	IOH = -5.4 mA, VDD = 4.5V IOH = -1.0 mA, VDD = 4.5V, RC mode only		

^{*} These parameters are characterized but not tested.

- 2: Negative current is defined as coming out of the pin.
- **3:** For the RC mode, the OSC1/CLKIN pin is a Schmitt Trigger input. It is not recommended that the PIC16C5X be driven with external clock in RC mode.
- 4: The user may use the better of the two specifications.

[†] Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

Note 1: The leakage current on the MCLR/VPP pin is strongly dependent on the applied voltage level. The specified levels represent normal operating conditions. Higher leakage current may be measured at different input voltage.

13.5 Timing Parameter Symbology and Load Conditions

The timing parameter symbols have been created with one of the following formats:

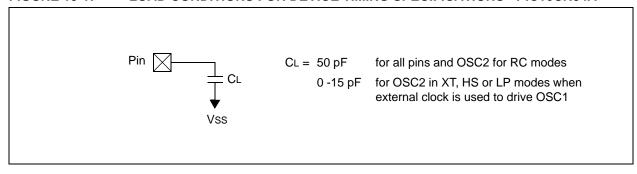
- 1. TppS2ppS
- 2. TppS

Frequency	T Time
rcase letters (pp) and their meanings:	
to	mc MCLR
CLKOUT	osc oscillator
cycle time	os OSC1
device reset timer	t0 T0CKI
I/O port	wdt watchdog timer
	to CLKOUT cycle time device reset timer

Uppercase letters and their meanings:

OPP	ordado fottoro arra trion rificariningo.		
S			
F	Fall	Р	Period
Н	High	R	Rise
ı	Invalid (Hi-impedance)	V	Valid
L	Low	Z	Hi-impedance

FIGURE 13-1: LOAD CONDITIONS FOR DEVICE TIMING SPECIFICATIONS - PIC16CR54A



13.6 Timing Diagrams and Specifications

FIGURE 13-2: EXTERNAL CLOCK TIMING - PIC16CR54A

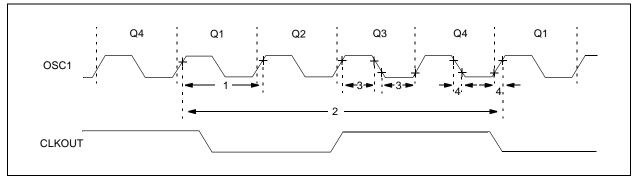


TABLE 13-1: EXTERNAL CLOCK TIMING REQUIREMENTS - PIC16CR54A

AC Chara	cteristics	Standard Operating Conditions (unless otherwise specified) Operating Temperature $0^{\circ}C \le TA \le +70^{\circ}C$ for commercial $-40^{\circ}C \le TA \le +85^{\circ}C$ for industrial $-40^{\circ}C \le TA \le +125^{\circ}C$ for extended							
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units	Conditions		
	Fosc	External CLKIN Frequency ⁽¹⁾	DC	_	4.0	MHz	XT osc mode		
			DC	_	4.0	MHz	HS osc mode (04)		
			DC	_	10	MHz	HS osc mode (10)		
			DC	_	20	MHz	HS osc mode (20)		
			DC	_	200	kHz	LP osc mode		
		Oscillator Frequency ⁽¹⁾	DC	_	4.0	MHz	RC osc mode		
			0.1	_	4.0	MHz	XT osc mode		
			4.0	_	4.0	MHz	HS osc mode (04)		
			4.0	_	10	MHz	HS osc mode (10)		
			4.0	_	20	MHz	HS osc mode (20)		
			5.0	_	200	kHz	LP osc mode		

^{*} These parameters are characterized but not tested.

- Note 1: All specified values are based on characterization data for that particular oscillator type under standard operating conditions with the device executing code. Exceeding these specified limits may result in an unstable oscillator operation and/or higher than expected current consumption.

 When an external clock input is used, the "max" cycle time limit is "DC" (no clock) for all devices.
 - 2: Instruction cycle period (TCY) equals four times the input oscillator time base period.

[†] Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

TABLE 13-1: EXTERNAL CLOCK TIMING REQUIREMENTS - PIC16CR54A

AC Characteristics Standard Operating Conditions (unless otherwise specified)
Operating Temperature $0^{\circ}\text{C} \leq \text{Ta} \leq +70^{\circ}\text{C}$ for commercial $-40^{\circ}\text{C} \leq \text{Ta} \leq +85^{\circ}\text{C}$ for industrial $-40^{\circ}\text{C} \leq \text{Ta} \leq +125^{\circ}\text{C}$ for extended

Param No.	Symbol	Characteristic	Min	Тур†	Max	Units	Conditions
1	Tosc	External CLKIN Period ⁽¹⁾	250		_	ns	XT osc mode
			250	_	_	ns	HS osc mode (04)
			100	_	_	ns	HS osc mode (10)
			50	_	_	ns	HS osc mode (20)
			5.0	_	_	μS	LP osc mode
		Oscillator Period ⁽¹⁾	250	_	_	ns	RC osc mode
			250	_	10,000	ns	XT osc mode
			250	_	250	ns	HS osc mode (04)
			100	_	250	ns	HS osc mode (10)
			50	_	250	ns	HS osc mode (20)
			5.0	_	200	μS	LP osc mode
2	Tcy	Instruction Cycle Time ⁽²⁾	_	4/Fosc	_	_	
3	TosL, TosH	Clock in (OSC1) Low or High	50*	_	_	ns	XT oscillator
		Time	20*	_	_	ns	HS oscillator
			2.0*	_	_	μS	LP oscillator
4	TosR, TosF	Clock in (OSC1) Rise or Fall	_	_	25*	ns	XT oscillator
		Time	_	_	25*	ns	HS oscillator
					50*	ns	LP oscillator

- * These parameters are characterized but not tested.
- † Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.
- **Note 1:** All specified values are based on characterization data for that particular oscillator type under standard operating conditions with the device executing code. Exceeding these specified limits may result in an unstable oscillator operation and/or higher than expected current consumption. When an external clock input is used, the "max" cycle time limit is "DC" (no clock) for all devices.
 - 2: Instruction cycle period (TCY) equals four times the input oscillator time base period.

Q1 Q3 Q4 Q2 OSC1 CLKOUT <-18→ 19 14 I/O Pin (input) I/O Pin (output) New Value Old Value 20, 21 Note: Please refer to Figure 13.1 for load conditions.

FIGURE 13-3: CLKOUT AND I/O TIMING - PIC16CR54A

TABLE 13-2: CLKOUT AND I/O TIMING REQUIREMENTS - PIC16CR54A

AC Char	acteristics	Standard Operating Conditions (unless otherwise specified) Operating Temperature $0^{\circ}C \leq TA \leq +70^{\circ}C$ for commercial $-40^{\circ}C \leq TA \leq +85^{\circ}C$ for industrial $-40^{\circ}C \leq TA \leq +125^{\circ}C$ for extended							
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units			
10	TosH2ckL	OSC1 [↑] to CLKOUT↓ ⁽¹⁾	_	15	30**	ns			
11	TosH2ckH	OSC1 [†] to CLKOUT ^{†(1)}	_	15	30**	ns			
12	TckR	CLKOUT rise time ⁽¹⁾	_	5.0	15**	ns			
13	TckF	CLKOUT fall time ⁽¹⁾	_	5.0	15**	ns			
14	TckL2ioV	CLKOUT↓ to Port out valid ⁽¹⁾	_	_	40**	ns			
15	TioV2ckH	Port in valid before CLKOUT ⁽¹⁾	0.25 TCY+30*		_	ns			
16	TckH2ioI	Port in hold after CLKOUT ⁽¹⁾	0*		_	ns			
17	TosH2ioV	OSC1 [↑] (Q1 cycle) to Port out valid ⁽²⁾	_	_	100*	ns			
18	TosH2ioI	OSC1 [†] (Q2 cycle) to Port input invalid (I/O in hold time)	TBD		_	ns			
19	TioV2osH	Port input valid to OSC1↑ (I/O in setup time)	TBD		_	ns			
20	TioR	Port output rise time ⁽²⁾	_	10	25**	ns			
21	TioF	Port output fall time ⁽²⁾	_	10	25**	ns			

^{*} These parameters are characterized but not tested.

^{**} These parameters are design targets and are not tested. No characterization data available at this time.

[†] Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

Note 1: Measurements are taken in RC Mode where CLKOUT output is 4 x Tosc.

^{2:} Please refer to Figure 13.1 for load conditions.

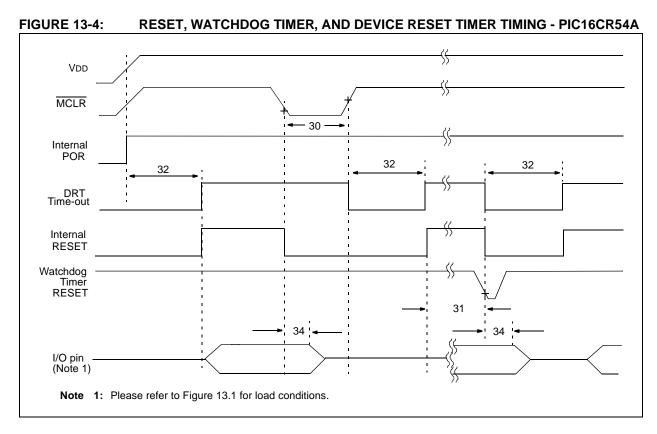


TABLE 13-3: RESET, WATCHDOG TIMER, AND DEVICE RESET TIMER - PIC16CR54A

AC Charac	cteristics	Standard Operating Conditions (unless otherwise specified) Operating Temperature $0^{\circ}C \le TA \le +70^{\circ}C$ for commercial $-40^{\circ}C \le TA \le +85^{\circ}C$ for industrial $-40^{\circ}C \le TA \le +125^{\circ}C$ for extended							
Param No.	Characteristic	Min	Тур†	Max	Units	Conditions			
30	TmcL	MCLR Pulse Width (low)	1.0*	_		μS	VDD = 5.0V		
31	Twdt	Watchdog Timer Time-out Period (No Prescaler)	7.0*	18*	40*	ms	VDD = 5.0V (Comm)		
32	TDRT	Device Reset Timer Period	7.0*	18*	30*	ms	VDD = 5.0V (Comm)		
34	Tioz	I/O Hi-impedance from MCLR Low	_	_	1.0*	μS			

^{*} These parameters are characterized but not tested.

[†] Data in the Typical ("Typ") column is at 5.0V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

FIGURE 13-5: TIMERO CLOCK TIMINGS - PIC16CR54A

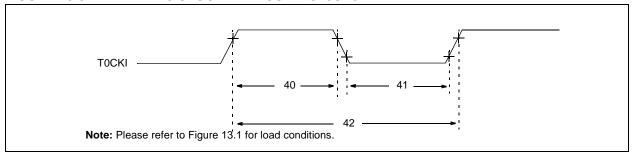


TABLE 13-4: TIMERO CLOCK REQUIREMENTS - PIC16CR54A

Standard Operating Operating Temperat				•	$TA \le +7$ $TA \le +8$	70°C fo 35°C fo	or comn or indus	nercial trial
Param No.	Symbol		Characteristic	Min	Тур†	Max	Units	Conditions
40	Tt0H	T0CKI High	Pulse Width					
			 No Prescaler 	0.5 Tcy + 20*	_	_	ns	
			 With Prescaler 	10*	_	_	ns	
41	Tt0L	T0CKI Low	Pulse Width					
			 No Prescaler 	0.5 Tcy + 20*	_	_	ns	
			 With Prescaler 	10*	_		ns	

T0CKI Period

20 or Tcy + 40

42

Tt0P

Whichever is greater.

N = Prescale Value (1, 2, 4,..., 256)

ns

^{*} These parameters are characterized but not tested.

[†] Data in the Typical ("Typ") column is at 5.0V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

14.0 DEVICE CHARACTERIZATION - PIC16C54A

The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.

"Typical" represents the mean of the distribution at 25°C. "Maximum" or "minimum" represents (mean + 3σ) or (mean – 3σ) respectively, where σ is a standard deviation, over the whole temperature range.

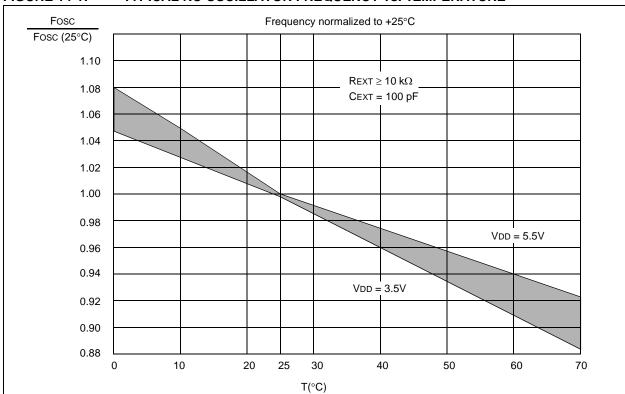


FIGURE 14-1: TYPICAL RC OSCILLATOR FREQUENCY vs. TEMPERATURE

TABLE 14-1: RC OSCILLATOR FREQUENCIES

Сехт	REXT	Average Fosc @ 5 V, 25°C		
20 pF	3.3K	5 MHz	± 27%	
	5K	3.8 MHz	± 21%	
	10K	2.2 MHz	± 21%	
	100K	262 kHz	± 31%	
100 pF	100 pF 3.3K		± 13%	
	5K	1.2 MHz	± 13%	
	10K	684 kHz	± 18%	
	100K	71 kHz	± 25%	
300 pF	3.3K	660 kHz	± 10%	
	5.0K	484 kHz	± 14%	
	10K	267 kHz	± 15%	
	100K	29 kHz	± 19%	

The frequencies are measured on DIP packages.

The percentage variation indicated here is part-to-part variation due to normal process distribution. The variation indicated is ± 3 standard deviations from the average value for VDD = 5V.

FIGURE 14-2: TYPICAL RC OSC FREQUENCY vs. VDD, CEXT = 20 PF

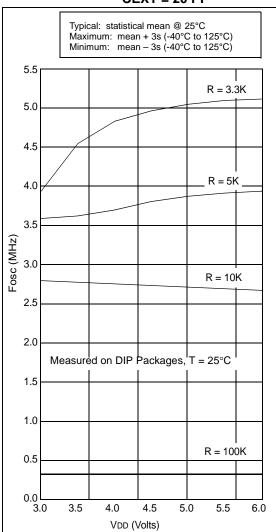


FIGURE 14-3: TYPICAL RC OSC FREQUENCY vs. VDD, CEXT = 100 PF

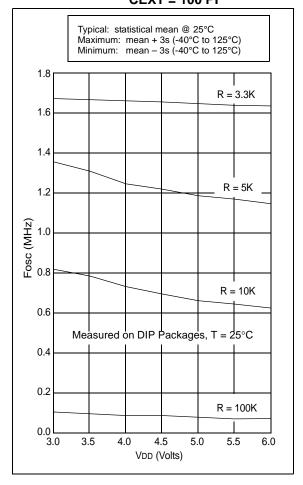


FIGURE 14-4: TYPICAL RC OSC FREQUENCY vs. VDD, CEXT = 300 PF

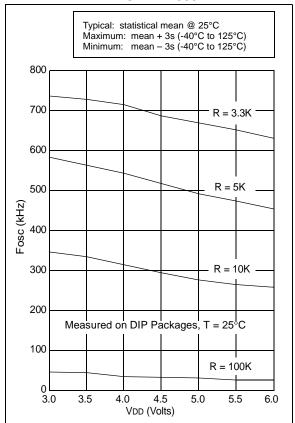


FIGURE 14-5: TYPICAL IPD vs. Vdd, WATCHDOG DISABLED

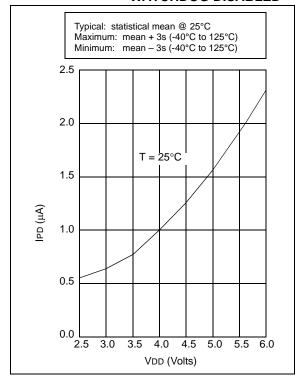


FIGURE 14-6: MAXIMUM IPD vs. VDD, WATCHDOG DISABLED

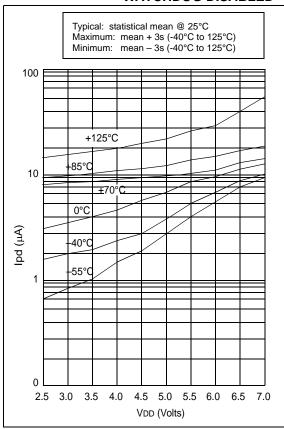


FIGURE 14-7: TYPICAL IPD vs. VDD, WATCHDOG ENABLED

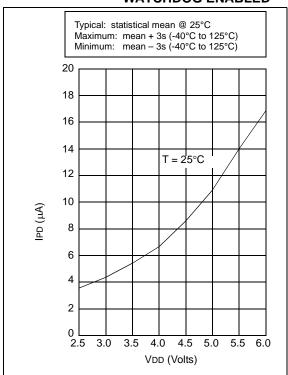
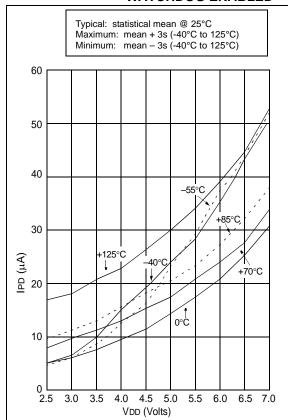


FIGURE 14-8: MAXIMUM IPD vs. VDD, WATCHDOG ENABLED



IPD, with WDT enabled, has two components: The leakage current, which increases with higher temperature, and the operating current of the WDT logic, which increases with lower temperature. At -40° C, the latter dominates explaining the apparently anomalous behavior.

FIGURE 14-9: VTH (INPUT THRESHOLD VOLTAGE) OF I/O PINS vs. VDD

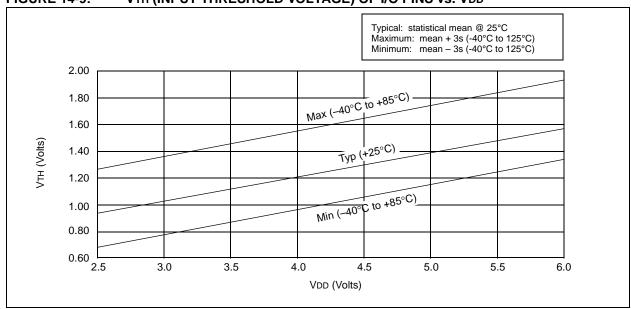


FIGURE 14-10: VIH, VIL OF MCLR, TOCKI AND OSC1 (RC MODE) vs. VDD

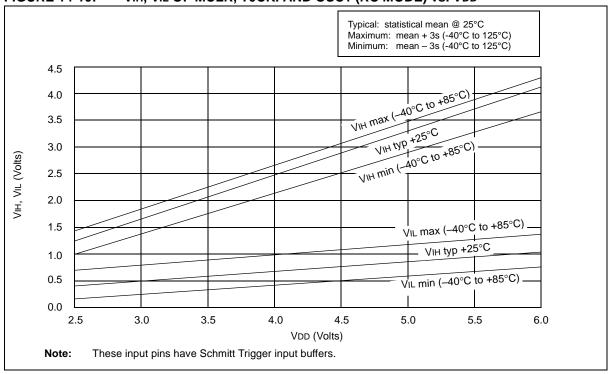


FIGURE 14-11: VTH (INPUT THRESHOLD VOLTAGE) OF OSC1 INPUT (XT, HS, AND LP MODES) vs. VDD

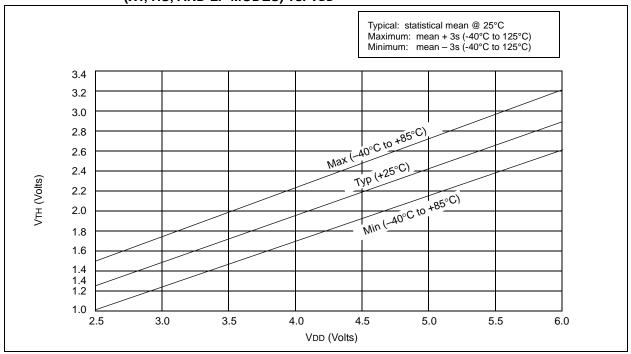
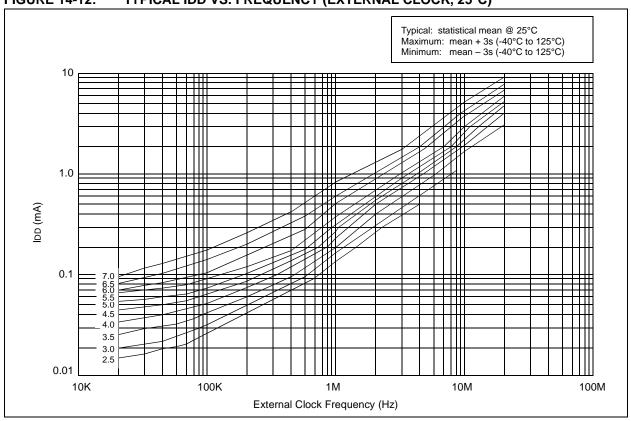


FIGURE 14-12: TYPICAL IDD VS. FREQUENCY (EXTERNAL CLOCK, 25°C)



MAXIMUM IDD VS. FREQUENCY (EXTERNAL CLOCK, -40°C TO +85°C) FIGURE 14-13: Typical: statistical mean @ 25°C Maximum: mean + 3s (-40°C to 125°C) Minimum: mean - 3s (-40°C to 125°C) 10 1.0 IDD (mA) 7.0 6.5 0.1 4.0 3.5 = 3.0 0.01 10K 100K 1M 10M 100M External Clock Frequency (Hz)



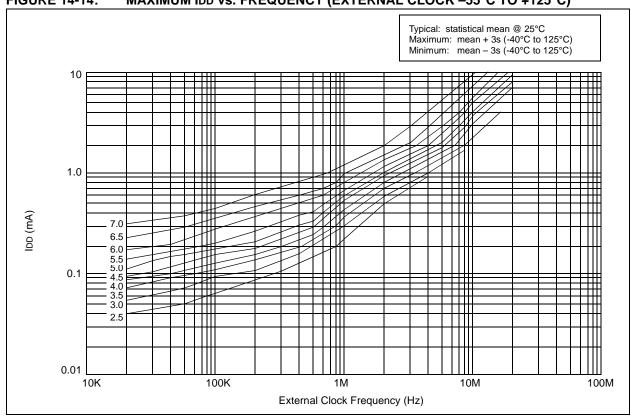


FIGURE 14-15: WDT TIMER TIME-OUT PERIOD vs. VDD⁽¹⁾

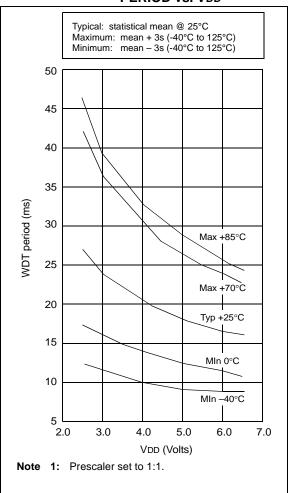


FIGURE 14-16: TRANSCONDUCTANCE (gm) OF HS OSCILLATOR vs. VDD

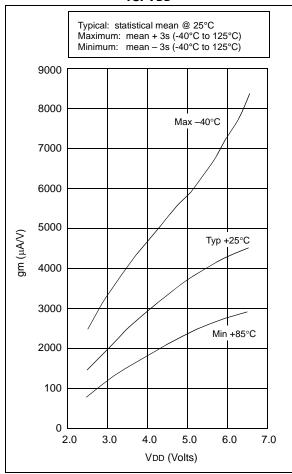


FIGURE 14-17: TRANSCONDUCTANCE (gm) OF LP OSCILLATOR vs. VDD

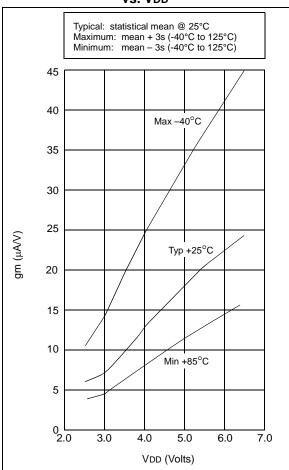


FIGURE 14-18: TRANSCONDUCTANCE (gm) OF XT OSCILLATOR vs. VDD

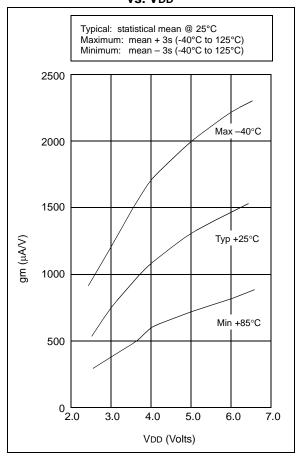


FIGURE 14-19: PORTA, B AND C IOH vs. Voh, VDD = 3 V

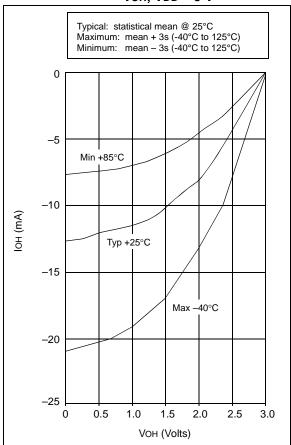


FIGURE 14-20: PORTA, B AND C IOH vs. Voh, VDD = 5 V

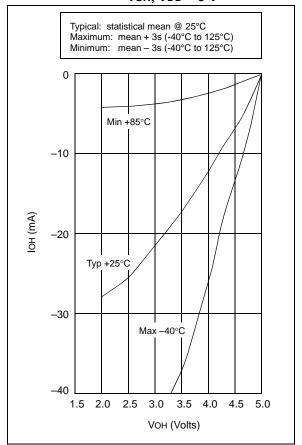


FIGURE 14-21: PORTA, B AND C IOL vs. Vol, VDD = 3 V

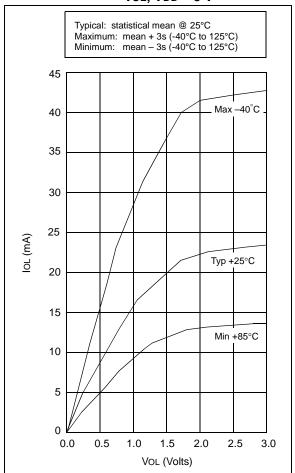


FIGURE 14-22: PORTA, B AND C IOL vs. Vol, VDD = 5 V

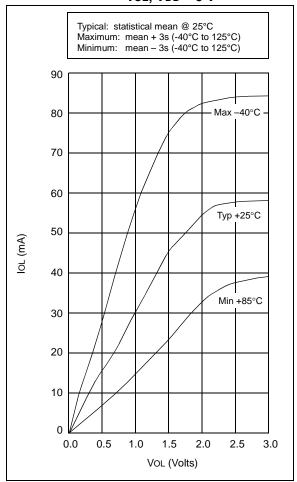


TABLE 14-2: INPUT CAPACITANCE FOR PIC16C54/56

Pin	Typical Capacitance (pF)				
Pin	18L PDIP	18L SOIC			
RA port	5.0	4.3			
RB port	5.0	4.3			
MCLR	17.0	17.0			
OSC1	4.0	3.5			
OSC2/CLKOUT	4.3	3.5			
T0CKI	3.2	2.8			

All capacitance values are typical at 25°C. A part-to-part variation of $\pm 25\%$ (three standard deviations) should be taken into account.

TABLE 14-3: INPUT CAPACITANCE FOR PIC16C55/57

	Typical Capacitance (pF)				
Pin	28L PDIP (600 mil)	28L SOIC			
RA port	5.2	4.8			
RB port	5.6	4.7			
RC port	5.0	4.1			
MCLR	17.0	17.0			
OSC1	6.6	3.5			
OSC2/CLKOUT	4.6	3.5			
TOCKI	4.5	3.5			

All capacitance values are typical at 25°C. A part-to-part variation of $\pm 25\%$ (three standard deviations) should be taken into account.

15.0 ELECTRICAL CHARACTERISTICS - PIC16C54A

Absolute Maximum Ratings(†) Voltage on all other pins with respect to Vss—0.6V to (VDD + 0.6V) Total power dissipation⁽¹⁾......800 mW Max. current into an input pin (T0CKI only)±500 μA Input clamp current, IK (VI < 0 or VI > VDD)......±20 mA Output clamp current, IOK (VO < 0 or VO > VDD)±20 mA

Note 1: Power dissipation is calculated as follows: Pdis = VDD x {IDD - Σ IOH} + Σ {(VDD-VOH) x IOH} + Σ (VOL x IOL)

† NOTICE: Stresses above those listed under "Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operation listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

15.1 DC Characteristics: PIC16C54A-04, 10, 20 (Commercial)
PIC16C54A-04I, 10I, 20I (Industrial)
PIC16LC54A-04 (Commercial)
PIC16LC54A-04I (Industrial)

				Standard Operating Conditions (unless otherwise specified) Operating Temperature $0^{\circ}C \le TA \le +70^{\circ}C$ for commercial $-40^{\circ}C \le TA \le +85^{\circ}C$ for industrial					
PIC16C54A-04, 10, 20 PIC16C54A-04I, 10I, 20I (Commercial, Industrial)				Standard Operating Conditions (unless otherwise specified) Operating Temperature $0^{\circ}C \le TA \le +70^{\circ}C$ for commercial $-40^{\circ}C \le TA \le +85^{\circ}C$ for industrial					
Param No. Symbol Characteristic/Device				Тур†	Max	Units	Conditions		
	VDD	Supply Voltage							
D001		PIC16LC54A	3.0 2.5	_ _	6.25 6.25	V V	XT and RC modes LP mode		
D001A		PIC16C54A	3.0 4.5		6.25 5.5	V V	RC, XT and LP modes HS mode		
D002	Vdr	RAM Data Retention Voltage ⁽¹⁾	1	1.5*	_	>	Device in SLEEP mode		
D003	VPOR	VDD Start Voltage to ensure Power-on Reset		Vss	_	V	See Section 5.1 for details on Power-on Reset		
D004	SVDD	VDD Rise Rate to ensure Power-on Reset	0.05*	_	_	V/ms	See Section 5.1 for details on Power-on Reset		
	IDD	Supply Current ⁽²⁾							
D005		PIC16LC5X	_	0.5	2.5	mA	FOSC = 4.0 MHz, VDD = 5.5V, RC ⁽³⁾ and XT modes		
				11	27	μΑ	FOSC = 32 kHz, VDD = 2.5V, WDT disabled, LP mode, Commercial		
				11	35	μΑ	FOSC = 32 kHz, VDD = 2.5V, WDT disabled, LP mode, Industrial		
D005A		PIC16C5X		1.8	2.4	mA	FOSC = 4.0 MHz, VDD = 5.5V, RC ⁽³⁾ and XT modes		
			_	2.4	8.0	mΑ	FOSC = 10 MHz, VDD = 5.5V, HS mode		
			_	4.5	16	mΑ	FOSC = 20 MHz, VDD = 5.5V, HS mode		
			_	14	29	μΑ	Fosc = 32 kHz, VDD = 3.0V,		
			_	17	37	μΑ	WDT disabled, LP mode, Commercial Fosc = 32 kHz, VDD = 3.0V, WDT disabled, LP mode, Industrial		

- * These parameters are characterized but not tested.
- † Data in "Typ" column is based on characterization results at 25°C. This data is for design guidance only and is not tested.
- Note 1: This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.
 - 2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.
 - a) The test conditions for all IDD measurements in active Operation mode are: OSC1 = external square wave, from rail-to-rail; all I/O pins tristated, pulled to Vss, T0CKI = VDD, MCLR = VDD; WDT enabled/ disabled as specified.
 - b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.
 - 3: Does not include current through REXT. The current through the resistor can be estimated by the formula: IR = VDD/2REXT (mA) with REXT in $k\Omega$.

15.1 DC Characteristics: PIC16C54A-04, 10, 20 (Commercial)
PIC16C54A-04I, 10I, 20I (Industrial)
PIC16LC54A-04 (Commercial)
PIC16LC54A-04I (Industrial)

PIC16LC54A-04

PIC16LC54A-04I
(Commercial, Industrial)Operating Temperature $0^{\circ}C \leq TA \leq +70^{\circ}C$ for commercial
 $-40^{\circ}C \leq TA \leq +85^{\circ}C$ for industrialPIC16C54A-04, 10, 20
PIC16C54A-04I, 10I, 20IStandard Operating Conditions (unless otherwise specified)
Operating Temperature $0^{\circ}C \leq TA \leq +70^{\circ}C$ for commercial

Standard Operating Conditions (unless otherwise specified)

Operating Temperature $0^{\circ}\text{C} \leq \text{TA} \leq +70^{\circ}\text{C}$ for commercial (Commercial, Industrial) $-40^{\circ}\text{C} \leq \text{TA} \leq +85^{\circ}\text{C}$ for industrial

Param No.	Symbol	Characteristic/Device	Min	Тур†	Max	Units	Conditions
	IPD	Power-down Current ⁽²⁾					
D006		PIC16LC5X	_	2.5	12	μΑ	VDD = 2.5V, WDT enabled, Commercial
			_	0.25	4.0	μΑ	VDD = 2.5V, WDT disabled, Commercial
			_	2.5	14	μΑ	VDD = 2.5V, WDT enabled, Industrial
			_	0.25	5.0	μΑ	VDD = 2.5V, WDT disabled, Industrial
D006A		PIC16C5X	_	4.0	12	μА	VDD = 3.0V, WDT enabled, Commercial
			_	0.25	4.0	μΑ	VDD = 3.0V, WDT disabled, Commercial
			_	5.0	14	μΑ	VDD = 3.0V, WDT enabled, Industrial
			_	0.3	5.0	μΑ	VDD = 3.0V, WDT disabled, Industrial

- These parameters are characterized but not tested.
- † Data in "Typ" column is based on characterization results at 25°C. This data is for design guidance only and is not tested.
- Note 1: This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.
 - 2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.
 - a) The test conditions for all IDD measurements in active Operation mode <u>are: OSC1</u> = external square wave, from rail-to-rail; all I/O pins tristated, pulled to Vss, T0CKI = VDD, MCLR = VDD; WDT enabled/disabled as specified.
 - b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.
 - 3: Does not include current through REXT. The current through the resistor can be estimated by the formula: IR = VDD/2REXT (mA) with REXT in $k\Omega$.

15.2 DC Characteristics: PIC16C54A-04E, 10E, 20E (Extended) PIC16LC54A-04E (Extended)

PIC16LC54A-04E (Extended)				Standard Operating Conditions (unless otherwise specified) Operating Temperature $-40^{\circ}\text{C} \le \text{Ta} \le +125^{\circ}\text{C}$ for extended					
PIC16C54A-04E, 10E, 20E (Extended)			Standard Operating Conditions (unless otherwise specified) Operating Temperature $-40^{\circ}\text{C} \le \text{TA} \le +125^{\circ}\text{C}$ for extended						
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units	Conditions		
	VDD	Supply Voltage							
D001		PIC16LC54A	3.0 2.5		6.25 6.25	-	XT and RC modes LP mode		
D001A		PIC16C54A	3.5 4.5	_	5.5 5.5	V	RC and XT modes HS mode		
D002	Vdr	RAM Data Retention Voltage ⁽¹⁾	_	1.5*	_	V	Device in SLEEP mode		
D003	VPOR	VDD Start Voltage to ensure Power-on Reset	_	Vss	_	V	See Section 5.1 for details on Power-on Reset		
D004	SVDD	VDD Rise Rate to ensure Power-on Reset	0.05*	_	_	V/ms	See Section 5.1 for details on Power-on Reset		
	IDD	Supply Current ⁽²⁾							
D010		PIC16LC54A	_	0.5	25	mA	Fosc = 4.0 MHz, VDD = 5.5V, RC ⁽³⁾ and XT modes		
			_	11	27	μА	FOSC = 32 kHz, VDD = 2.5V, LP mode, Commercial		
			_	11	35	μА	FOSC = 32 kHz, VDD = 2.5V, LP mode, Industrial		
			_	11	37	μА	FOSC = 32 kHz, VDD = 2.5V, LP mode, Extended		
D010A		PIC16C54A	_	1.8	3.3	mA	Fosc = 4.0 MHz, VDD = 5.5V, RC ⁽³⁾ and XT modes		
			_	4.8	10	mA	FOSC = 10 MHz, VDD = 5.5V, HS mode		
			_	9.0	20	mA	FOSC = 20 MHz, VDD = 5.5V, HS mode		

- * These parameters are characterized but not tested.
- † Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.
- Note 1: This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.
 - 2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.
 - a) The test conditions for all IDD measurements in active Operation mode are: OSC1 = external square wave, from rail-to-rail; all I/O pins tristated, pulled to Vss, ToCKI = VDD, MCLR = VDD; WDT enabled/disabled as specified.
 - b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.
 - 3: Does not include current through REXT. The current through the resistor can be estimated by the formula: IR = VDD/2REXT (mA) with REXT in $k\Omega$.

15.2 DC Characteristics: PIC16C54A-04E, 10E, 20E (Extended) PIC16LC54A-04E (Extended)

PIC16LC54A-04E (Extended)							tions (unless otherwise specified) $-40^{\circ}\text{C} \le \text{TA} \le +125^{\circ}\text{C}$ for extended
PIC16C (Extend	54A-04E, ded)	Standard Operating Conditions (unless otherwise specified) Operating Temperature $-40^{\circ}\text{C} \le \text{TA} \le +125^{\circ}\text{C}$ for extended					
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units	Conditions
	IPD	Power-down Current ⁽²⁾					
D020		PIC16LC54A		2.5 0.25	15 7.0	μA μA	VDD = 2.5V, WDT enabled, Extended VDD = 2.5V, WDT disabled, Extended
D020A		PIC16C54A	_	5.0 0.8	22 18*	μA μA	VDD = 3.5V, WDT enabled VDD = 3.5V, WDT disabled

- Legend: Rows with standard voltage device data only are shaded for improved readability.
 - * These parameters are characterized but not tested.
 - † Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.
- Note 1: This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.
 - 2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.
 - a) The test conditions for all IDD measurements in active Operation mode <u>are: OSC1 = external square</u> wave, from rail-to-rail; all I/O pins tristated, pulled to Vss, T0CKI = VDD, MCLR = VDD; WDT enabled/ disabled as specified.
 - b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.
 - 3: Does not include current through REXT. The current through the resistor can be estimated by the formula: IR = VDD/2REXT (mA) with REXT in $k\Omega$.

15.3 DC Characteristics: PIC16LV54A-02 (Commercial) PIC16LV54A-02I (Industrial)

PIC16LV54A-02 PIC16LV54A-02I (Commercial, Industrial)			Standard Operating Conditions (unless otherwise specified) Operating Temperature $0^{\circ}C \leq TA \leq +70^{\circ}C$ for commercial $-20^{\circ}C \leq TA \leq +85^{\circ}C$ for industrial					
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units	Conditions	
D001	VDD	Supply Voltage RC and XT modes	2.0	_	3.8	V		
D002	VDR	RAM Data Retention Voltage ⁽¹⁾	_	1.5*	_	V	Device in SLEEP mode	
D003	VPOR	VDD Start Voltage to ensure Power-on Reset	_	Vss	_	V	See Section 5.1 for details on Power-on Reset	
D004	SVDD	VDD Rise Rate to ensure Power-on Reset	0.05*	_	_	V/ms	See Section 5.1 for details on Power-on Reset	
D010	IDD	Supply Current ⁽²⁾ RC ⁽³⁾ and XT modes LP mode, Commercial LP mode, Industrial	_ _ _	0.5 11 14	 27 35	mA μA μA	Fosc = 2.0 MHz, VDD = 3.0V Fosc = 32 kHz, VDD = 2.5V WDT disabled Fosc = 32 kHz, VDD = 2.5V WDT disabled	
D020	IPD	Power-down Current ^(2,4) Commercial Commercial Industrial	_ _ _	2.5 0.25 3.5	12 4.0 14	μΑ μΑ μΑ	VDD = 2.5V, WDT enabled VDD = 2.5V, WDT disabled VDD = 2.5V, WDT enabled	
		Industrial	_	0.3	5.0	μ A	VDD = 2.5V, WDT disabled	

^{*} These parameters are characterized but not tested.

- † Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.
- Note 1: This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.
 - 2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.
 - a) The test conditions for all IDD measurements in active Operation mode <u>are: OSC1 = external square</u> wave, from rail-to-rail; all I/O pins tristated, pulled to Vss, T0CKI = VDD, MCLR = VDD; WDT enabled/ disabled as specified.
 - b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.
 - 3: Does not include current through REXT. The current through the resistor can be estimated by the formula: IR = VDD/2REXT (mA) with REXT in kΩ.
 - **4:** The oscillator start-up time can be as much as 8 seconds for XT and LP oscillator selection on wake-up from SLEEP mode or during initial power-up.

15.4 DC Characteristics: PIC16C54A-04, 10, 20, PIC16LC54A-04, PIC16LV54A-02 (Commercial) PIC16C54A-04I, 10I, 20I, PIC16LC54A-04I, PIC16LV54A-02I (Industrial) PIC16C54A-04E, 10E, 20E, PIC16LC54A-04E (Extended)

			Standard Operating Conditions (unless otherwise specified) Operating Temperature $0^{\circ}C \leq TA \leq +70^{\circ}C \text{ for commercial} \\ -40^{\circ}C \leq TA \leq +85^{\circ}C \text{ for industrial} \\ -20^{\circ}C \leq TA \leq +85^{\circ}C \text{ for industrial-PIC16LV54A-02I} \\ -40^{\circ}C \leq TA \leq +125^{\circ}C \text{ for extended}$					
Param No.	Symbol	Characteristic	Min	Тур†	Conditions			
D030	VIL	Input Low Voltage I/O ports MCLR (Schmitt Trigger) TOCKI (Schmitt Trigger) OSC1 (Schmitt Trigger) OSC1	Vss Vss Vss Vss Vss	 - - -	0.2 VDD 0.15 VDD 0.15 VDD 0.15 VDD 0.3 VDD	V V V	Pin at hi-impedance RC mode only ⁽³⁾ XT, HS and LP modes	
D040	VIH	Input High Voltage I/O ports I/O ports MCLR (Schmitt Trigger) TOCKI (Schmitt Trigger) OSC1 (Schmitt Trigger)	0.2 VDD + 1 2.0 0.85 VDD 0.85 VDD 0.85 VDD 0.7 VDD	 - - - -	VDD VDD VDD VDD VDD VDD	V V V V	For all $VDD^{(4)}$ $4.0V < VDD \le 5.5V^{(4)}$ RC mode only ⁽³⁾ XT, HS and LP modes	
D050	VHYS	Hysteresis of Schmitt Trigger inputs	0.15 VDD*	_	_	V		
D060	IIL	Input Leakage Current ^(1,2) I/O ports MCLR MCLR TOCKI OSC1	-1.0 -5.0 -3.0 -3.0	0.5 0.5 0.5 0.5	+1.0 +5.0 +3.0 +3.0	μΑ μΑ μΑ μΑ μΑ	For VDD \leq 5.5V: VSS \leq VPIN \leq VDD, pin at hi-impedance VPIN = VSS +0.25V VPIN = VDD VSS \leq VPIN \leq VDD VSS \leq VPIN \leq VDD, XT, HS and LP modes	
D080	VOL	Output Low Voltage I/O ports OSC2/CLKOUT	_		0.6 0.6	V	IOL = 8.7 mA, VDD = 4.5V IOL = 1.6 mA, VDD = 4.5V, RC mode only	
	VOH	Output High Voltage ⁽²⁾ I/O ports OSC2/CLKOUT	VDD - 0.7 VDD - 0.7		_	V V	IOH = -5.4 mA, VDD = 4.5V IOH = -1.0 mA, VDD = 4.5V, RC mode only	

^{*} These parameters are characterized but not tested.

[†] Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

Note 1: The leakage current on the MCLR/VPP pin is strongly dependent on the applied voltage level. The specified levels represent normal operating conditions. Higher leakage current may be measured at different input voltage.

^{2:} Negative current is defined as coming out of the pin.

^{3:} For the RC mode, the OSC1/CLKIN pin is a Schmitt Trigger input. It is not recommended that the PIC16C5X be driven with external clock in RC mode.

Timing Parameter Symbology and Load Conditions 15.5

The timing parameter symbols have been created with one of the following formats:

1. TppS2ppS

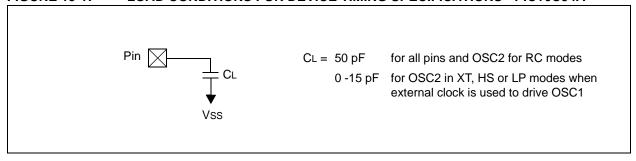
Low

2. TppS

Т		
F	Frequency	T Time
Lowe	ercase letters (pp) and their meanings:	
pp		
2	to	mc MCLR
ck	CLKOUT	osc oscillator
су	cycle time	os OSC1
drt	device reset timer	t0 T0CKI
io	I/O port	wdt watchdog timer
Uppe	ercase letters and their meanings:	
S		
F	Fall	P Period
Н	High	R Rise
I	Invalid (Hi-impedance)	V Valid

Hi-impedance

FIGURE 15-1: LOAD CONDITIONS FOR DEVICE TIMING SPECIFICATIONS - PIC16C54A



15.6 Timing Diagrams and Specifications

AC Characteristics

FIGURE 15-2: EXTERNAL CLOCK TIMING - PIC16C54A

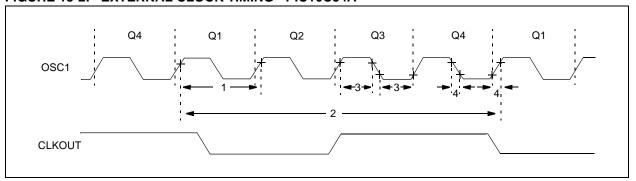


TABLE 15-1: EXTERNAL CLOCK TIMING REQUIREMENTS - PIC16C54A

Standard Operating Conditions (unless otherwise specified)

Operating Temperature $0^{\circ}C \le TA \le +70^{\circ}C$ for commercial $-40^{\circ}C \le TA \le +85^{\circ}C$ for industrial

-20°C \leq TA \leq +85°C for industrial - PIC16LV54A-02I

 -40° C \leq TA \leq +125 $^{\circ}$ C for extended

Param Symbol Characteristic Min Max Units Conditions Typ† No. External CLKIN Fre-Fosc DC MHz XT osc mode 4.0 quency⁽¹⁾ XT osc mode (PIC16LV54A) DC 2.0 MHz MHz HS osc mode (04) DC 4.0 DC 10 MHz HS osc mode (10) DC 20 MHz HS osc mode (20) DC 200 kHz LP osc mode Oscillator Frequency⁽¹⁾ DC MHz RC osc mode 4.0 DC 2.0 MHz RC osc mode (PIC16LV54A) 0.1 4.0 MHz XT osc mode MHz XT osc mode (PIC16LV54A) 2.0 0.1 4.0 MHz HS osc mode (04) 4.0 4.0 10 MHz HS osc mode (10) 20 MHz HS osc mode (20) 4.0 200 LP osc mode 5.0 kHz

Note 1: All specified values are based on characterization data for that particular oscillator type under standard operating conditions with the device executing code. Exceeding these specified limits may result in an unstable oscillator operation and/or higher than expected current consumption.

When an external clock input is used, the "max" cycle time limit is "DC" (no clock) for all devices.

2: Instruction cycle period (TcY) equals four times the input oscillator time base period.

^{*} These parameters are characterized but not tested.

[†] Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

AC Characteristics

TABLE 15-1: EXTERNAL CLOCK TIMING REQUIREMENTS - PIC16C54A

Standard Operating Conditions (unless otherwise specified)

Operating Temperature $0^{\circ}C \le TA \le +70^{\circ}C$ for commercial $-40^{\circ}C \le TA \le +85^{\circ}C$ for industrial

 $-20^{\circ}\text{C} \le \text{TA} \le +85^{\circ}\text{C}$ for industrial - PIC16LV54A-02I

 $-40^{\circ}C \le TA \le +125^{\circ}C$ for extended

Param No.	Symbol	Characteristic	Min	Тур†	Max	Units	Conditions
1	Tosc	External CLKIN Period ⁽¹⁾	250	_	_	ns	XT osc mode
			500	_	_	ns	XT osc mode (PIC16LV54A)
			250		_	ns	HS osc mode (04)
			100	_	_	ns	HS osc mode (10)
			50	_	_	ns	HS osc mode (20)
			5.0	_	1	μS	LP osc mode
		Oscillator Period ⁽¹⁾	250	_	_	ns	RC osc mode
			500	_	_	ns	RC osc mode (PIC16LV54A)
			250	_	10,000	ns	XT osc mode
			500	_	_	ns	XT osc mode (PIC16LV54A)
			250	_	250	ns	HS osc mode (04)
			100	_	250	ns	HS osc mode (10)
			50	_	250	ns	HS osc mode (20)
			5.0	_	200	μS	LP osc mode
2	Tcy	Instruction Cycle Time ⁽²⁾	_	4/Fosc	_		
3	TosL, TosH	Clock in (OSC1) Low or	85*	_	1	ns	XT oscillator
		High Time	20*	_	_	ns	HS oscillator
			2.0*			μS	LP oscillator
4	TosR, TosF	Clock in (OSC1) Rise or	_	_	25*	ns	XT oscillator
		Fall Time	_	_	25*	ns	HS oscillator
			_	_	50*	ns	LP oscillator

^{*} These parameters are characterized but not tested.

- Note 1: All specified values are based on characterization data for that particular oscillator type under standard operating conditions with the device executing code. Exceeding these specified limits may result in an unstable oscillator operation and/or higher than expected current consumption.

 When an external clock input is used, the "max" cycle time limit is "DC" (no clock) for all devices.
 - 2: Instruction cycle period (TCY) equals four times the input oscillator time base period.

[†] Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

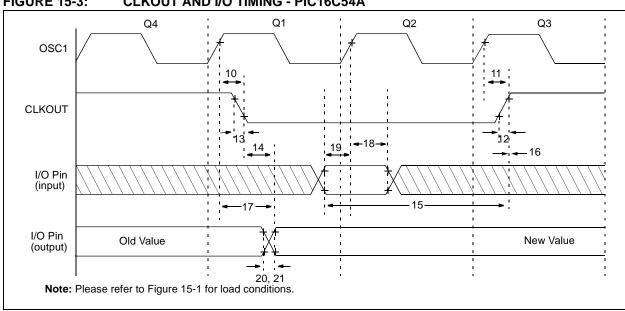


FIGURE 15-3: CLKOUT AND I/O TIMING - PIC16C54A

CLKOUT AND I/O TIMING REQUIREMENTS - PIC16C54A

IABLE 13-2. CENC	OT AND TO TIMING REQUIREMENTS - FICTOCS4A								
Standard Operating Conditions (unless otherwise specified)									
	Operating Temperature $0^{\circ}C \le TA \le +70^{\circ}C$ for commercial								
AC Characteristics	-40 °C \leq TA \leq +85°C for industrial								
	-20 °C \leq TA \leq +85°C for industrial - PIC16LV54A-02I								
	$-40^{\circ}C \le TA \le +125^{\circ}C$ for extended								

Param No.	Symbol	Characteristic	Min	Тур†	Max	Units
10	TosH2ckL	OSC1↑ to CLKOUT↓ ⁽¹⁾	_	15	30**	ns
11	TosH2ckH	OSC1↑ to CLKOUT↑ ⁽¹⁾	_	15	30**	ns
12	TckR	CLKOUT rise time ⁽¹⁾	_	5.0	15**	ns
13	TckF	CLKOUT fall time ⁽¹⁾	_	5.0	15**	ns
14	TckL2ioV	CLKOUT↓ to Port out valid ⁽¹⁾	_	_	40**	ns
15	TioV2ckH	Port in valid before CLKOUT ⁽¹⁾	0.25 TCY+30*	_	_	ns
16	TckH2iol	Port in hold after CLKOUT ⁽¹⁾	0*	_	_	ns
17	TosH2ioV	OSC1↑ (Q1 cycle) to Port out valid ⁽²⁾	_	_	100*	ns
18	TosH2iol	OSC1↑ (Q2 cycle) to Port input invalid (I/O in hold time)	TBD		_	ns
19	TioV2osH	Port input valid to OSC1↑ (I/O in setup time)	TBD	_	_	ns
20	TioR	Port output rise time ⁽²⁾	_	10	25**	ns
21	TioF	Port output fall time ⁽²⁾	_	10	25**	ns

^{*} These parameters are characterized but not tested.

2: Please refer to Figure 15-1 for load conditions.

^{**} These parameters are design targets and are not tested. No characterization data available at this time.

Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

Note 1: Measurements are taken in RC Mode where CLKOUT output is 4 x Tosc.

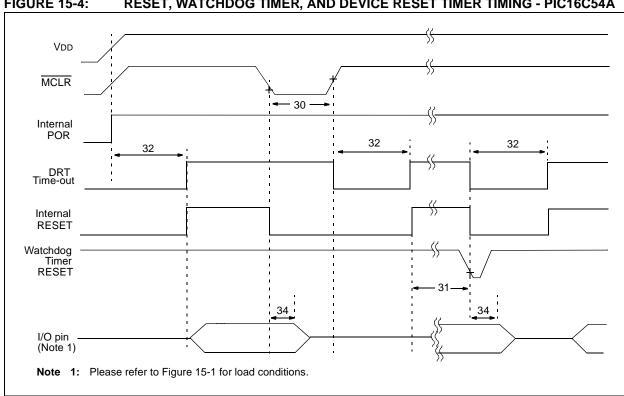


FIGURE 15-4: RESET, WATCHDOG TIMER, AND DEVICE RESET TIMER TIMING - PIC16C54A

TABLE 15-3: RESET, WATCHDOG TIMER, AND DEVICE RESET TIMER - PIC16C54A

	Standard Operating Conditions (unless otherwise specified)									
	Operating Temperature $0^{\circ}C \le TA \le +70^{\circ}C$ for commercial									
AC Characteristics	-40° C \leq TA \leq +85 $^{\circ}$ C for industrial									
	-20 °C \leq TA \leq +85°C for industrial - PIC16LV54A-02I									
-40° C \leq TA \leq +125 $^{\circ}$ C for extended										

Param No.	Symbol	Characteristic	Min	Тур†	Max	Units	Conditions
30	TmcL	MCLR Pulse Width (low)	100* 1	_		ns μs	VDD = 5.0V VDD = 5.0V (PIC16LV54A only)
31	Twdt	Watchdog Timer Time-out Period (No Prescaler)	9.0*	18*	30*	ms	VDD = 5.0V (Comm)
32	TDRT	Device Reset Timer Period	9.0*	18*	30*	ms	VDD = 5.0V (Comm)
34	Tioz	I/O Hi-impedance from MCLR Low	_	_	100* 1μs	ns —	(PIC16LV54A only)

These parameters are characterized but not tested.

Data in the Typical ("Typ") column is at 5V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

FIGURE 15-5: TIMER0 CLOCK TIMINGS - PIC16C54A

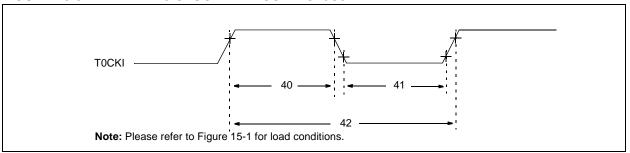


TABLE 15-4: TIMERO CLOCK REQUIREMENTS - PIC16C54A

TABLE 15-4:	HIMERO CLOC	K REQUIREMENTS	- PIC16C54A					
		Standard Operating Conditions (unless otherwise specified)						
		Operating Temperatu	ure 0°C ≤	T A ≤ + 7	70°C fo	or comn	nercial	
AC Cha	racteristics	-40°C ≤ TA ≤ +85°C for industrial						
			– 20°C ≤	T A ≤ + 8	S5°C fo	or indus	trial - PIC16LV54A-02I	
		$-40^{\circ}C \le TA \le +125^{\circ}C$ for extended						

Param No.	Symbol	Characteristic	Min	Тур†	Max	Units	Conditions
40	Tt0H	T0CKI High Pulse Width					
		- No Prescaler	0.5 Tcy + 20*	_	_	ns	
		- With Prescaler	10*	_	_	ns	
41	Tt0L	T0CKI Low Pulse Width					
		- No Prescaler	0.5 Tcy + 20*	_	_	ns	
		- With Prescaler	10*	_	_	ns	
42	Tt0P	T0CKI Period	20 or <u>Tcy + 40</u> * N	_	1		Whichever is greater. N = Prescale Value (1, 2, 4,, 256)

^{*} These parameters are characterized but not tested.

[†] Data in the Typical ("Typ") column is at 5V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

PIC16C5X

NOTES:

16.0 DEVICE CHARACTERIZATION - PIC16C54A

The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.

"Typical" represents the mean of the distribution at 25°C. "Maximum" or "minimum" represents (mean + 3σ) or (mean – 3σ) respectively, where σ is a standard deviation, over the whole temperature range.

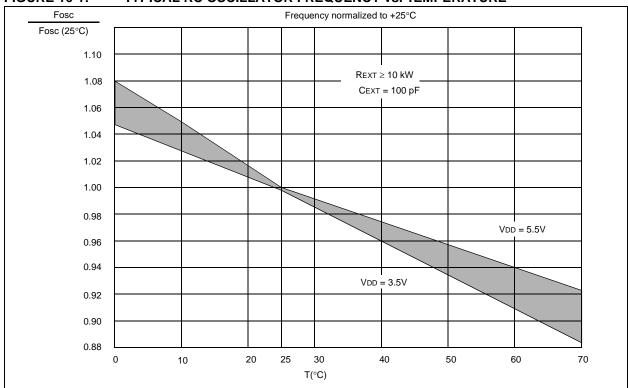


FIGURE 16-1: TYPICAL RC OSCILLATOR FREQUENCY vs. TEMPERATURE

TABLE 16-1: RC OSCILLATOR FREQUENCIES

Сехт	REXT	Average Fosc @ 5 V, 25°C				
20 pF	3.3K	5 MHz	± 27%			
	5K	3.8 MHz	± 21%			
	10K	2.2 MHz	± 21%			
	100K	262 kHz	± 31%			
100 pF	3.3K	1.6 MHz	± 13%			
	5K	1.2 MHz	± 13%			
	10K	684 kHz	± 18%			
	100K	71 kHz	± 25%			
300 pF	3.3K	660 kHz	± 10%			
	5.0K	484 kHz	± 14%			
	10K	267 kHz	± 15%			
	100K	29 kHz	± 19%			

The frequencies are measured on DIP packages.

The percentage variation indicated here is part-to-part variation due to normal process distribution. The variation indicated is ± 3 standard deviation from average value for VDD = 5V.

FIGURE 16-2: TYPICAL RC OSCILLATOR FREQUENCY vs. VDD, CEXT = 20 PF, 25°C

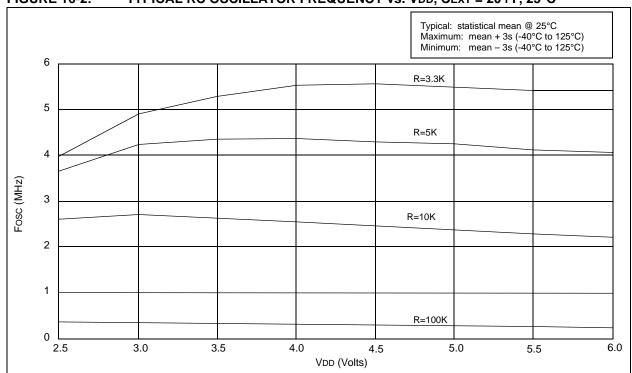
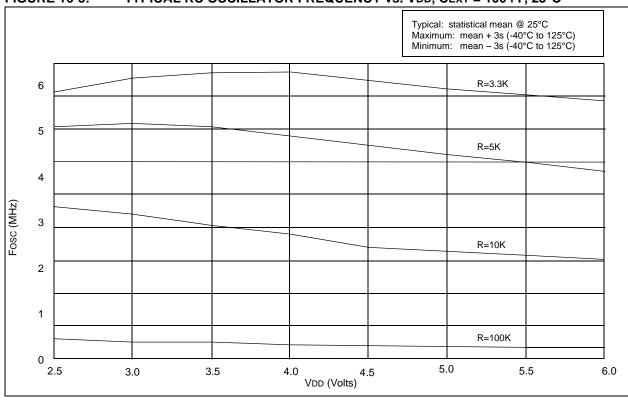


FIGURE 16-3: TYPICAL RC OSCILLATOR FREQUENCY vs. VDD, CEXT = 100 PF, 25°C



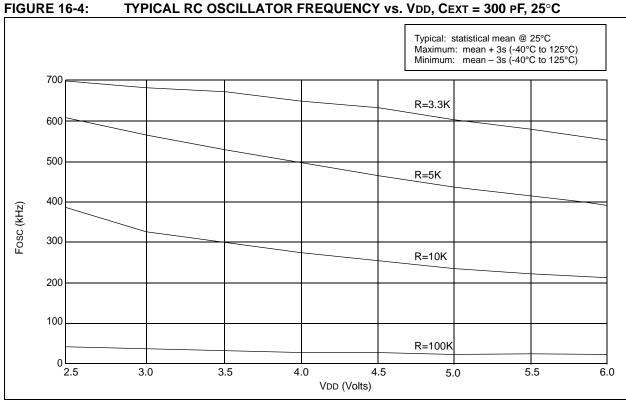


FIGURE 16-5: TYPICAL IPD vs. VDD, WATCHDOG DISABLED (25°C)

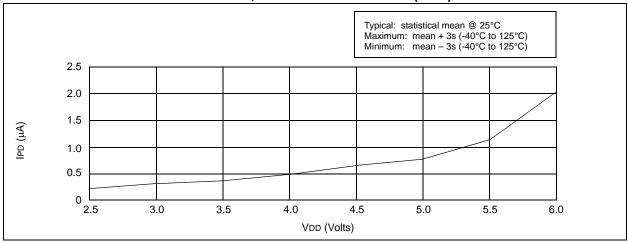
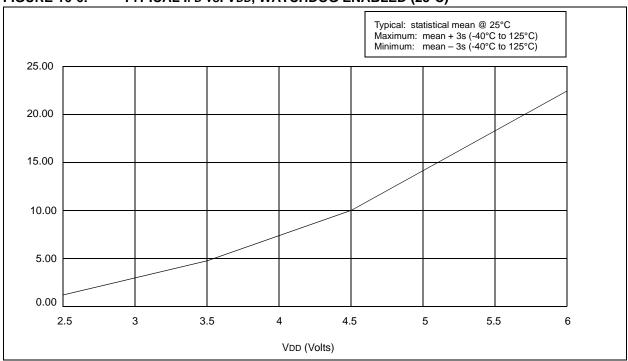
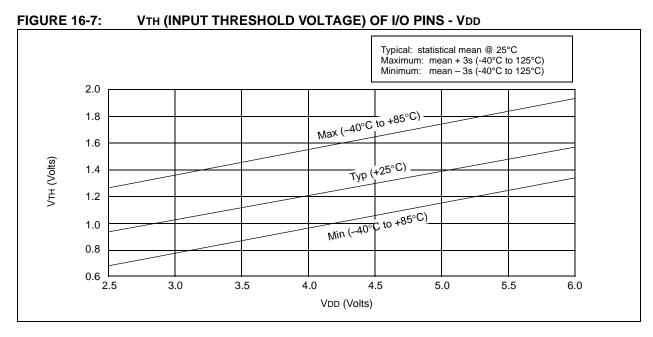
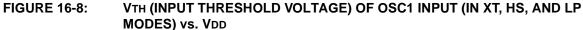
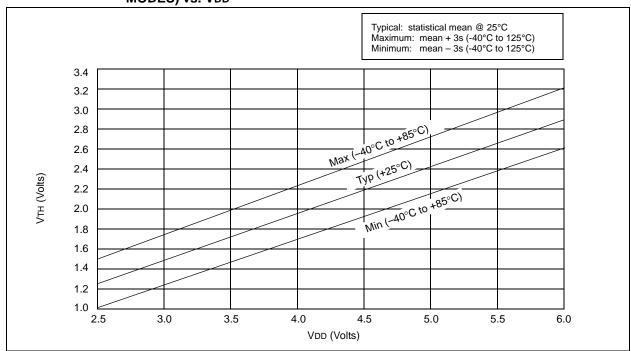


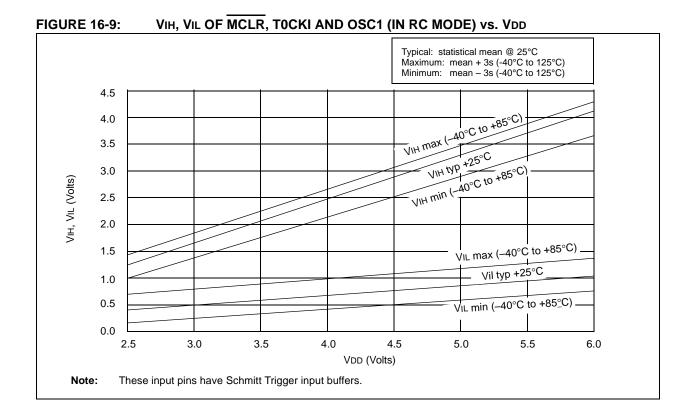
FIGURE 16-6: TYPICAL IPD vs. VDD, WATCHDOG ENABLED (25°C)







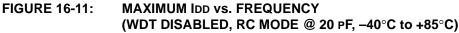




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Typical: statistical mean @ 25°C Maximum: mean + 3s (-40°C to 125°C) Minimum: mean - 3s (-40°C to 125°C) 10000 1000 IDD (μA) 100 10 0.1 10 Freq (MHz)

FIGURE 16-10: TYPICAL IDD vs. FREQUENCY (WDT DISABLED, RC MODE @ 20 PF, 25°C)



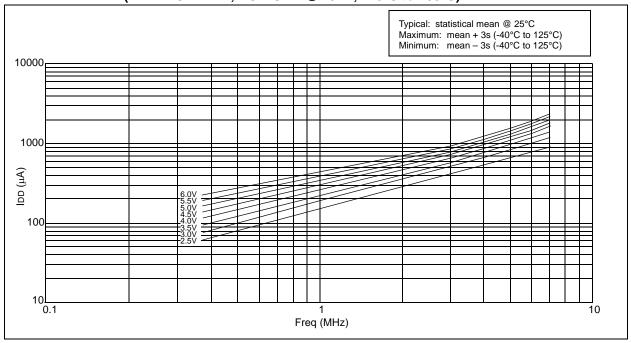


FIGURE 16-12: TYPICAL IDD vs. FREQUENCY (WDT DISABLED, RC MODE @ 100 PF, 25°C)

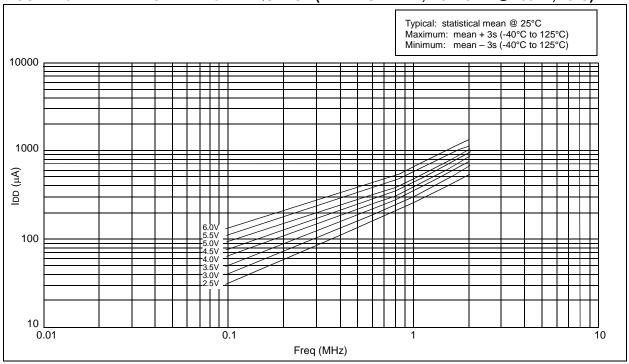
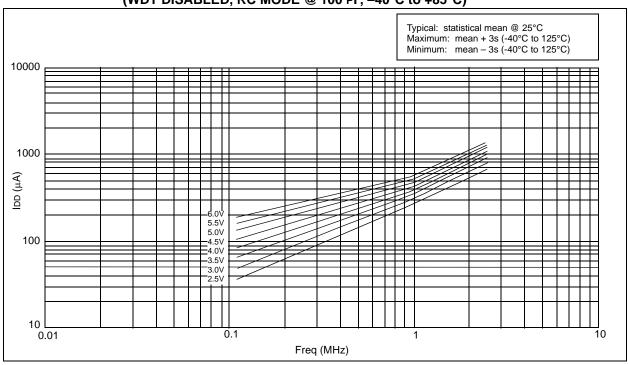


FIGURE 16-13: MAXIMUM IDD vs. FREQUENCY (WDT DISABLED, RC MODE @ 100 PF, -40°C to +85°C)



TYPICAL IDD vs. FREQUENCY (WDT DISABLED, RC MODE @ 300 PF, 25°C) Typical: statistical mean @ 25°C Maximum: mean + 3s (-40°C to 125°C) Minimum: mean - 3s (-40°C to 125°C) 10000 1000 IDD (μA) 100 5.5V 5.0V 4.5V 3.0V <u>—</u> 2.5V — 10 0.01 0.1 Freq (MHz)

FIGURE 16-14:

FIGURE 16-15: MAXIMUM IDD vs. FREQUENCY (WDT DISABLED, RC MODE @ 300 PF, -40°C to +85°C)

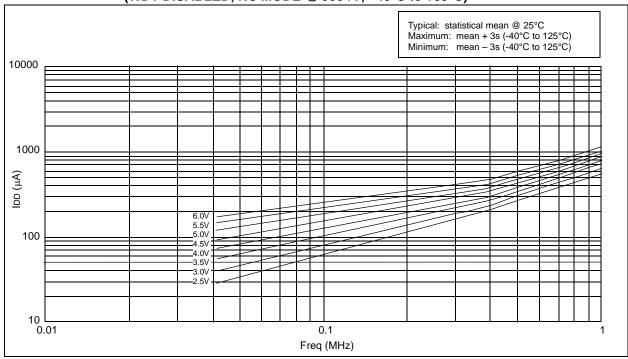


FIGURE 16-16: WDT TIMER TIME-OUT PERIOD vs. VDD⁽¹⁾

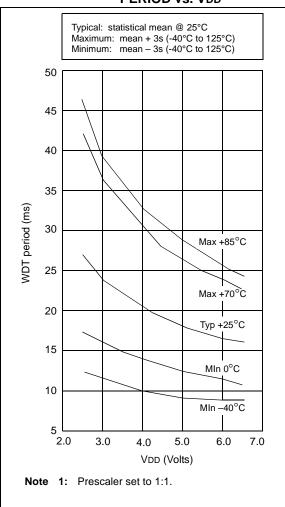


FIGURE 16-17: TRANSCONDUCTANCE (gm) OF HS OSCILLATOR vs. VDD

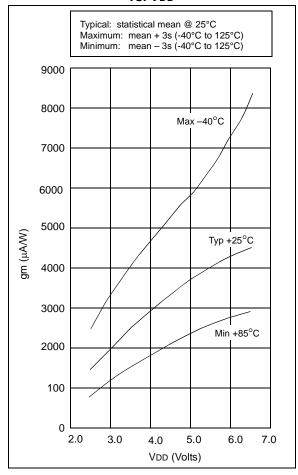


FIGURE 16-18: TRANSCONDUCTANCE (gm) OF LP OSCILLATOR vs. VDD

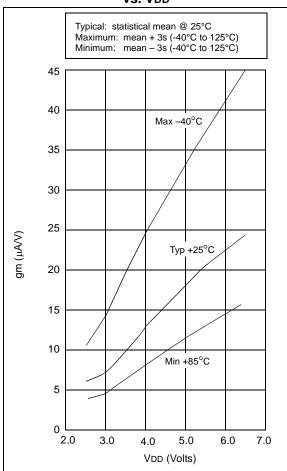


FIGURE 16-19: TRANSCONDUCTANCE (gm) OF XT OSCILLATOR vs. VDD

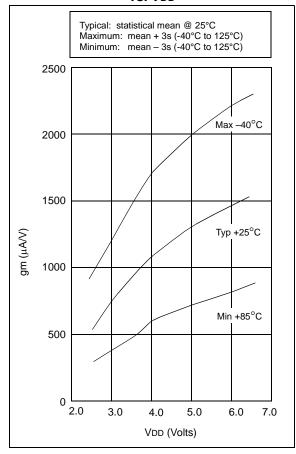


FIGURE 16-20: PORTA, B AND C IOH vs. Voh, VDD = 3V

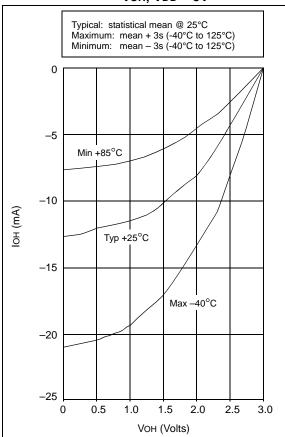


FIGURE 16-21: PORTA, B AND C IOH vs. VOH, VDD = 5V

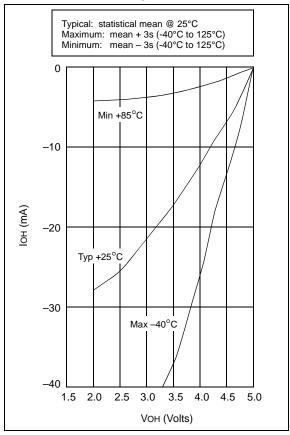


FIGURE 16-22: PORTA, B AND C IOL vs. Vol., VDD = 3V

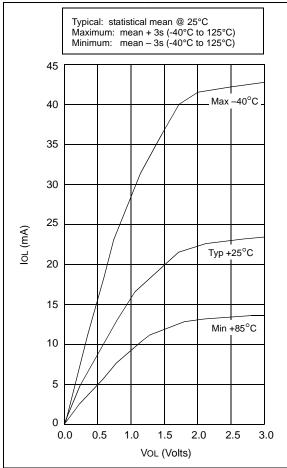
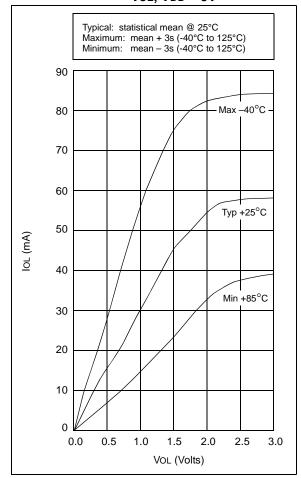


TABLE 16-2: INPUT CAPACITANCE FOR PIC16C54A/C58A

Pin	Typical Capacitance (pF)				
PIII	18L PDIP	18L SOIC			
RA port	5.0	4.3			
RB port	5.0	4.3			
MCLR	17.0	17.0			
OSC1	4.0	3.5			
OSC2/CLKOUT	4.3	3.5			
T0CKI	3.2	2.8			

All capacitance values are typical at 25°C. A part-to-part variation of $\pm 25\%$ (three standard deviations) should be taken into account.

FIGURE 16-23: PORTA, B AND C IOL vs. Vol., VDD = 5V



PIC16C5X

NOTES:

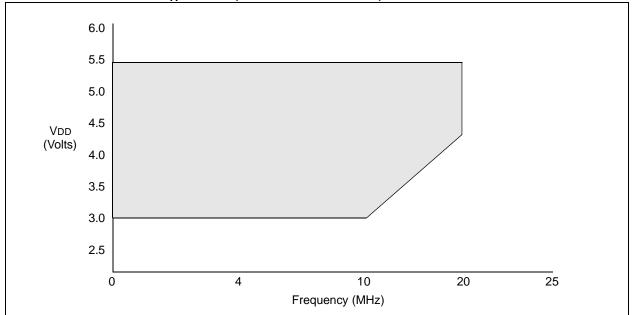
17.0 ELECTRICAL CHARACTERISTICS - PIC16LC54A

Absolute Maximum Ratings(†)

Ambient temperature under bias	55°C to +125°C
Storage temperature	–65°C to +150°C
Voltage on VDD with respect to Vss	
Voltage on MCLR with respect to Vss	0 to +14V
Voltage on all other pins with respect to Vss	0.6V to (VDD + 0.6V)
Total power dissipation ⁽¹⁾	
Max. current out of Vss pin	
Max. current into VDD pin	100 mA
Max. current into an input pin (T0CKI only)	±500 μA
Input clamp current, Iik (Vi < 0 or Vi > VDD)	±20 mA
Output clamp current, loκ (Vo < 0 or Vo > VDD)	±20 mA
Max. output current sunk by any I/O pin	25 mA
Max. output current sourced by any I/O pin	20 mA
Max. output current sourced by a single I/O (Port A, B or C)	50 mA
Max. output current sunk by a single I/O (Port A, B or C)	50 mA
Note 1: Power dissipation is calculated as follows: Pdis = VDD x {IDD - Σ IOH} + Σ {(VDD-V	/OH) x IOH} + Σ (VOL x IOL)

† NOTICE: Stresses above those listed under "Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operation listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

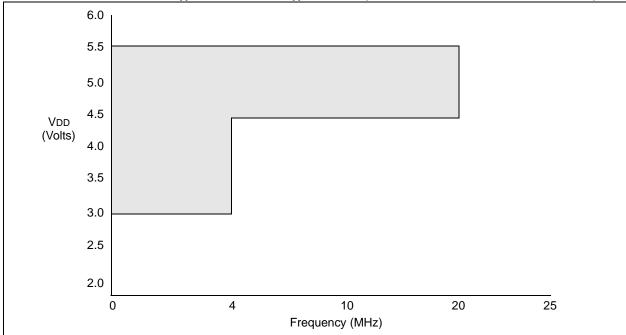
FIGURE 17-1: PIC16C54C/55A/56A/57C/58B-04, 20 VOLTAGE-FREQUENCY GRAPH, $0^{\circ}C \le T_{A} \le +70^{\circ}C$ (COMMERCIAL TEMPS)



Note 1: The shaded region indicates the permissible combinations of voltage and frequency.

2: The maximum rated speed of the part limits the permissible combinations of voltage and frequency. Please reference the Product Identification System section for the maximum rated speed of the parts.

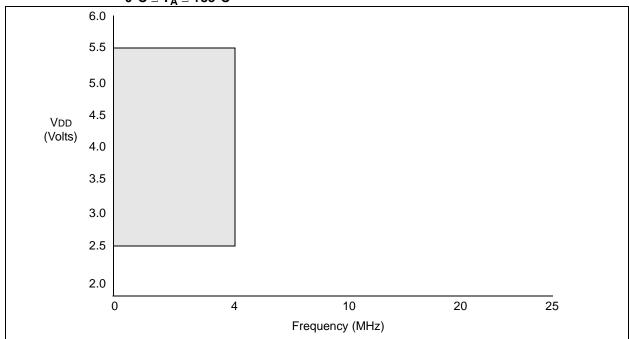
FIGURE 17-2: PIC16C54C/55A/56A/57C/58B-04, 20 VOLTAGE-FREQUENCY GRAPH, $-40^{\circ}C \leq T_A < 0^{\circ}C, +70^{\circ}C < T_A \leq +125^{\circ}C \text{ (OUTSIDE OF COMMERCIAL TEMPS)}$



Note 1: The shaded region indicates the permissible combinations of voltage and frequency.

2: The maximum rated speed of the part limits the permissible combinations of voltage and frequency. Please reference the Product Identification System section for the maximum rated speed of the parts.

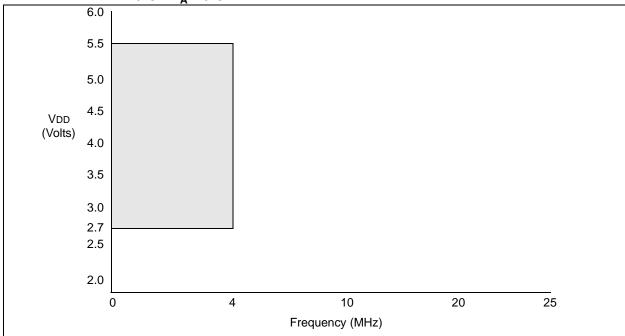
FIGURE 17-3: PIC16LC54C/55A/56A/57C/58B VOLTAGE-FREQUENCY GRAPH, $0^{\circ}C \leq T_{A} \leq +85^{\circ}C$



Note 1: The shaded region indicates the permissible combinations of voltage and frequency.

2: The maximum rated speed of the part limits the permissible combinations of voltage and frequency. Please reference the Product Identification System section for the maximum rated speed of the parts.

FIGURE 17-4: PIC16LC54C/55A/56A/57C/58B VOLTAGE-FREQUENCY GRAPH, $-40^{\circ}\text{C} \leq \text{T}_{\text{A}} \leq 0^{\circ}\text{C}$



Note 1: The shaded region indicates the permissible combinations of voltage and frequency.

2: The maximum rated speed of the part limits the permissible combinations of voltage and frequency. Please reference the Product Identification System section for the maximum rated speed of the parts.

17.1 DC Characteristics:PIC16C54C/C55A/C56A/C57C/C58B-04, 20 (Commercial, Industrial)
PIC16LC54C/LC55A/LC56A/LC57C/LC58B-04 (Commercial, Industrial)
PIC16CR54C/CR56A/CR57C/CR58B-04, 20 (Commercial, Industrial)
PIC16LCR54C/LCR56A/LCR57C/LCR58B-04 (Commercial, Industrial)

PIC16LCR5X (Commercial, Industrial) PIC16C5X St			Opera Stand	Standard Operating Conditions (unless otherwise specific Operating Temperature $0^{\circ}C \le TA \le +70^{\circ}C$ for commerciation $-40^{\circ}C \le TA \le +85^{\circ}C$ for industrial Standard Operating Conditions (unless otherwise specific Operating Temperature $0^{\circ}C \le TA \le +70^{\circ}C$ for commerciation $-40^{\circ}C \le TA \le +85^{\circ}C$ for industrial $-40^{\circ}C \le TA \le +85^{\circ}C$ for indust					
Param No.	Symbol	Characteristic/Device	Min Typ† Max Units Conditions				Conditions		
	VDD	Supply Voltage							
D001		PIC16LC5X	2.5 2.7 2.5	_ _ _	5.5 5.5 5.5	V V V	-40°C ≤ TA ≤ + 85°C, 16LCR5X -40°C ≤ TA ≤ 0°C, 16LC5X 0°C ≤ TA ≤ + 85°C 16LC5X		
D001A		PIC16C5X	3.0 4.5	_	5.5 5.5	V V	RC, XT, LP and HS mode from 0 - 10 MHz from 10 - 20 MHz		
D002	Vdr	RAM Data Retention Voltage ⁽¹⁾	_	1.5*	_	V	Device in SLEEP mode		
D003	VPOR	VDD Start Voltage to ensure Power-on Reset	_	Vss	_	V	See Section 5.1 for details on Power-on Reset		
D004	SVDD	VDD Rise Rate to ensure Power-on Reset	0.05*	_	_	V/ms	See Section 5.1 for details on Power-on Reset		

Legend: Rows with standard voltage device data only are shaded for improved readability.

- * These parameters are characterized but not tested.
- † Data in "Typ" column is at 5V, 25°C, unless otherwise stated. These parameters are for design guidance only, and are not tested.
- Note 1: This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.
 - 2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.
 - a) The test conditions for all IDD measurements in active Operation mode are: OSC1 = external square wave, from rail-to-rail; all I/O pins tristated, pulled to Vss, T0CKI = VDD, MCLR = VDD; WDT enabled/disabled as specified.
 - b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.
 - 3: Does not include current through REXT. The current through the resistor can be estimated by the formula: IR = VDD/2REXT (mA) with REXT in kΩ.

17.1 DC Characteristics:PIC16C54C/C55A/C56A/C57C/C58B-04, 20 (Commercial, Industrial) PIC16LC54C/LC55A/LC56A/LC57C/LC58B-04 (Commercial, Industrial) PIC16CR54C/CR56A/CR57C/CR58B-04, 20 (Commercial, Industrial) PIC16LCR54C/LCR56A/LCR57C/LCR58B-04 (Commercial, Industrial)

PIC16LO PIC16LO (Comm		ustrial)	Standard Operating Conditions (unless otherwise specified) Operating Temperature $0^{\circ}C \le TA \le +70^{\circ}C$ for commercial $-40^{\circ}C \le TA \le +85^{\circ}C$ for industrial				
PIC16C5X PIC16CR5X (Commercial, Industrial)							0°C ≤ TA ≤ +70°C for commercial
Param No.	Symbol	Characteristic/Device	Min Typ† Max Units Conditions				
	IDD	Supply Current ^(2,3)					
D010		PIC16LC5X	_	0.5	2.4	mA	Fosc = 4.0 MHz, VDD = 5.5V, XT and
			_	11	27	μΑ	RC modes
				14	35	μΑ	Fosc = 32 kHz, VDD = 2.5V, LP mode, Commercial
				14	33	μΑ	FOSC = 32 kHz, VDD = 2.5V, LP mode,
							Industrial
D010A		PIC16C5X	_	1.8	2.4	mA	Fosc = 4 MHz, VDD = 5.5V, XT and RC
			_	2.6	3.6*	mA	modes
			_	4.5	16	mA	FOSC = 10 MHz, VDD = 3.0V, HS mode
			_	14	32	μΑ	FOSC = 20 MHz, VDD = 5.5V, HS mode
							FOSC = 32 kHz, VDD = 3.0V, LP mode,
			_	17	40	μΑ	Commercial
							FOSC = 32 kHz, VDD = 3.0V, LP mode,
				<u> </u>			Industrial

Legend: Rows with standard voltage device data only are shaded for improved readability.

- * These parameters are characterized but not tested.
- † Data in "Typ" column is at 5V, 25°C, unless otherwise stated. These parameters are for design guidance only, and are not tested.
- Note 1: This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.
 - 2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.
 - a) The test conditions for all IDD measurements in active Operation mode are: OSC1 = external square wave, from rail-to-rail; all I/O pins tristated, pulled to Vss, T0CKI = VDD, MCLR = VDD; WDT enabled/disabled as specified
 - b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.
 - 3: Does not include current through REXT. The current through the resistor can be estimated by the formula: IR = VDD/2REXT (mA) with REXT in $k\Omega$.

17.1 DC Characteristics:PIC16C54C/C55A/C56A/C57C/C58B-04, 20 (Commercial, Industrial)
PIC16LC54C/LC55A/LC56A/LC57C/LC58B-04 (Commercial, Industrial)
PIC16CR54C/CR56A/CR57C/CR58B-04, 20 (Commercial, Industrial)
PIC16LCR54C/LCR56A/LCR57C/LCR58B-04 (Commercial, Industrial)

PIC16LC5X PIC16LCR5X (Commercial, Industrial)									
PIC16C5X PIC16CR5X (Commercial, Industrial)				Standard Operating Conditions (unless otherwise specified) Operating Temperature $0^{\circ}C \le TA \le +70^{\circ}C$ for commercial $-40^{\circ}C \le TA \le +85^{\circ}C$ for industrial					
Param No.	Symbol	Characteristic/Device	Min	Тур†	Conditions				
	IPD	Power-down Current ⁽²⁾							
D020		PIC16LC5X	_	0.25	2	μΑ	VDD = 2.5V, WDT disabled, Commercial		
			_	0.25	3	μА	VDD = 2.5V, WDT disabled, Industrial		
			_	1	5	μΑ	VDD = 2.5V, WDT enabled, Commercial		
			_	1.25	8	μА	VDD = 2.5V, WDT enabled, Industrial		
D020A		PIC16C5X	_	0.25	4.0	μΑ	VDD = 3.0V, WDT disabled, Commercial		
			_	0.25	5.0	μA	VDD = 3.0V, WDT disabled, Industrial		
				1.8	7.0*	μA	VDD = 5.5V, WDT disabled, Commercial		
				2.0	8.0*	μΑ	VDD = 5.5V, WDT disabled, Industrial		
				4 4	12* 14*	μA Λ	VDD = 3.0V, WDT enabled, Commercial VDD = 3.0V, WDT enabled, Industrial		
				9.8	27*	μA μA	VDD = 5.5V, WDT enabled, Industrial		
				12	30*	μA μA	VDD = 5.5V, WDT enabled, Confine clar		

Legend: Rows with standard voltage device data only are shaded for improved readability.

- * These parameters are characterized but not tested.
- † Data in "Typ" column is at 5V, 25°C, unless otherwise stated. These parameters are for design guidance only, and are not tested.
- Note 1: This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.
 - 2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.
 - a) The test conditions for all IDD measurements in active Operation mode are: OSC1 = external square wave, from rail-to-rail; all I/O pins tristated, pulled to Vss, T0CKI = VDD, MCLR = VDD; WDT enabled/disabled as specified.
 - b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.
 - 3: Does not include current through REXT. The current through the resistor can be estimated by the formula: IR = VDD/2REXT (mA) with REXT in kΩ.

17.2 DC Characteristics: PIC16C54C/C55A/C56A/C57C/C58B-04E, 20E (Extended) PIC16CR54C/CR56A/CR57C/CR58B-04E, 20E (Extended)

	R54C/CR	A/C56A/C57C/C58B-04E, 20E 56A/CR57C/CR58B-04E, 20E					tions (unless otherwise specified) $40^{\circ}C \le TA \le +125^{\circ}C$ for extended		
Param No.	Symbol	Characteristic	Min Typ† Max Units Conditions						
D001	VDD	Supply Voltage	3.0 4.5	_	5.5 5.5		RC, XT, LP, and HS mode from 0 - 10 MHz from 10 - 20 MHz		
D002	Vdr	RAM Data Retention Voltage ⁽¹⁾	_	1.5*	_	V	Device in SLEEP mode		
D003	VPOR	VDD start voltage to ensure Power-on Reset	_	Vss	_	V	See Section 5.1 for details on Power-on Reset		
D004	SVDD	VDD rise rate to ensure Power-on Reset	0.05*	_	_	V/ms	See Section 5.1 for details on Power-on Reset		
D010	IDD	Supply Current ⁽²⁾ XT and RC ⁽³⁾ modes HS mode	_	1.8 9.0	3.3 20	mA mA	Fosc = 4.0 MHz, VDD = 5.5V Fosc = 20 MHz, VDD = 5.5V		
D020	IPD	Power-down Current ⁽²⁾	_ _ _ _	0.3 10 12 4.8 18 26	17 50* 60* 31* 68* 90*	μΑ μΑ μΑ μΑ μΑ	VDD = 3.0V, WDT disabled VDD = 4.5V, WDT disabled VDD = 5.5V, WDT disabled VDD = 3.0V, WDT enabled VDD = 4.5V, WDT enabled VDD = 5.5V, WDT enabled		

^{*} These parameters are characterized but not tested.

- Note 1: This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.
 - 2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern, and temperature also have an impact on the current consumption.
 - a) The test conditions for all IDD measurements in active Operation mode <u>are: OSC1</u> = external square wave, from rail-to-rail; all I/O pins tristated, pulled to Vss, T0CKI = VDD, MCLR = VDD; WDT enabled/ disabled as specified.
 - b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.
 - 3: Does not include current through REXT. The current through the resistor can be estimated by the formula: IR = VDD/2REXT (mA) with REXT in $k\Omega$.

[†] Data in "Typ" column is at 5V, 25°C, unless otherwise stated. These parameters are for design guidance only, and are not tested.

17.3 DC Characteristics: PIC16C54C/C55A/C56A/C57C/C58B-04, 20 (Commercial, Industrial, Extended)
PIC16LC54C/LC55A/LC56A/LC57C/LC58B-04 (Commercial, Industrial)
PIC16CR54C/CR56A/CR57C/CR58B-04, 20 (Commercial, Industrial, Extended)
PIC16LCR54C/LCR56A/LCR57C/LCR58B-04 (Commercial, Industrial)

DC CH	ARACTE	RISTICS	Standard Operating Conditions (unless otherwise specified) Operating Temperature $0^{\circ}C \leq TA \leq +70^{\circ}C$ for commercial $-40^{\circ}C \leq TA \leq +85^{\circ}C$ for industrial $-40^{\circ}C \leq TA \leq +125^{\circ}C$ for extended						
Param No.	Symbol	Characteristic	Min Typ† Max Units Conditions						
D030	VIL	Input Low Voltage I/O Ports I/O Ports MCLR (Schmitt Trigger) T0CKI (Schmitt Trigger) OSC1 (Schmitt Trigger) OSC1	Vss Vss Vss Vss Vss	_ _ _ _	0.8 V 0.15 VDD 0.15 VDD 0.15 VDD 0.15 VDD 0.3 VDD	V V V V	4.5V <vdd 5.5v="" mode="" only<sup="" otherwise="" rc="" ≤="">(3) XT, HS and LP modes</vdd>		
D040	ViH	Input High Voltage I/O ports I/O ports MCLR (Schmitt Trigger) T0CKI (Schmitt Trigger) OSC1 (Schmitt Trigger) OSC1	2.0 0.25 Vdd+0.8 0.85 Vdd 0.85 Vdd 0.85 Vdd 0.7 Vdd	_ _ _ _	VDD VDD VDD VDD VDD VDD	V V V V	4.5V < VDD ≤ 5.5V Otherwise RC mode only ⁽³⁾ XT, HS and LP modes		
D050	VHYS	Hysteresis of Schmitt Trigger inputs	0.15 VDD*	_	_	V			
D060	lı∟	Input Leakage Current ^(1,2) I/O ports	-1.0	0.5	+1.0	μΑ	For VDD ≤ 5.5V: VSS ≤ VPIN ≤ VDD, pin at hi-impedance		
		MCLR MCLR TOCKI OSC1	-5.0 -3.0 -3.0	0.5 0.5 0.5	+5.0 +3.0 +3.0	μΑ μΑ μΑ μΑ	VPIN = VSS +0.25V VPIN = VDD VSS ≤ VPIN ≤ VDD VSS ≤ VPIN ≤ VDD, XT, HS and LP modes		
D080	Vol	Output Low Voltage I/O ports OSC2/CLKOUT		_	0.6 0.6	V V	IOL = 8.7 mA, VDD = 4.5V IOL = 1.6 mA, VDD = 4.5V, RC mode only		
D090	Voн	Output High Voltage ⁽²⁾ I/O ports OSC2/CLKOUT	VDD - 0.7 VDD - 0.7	_		V V	IOH = -5.4 mA, VDD = 4.5V IOH = -1.0 mA, VDD = 4.5V, RC mode only		

These parameters are characterized but not tested.

[†] Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

Note 1: The leakage current on the MCLR/VPP pin is strongly dependent on the applied voltage level. The specified levels represent normal operating conditions. Higher leakage current may be measured at different input voltage.

^{2:} Negative current is defined as coming out of the pin.

^{3:} For the RC mode, the OSC1/CLKIN pin is a Schmitt Trigger input. It is not recommended that the PIC16C5X be driven with external clock in RC mode.

17.4 Timing Parameter Symbology and Load Conditions

The timing parameter symbols have been created with one of the following formats:

- 1. TppS2ppS
- 2. TppS

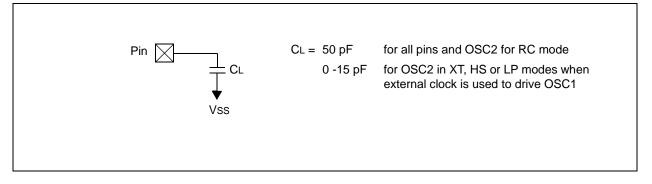
T	
F Frequency	T Time
Lowercase letters (pp) and their meanings:	

рр		
2	to	mc MCLR
ck	CLKOUT	osc oscillator
су	cycle time	os OSC1
drt	device reset timer	t0 T0CKI
io	I/O port	wdt watchdog timer

Uppercase letters and their meanings:

S			
F	Fall	Р	Period
Н	High	R	Rise
1	Invalid (Hi-impedance)	V	Valid
L	Low	Z	Hi-impedance

FIGURE 17-5: LOAD CONDITIONS FOR DEVICE TIMING SPECIFICATIONS - PIC16C54C/CR54C/C55A/C56A/CR56A/C57C/CR57C/C58B/CR58B-04, 20



17.5 Timing Diagrams and Specifications

FIGURE 17-6: EXTERNAL CLOCK TIMING - PIC16C5X, PIC16CR5X

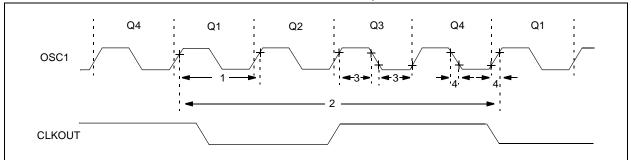


TABLE 17-1: EXTERNAL CLOCK TIMING REQUIREMENTS - PIC16C5X, PIC16CR5X

	Standard Operating Co	nditions (unless otherwise specified)	
AC Characteristics	Operating Temperature	$0^{\circ}C \leq TA \leq +70^{\circ}C$ for commercial	
AC Characteristics		-40°C ≤ TA ≤ +85°C for industrial	
		-40 °C \leq TA \leq +125°C for extended	

Param No.	Symbol	Characteristic	Min	Typ†	Max	Units	Conditions
	Fosc	External CLKIN Frequency(1)	DC		4.0	MHz	XT osc mode
			DC	_	4.0	MHz	HS osc mode (04)
			DC	_	20	MHz	HS osc mode (20)
			DC	_	200	kHz	LP osc mode
		Oscillator Frequency ⁽¹⁾	DC	_	4.0	MHz	RC osc mode
			0.45	_	4.0	MHz	XT osc mode
			4.0	_	4.0	MHz	HS osc mode (04)
			4.0	_	20	MHz	HS osc mode (20)
			5.0	_	200	kHz	LP osc mode
1	Tosc	External CLKIN Period ⁽¹⁾	250	_	_	ns	XT osc mode
			250	_		ns	HS osc mode (04)
			50	_		ns	HS osc mode (20)
			5.0	_		μS	LP osc mode
		Oscillator Period ⁽¹⁾	250	_	_	ns	RC osc mode
			250	_	2,200	ns	XT osc mode
			250	_	250	ns	HS osc mode (04)
			50	_	250	ns	HS osc mode (20)
			5.0	_	200	μS	LP osc mode

^{*} These parameters are characterized but not tested.

[†] Data in the Typical ("Typ") column is at 5V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

Note 1: All specified values are based on characterization data for that particular oscillator type under standard operating conditions with the device executing code. Exceeding these specified limits may result in an unstable oscillator operation and/or higher than expected current consumption.

When an external clock input is used, the "max" cycle time limit is "DC" (no clock) for all devices.

^{2:} Instruction cycle period (TCY) equals four times the input oscillator time base period.

TABLE 17-1: EXTERNAL CLOCK TIMING REQUIREMENTS - PIC16C5X, PIC16CR5X

AC Characteristics		Standard Operating Conditions (unless otherwise specified) Operating Temperature $0^{\circ}C \leq TA \leq +70^{\circ}C$ for commercial $-40^{\circ}C \leq TA \leq +85^{\circ}C$ for industrial $-40^{\circ}C \leq TA \leq +125^{\circ}C$ for extended							
Param No.	Symbol	Characteristic	Min	Typ†	Max	Units	Conditions		
2	Tcy	Instruction Cycle Time ⁽²⁾	_	4/Fosc	_	_			
3	TosL, TosH	Clock in (OSC1) Low or High	gh 50* — —		ns	XT oscillator			
		Time	20*	_	_	ns	HS oscillator		
			2.0*	_		μS	LP oscillator		
4	TosR, TosF	Clock in (OSC1) Rise or Fall	_	_	25*	ns	XT oscillator		
		Time	_	_	25*	ns	HS oscillator		
					50*	ne	I P oscillator		

^{*} These parameters are characterized but not tested.

- Note 1: All specified values are based on characterization data for that particular oscillator type under standard operating conditions with the device executing code. Exceeding these specified limits may result in an unstable oscillator operation and/or higher than expected current consumption.

 When an external clock input is used, the "max" cycle time limit is "DC" (no clock) for all devices.
 - 2: Instruction cycle period (TCY) equals four times the input oscillator time base period.

[†] Data in the Typical ("Typ") column is at 5V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

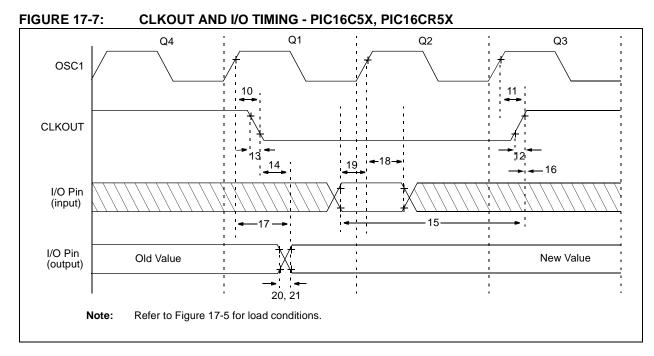


TABLE 17-2	: CLKOUT	AND I/O TIMING REQUIREMENTS -	PIC16C5X, PI	C16CR	25X		
AC Characteristics Standard Operating Conditions (unless otherwise specified) Operating Temperature $0^{\circ}\text{C} \le \text{Ta} \le +70^{\circ}\text{C}$ for commercial $-40^{\circ}\text{C} \le \text{Ta} \le +85^{\circ}\text{C}$ for industrial $-40^{\circ}\text{C} \le \text{Ta} \le +125^{\circ}\text{C}$ for extended							
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units	
10	TosH2ckL	OSC1↑ to CLKOUT↓ ⁽¹⁾	_	15	30**	ns	

Param No.	Symbol	Characteristic	Min	Тур†	Max	Units
10	TosH2ckL	OSC1↑ to CLKOUT↓ ⁽¹⁾	_	15	30**	ns
11	TosH2ckH	OSC1↑ to CLKOUT↑ ⁽¹⁾	_	15	30**	ns
12	TckR	CLKOUT rise time ⁽¹⁾	_	5.0	15**	ns
13	TckF	CLKOUT fall time ⁽¹⁾	_	5.0	15**	ns
14	TckL2ioV	CLKOUT↓ to Port out valid ⁽¹⁾	_	_	40**	ns
15	TioV2ckH	Port in valid before CLKOUT ⁽¹⁾	0.25 TCY+30*	_	_	ns
16	TckH2ioI	Port in hold after CLKOUT ⁽¹⁾	0*	_	_	ns
17	TosH2ioV	OSC1↑ (Q1 cycle) to Port out valid ⁽²⁾	_	_	100*	ns
18	TosH2iol	OSC1↑ (Q2 cycle) to Port input invalid (I/O in hold time)	TBD	_	_	ns
19	TioV2osH	Port input valid to OSC1↑ (I/O in setup time)	TBD		_	ns
20	TioR	Port output rise time ⁽²⁾	_	10	25**	ns
21	TioF	Port output fall time ⁽²⁾		10	25**	ns

These parameters are characterized but not tested.

Note 1: Measurements are taken in RC Mode where CLKOUT output is 4 x Tosc.

2: Refer to Figure 17-5 for load conditions.

These parameters are design targets and are not tested. No characterization data available at this time.

Data in the Typical ("Typ") column is at 5V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

FIGURE 17-8: RESET, WATCHDOG TIMER, AND DEVICE RESET TIMER TIMING - PIC16C5X, PIC16CR5X

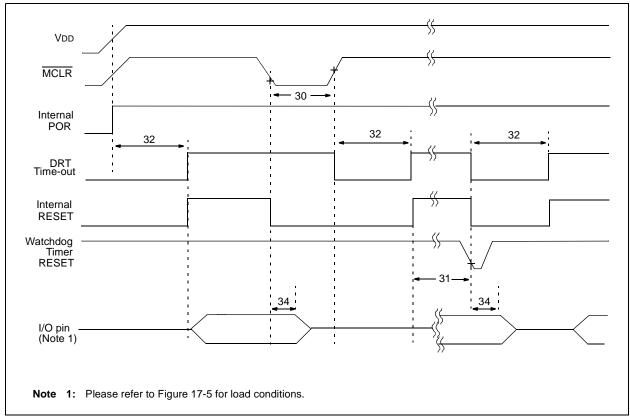


TABLE 17-3: RESET, WATCHDOG TIMER, AND DEVICE RESET TIMER - PIC16C5X, PIC16CR5X

AC Characteristics		Standard Operating Conditions (unless otherwise specified) Operating Temperature $0^{\circ}C \le TA \le +70^{\circ}C$ for commercial $-40^{\circ}C \le TA \le +85^{\circ}C$ for industrial $-40^{\circ}C \le TA \le +125^{\circ}C$ for extended						
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units	Conditions	
30	TmcL	MCLR Pulse Width (low)	1000*	_	_	ns	VDD = 5.0V	
31	Twdt	Watchdog Timer Time-out Period (No Prescaler)	9.0*	18*	30*	ms	VDD = 5.0V (Comm)	
32	TDRT	Device Reset Timer Period	9.0*	18*	30*	ms	VDD = 5.0V (Comm)	
34	Tioz	I/O Hi-impedance from MCLR Low	100*	300*	1000*	ns		

^{*} These parameters are characterized but not tested.

[†] Data in the Typical ("Typ") column is at 5V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

FIGURE 17-9: TIMERO CLOCK TIMINGS - PIC16C5X, PIC16CR5X

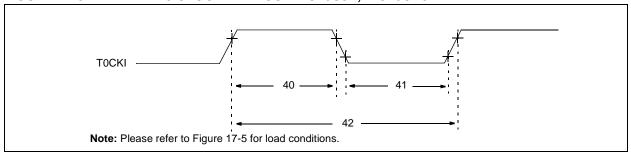


TABLE 17-4: TIMERO CLOCK REQUIREMENTS - PIC16C5X, PIC16CR5X

Standard Operating Conditions (unless otherwise specified)							
A	AC Chara	cteristics Operating Tempera	ture $0^{\circ}C \le TA \le +70^{\circ}C$ for commercial $-40^{\circ}C \le TA \le +85^{\circ}C$ for industrial $-40^{\circ}C \le TA \le +125^{\circ}C$ for extended				
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units	Conditions
40	Tt0H	T0CKI High Pulse Width - No Prescaler	0.5 Tcy + 20*	_	_	ns	
		- With Prescaler	10*	_	_	ns	
41	TtOL	T0CKI Low Pulse Width - No Prescaler	0.5 Tcy + 20*	_	_	ns	
		- With Prescaler	10*	_	_	ns	
42	Tt0P	T0CKI Period	20 or <u>Tcy + 40</u> * N	_	_	ns	Whichever is greater. N = Prescale Value (1, 2, 4,, 256)

^{*} These parameters are characterized but not tested.

[†] Data in the Typical ("Typ") column is at 5V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

18.0 DEVICE CHARACTERIZATION - PIC16LC54A

The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.

"Typical" represents the mean of the distribution at 25°C. "Maximum" or "minimum" represents (mean + 3σ) or (mean – 3σ) respectively, where σ is a standard deviation, over the whole temperature range.

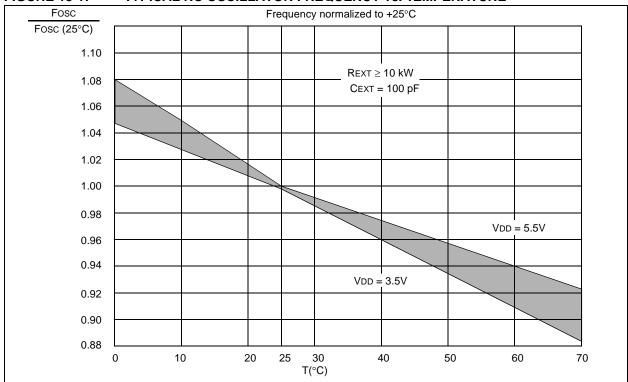


FIGURE 18-1: TYPICAL RC OSCILLATOR FREQUENCY vs. TEMPERATURE

TABLE 18-1: RC OSCILLATOR FREQUENCIES

Сехт	REXT	Aver Fosc @ !			
20 pF	3.3K	5 MHz	± 27%		
	5K	3.8 MHz	± 21%		
	10K	2.2 MHz	± 21%		
	100K	262 kHz	± 31%		
100 pF	3.3K	1.63 MHz	± 13%		
	5K	1.2 MHz	± 13%		
	10K	684 kHz	± 18%		
	100K	71 kHz	± 25%		
300 pF	3.3K	660 kHz	± 10%		
	5.0K	484 kHz	± 14%		
	10K	267 kHz	± 15%		
	100K	29 kHz ± 19%			

The frequencies are measured on DIP packages.

The percentage variation indicated here is part-to-part variation due to normal process distribution. The variation indicated is ± 3 standard deviation from average value for VDD = 5V.

FIGURE 18-2: TYPICAL RC OSCILLATOR FREQUENCY vs. VDD, CEXT = 20 PF, 25°C

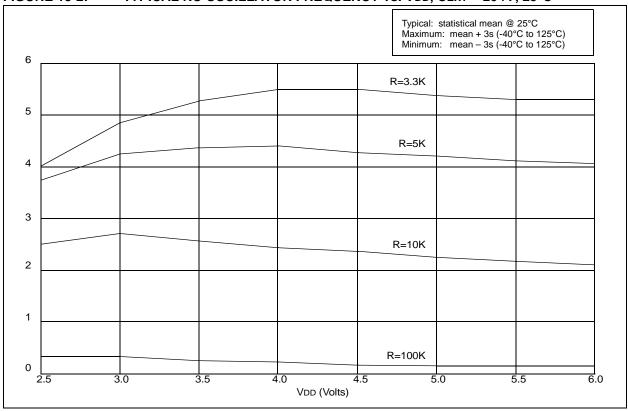


FIGURE 18-3: TYPICAL RC OSCILLATOR FREQUENCY vs. VDD, CEXT = 100 PF, 25°C

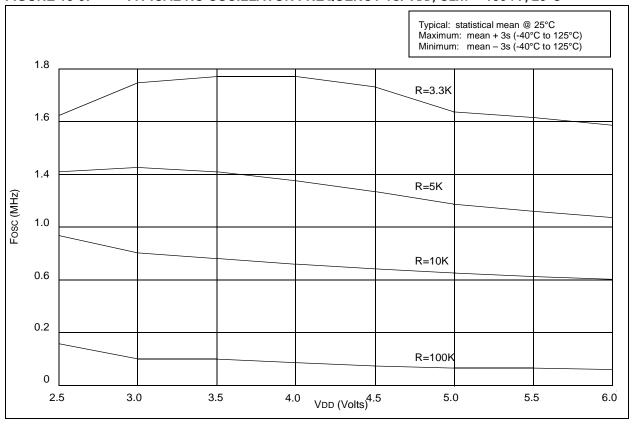
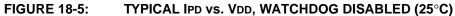


FIGURE 18-4: TYPICAL RC OSCILLATOR FREQUENCY vs. VDD, CEXT = 300 PF, 25°C Typical: statistical mean @ 25°C Maximum: mean + 3s (-40°C to 125°C) Minimum: mean - 3s (-40°C to 125°C) 700 R=3.3K 600 500 R=5K Fosc (kHz) 400 300 R=10K 200 100 R=100K 0 2.5 3.0 3.5 5.0 6.0 VDD (Volts)



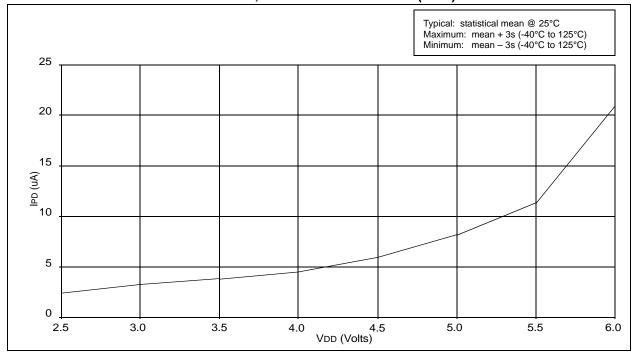


FIGURE 18-6: TYPICAL IPD vs. VDD, WATCHDOG ENABLED (25°C)

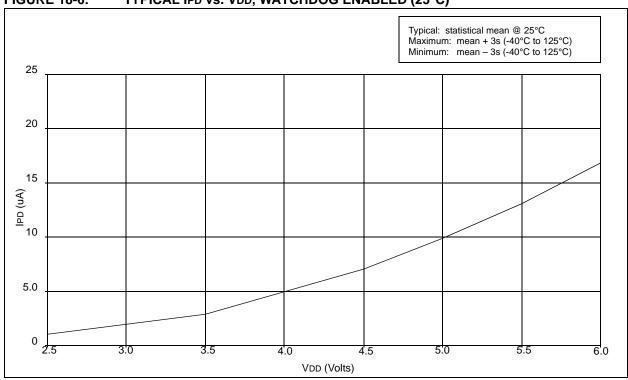


FIGURE 18-7: TYPICAL IPD vs. VDD, WATCHDOG ENABLED (-40°C, 85°C)

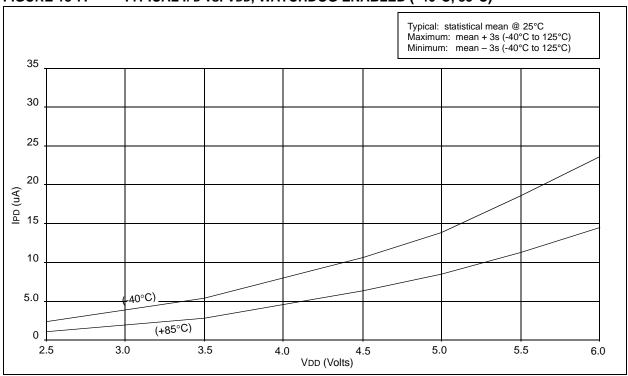


FIGURE 18-8: VTH (INPUT THRESHOLD TRIP POINT VOLTAGE) OF I/O PINS vs. VDD

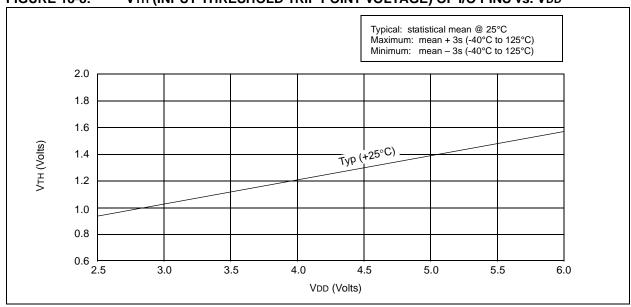


FIGURE 18-9: VIH, VIL OF MCLR, TOCKI AND OSC1 (IN RC MODE) vs. VDD

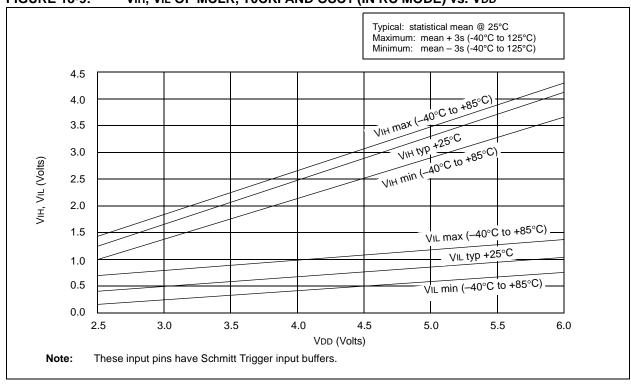


FIGURE 18-10: VTH (INPUT THRESHOLD TRIP POINT VOLTAGE) OF OSC1 INPUT (IN XT, HS AND LP MODES) vs. VDD

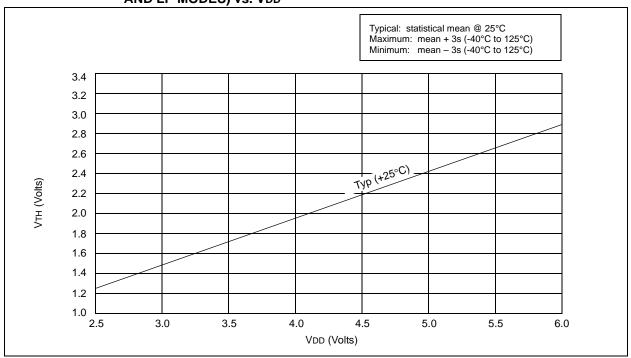
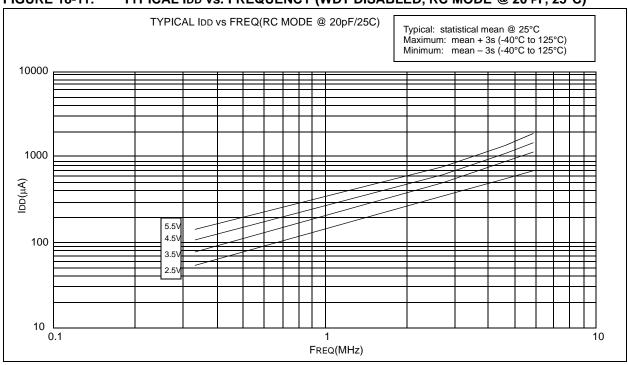


FIGURE 18-11: TYPICAL IDD vs. FREQUENCY (WDT DISABLED, RC MODE @ 20 pF, 25°C)



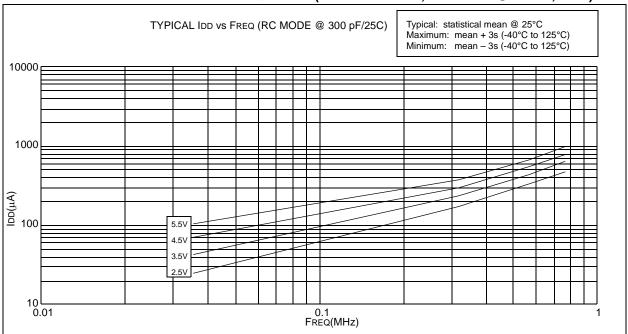
10

TYPICAL IDD vs FREQ(RC MODE @ 100 pF/25C) Typical: statistical mean @ 25°C Maximum: mean + 3s (-40°C to 125°C) Minimum: mean - 3s (-40°C to 125°C) 10000 1000 IDD(μA) 5.5\ 100 3.5

TYPICAL IDD vs. FREQUENCY (WDT DISABLED, RC MODE @ 100 PF, 25°C) FIGURE 18-12:



FREQ(MHz)



10 0.1

FIGURE 18-14: WDT TIMER TIME-OUT PERIOD vs. VDD⁽¹⁾

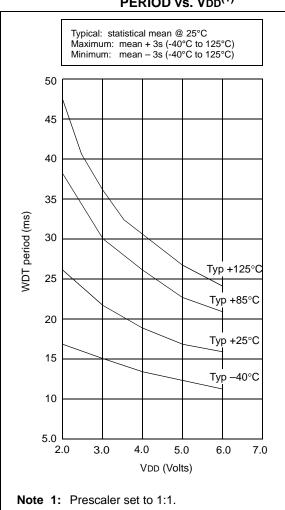


FIGURE 18-15: PORTA, B AND C IOH vs. Voh, VDD = 3 V

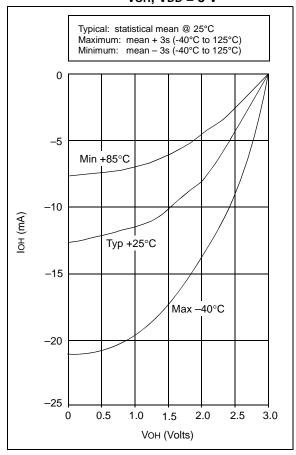


FIGURE 18-16: PORTA, B AND C IOH vs. Voh, VDD = 5 V

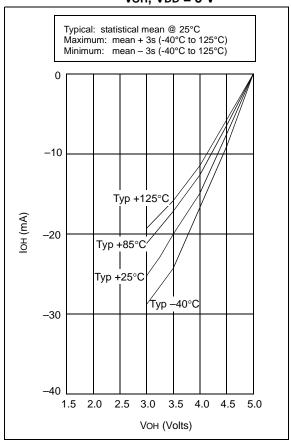


FIGURE 18-17: PORTA, B AND C IOL vs. Vol, VDD = 3 V

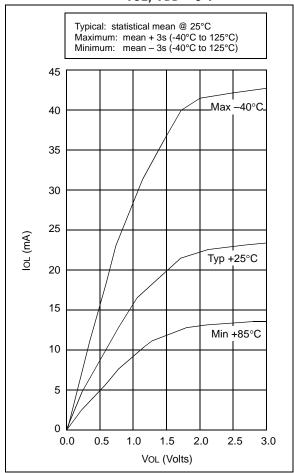


FIGURE 18-18: PORTA, B AND C IOL vs. Vol, VDD = 5 V

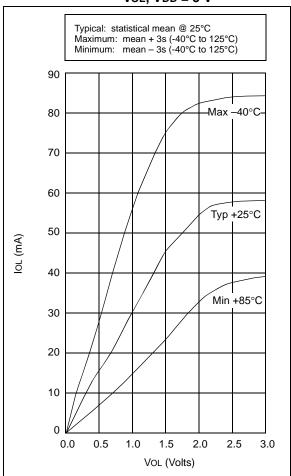


TABLE 18-2: INPUT CAPACITANCE

Pin	Typical Capacitance (pF)				
PIII	18L PDIP	18L SOIC			
RA port	5.0	4.3			
RB port	5.0	4.3			
MCLR	17.0	17.0			
OSC1	4.0	3.5			
OSC2/CLKOUT	4.3	3.5			
TOCKI	3.2	2.8			

All capacitance values are typical at 25° C. A part-to-part variation of $\pm 25\%$ (three standard deviations) should be taken into account.

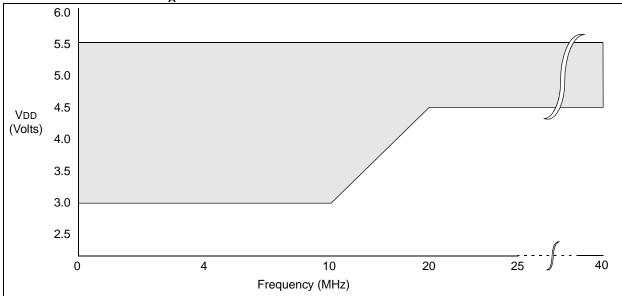
19.0 ELECTRICAL CHARACTERISTICS - PIC16LC54C 40MHz

Absolute Maximum Ratings(†)

Ambient temperature under bias	55°C to +125°C
Storage temperature	–65°C to +150°C
Voltage on VDD with respect to Vss	
Voltage on MCLR with respect to Vss	0 to +14V
Voltage on all other pins with respect to Vss	0.6V to (VDD + 0.6V)
Total power dissipation ⁽¹⁾	800 mW
Max. current out of Vss pin	
Max. current into VDD pin	100 mA
Max. current into an input pin (T0CKI only)	±500 μA
Input clamp current, IiK (VI < 0 or VI > VDD)	±20 mA
Output clamp current, loκ (Vo < 0 or Vo > VDD)	±20 mA
Max. output current sunk by any I/O pin	25 mA
Max. output current sourced by any I/O pin	20 mA
Max. output current sourced by a single I/O (Port A, B or C)	50 mA
Max. output current sunk by a single I/O (Port A, B or C)	50 mA
Note 1: Power dissipation is calculated as follows: Pdis = VDD x {IDD - Σ IOH} + Σ {(VDD-\	VOH) $x IOH$ + $\sum (VOL x IOL)$

† NOTICE: Stresses above those listed under "Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operation listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

FIGURE 19-1: PIC16C54C/C55A/C56A/C57C/C58B-40 VOLTAGE-FREQUENCY GRAPH, $0^{\circ}C \leq T_{A} \leq +70^{\circ}C$



- Note 1: The shaded region indicates the permissible combinations of voltage and frequency.
 - **2:** The maximum rated speed of the part limits the permissible combinations of voltage and frequency. Please reference the Product Identification System section for the maximum rated speed of the parts.
 - 3: Operation between 20 to 40 MHz requires the following:
 - VDD between 4.5V. and 5.5V
 - OSC1 externally driven
 - · OSC2 not connected
 - HS mode
 - Commercial temperatures

Devices qualified for 40 MHz operation have -40 designation (ex: PIC16C54C-40/P).

4: For operation between DC and 20 MHz, see Section 17.1.

19.1 DC Characteristics:PIC16C54C/C55A/C56A/C57C/C58B-40 (Commercial)⁽¹⁾

PIC16C54C/C55A/C56A/C57C/C58B-40 (Commercial)				ard Ope ing Tem	_		itions (unless otherwise specified) $0^{\circ}C \le TA \le +70^{\circ}C$ for commercial		
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units	Conditions		
D001	VDD	Supply Voltage	4.5	_	5.5	V	HS mode from 20 - 40 MHz		
D002	Vdr	RAM Data Retention Voltage ⁽²⁾	_	1.5*	_	V	Device in SLEEP mode		
D003	VPOR	VDD Start Voltage to ensure Power-on Reset	_	Vss	_	V	See Section 5.1 for details on Power-on Reset		
D004	SVDD	VDD Rise Rate to ensure Power- on Reset	0.05*	_	_	V/ms	See Section 5.1 for details on Power-on Reset		
D010	IDD	Supply Current ⁽³⁾	_	5.2 6.8	12.3 16	mA mA	FOSC = 40 MHz, VDD = 4.5V, HS mode FOSC = 40 MHz, VDD = 5.5V, HS mode		
D020	IPD	Power-down Current ⁽³⁾	_	1.8 9.8	7.0 27*	μ Α μ Α	VDD = 5.5V, WDT disabled, Commercial VDD = 5.5V, WDT enabled, Commercial		

^{*} These parameters are characterized but not tested.

- **Note 1:** Device operation between 20 MHz to 40 MHz requires the following: VDD between 4.5V to 5.5V, OSC1 pin externally driven, OSC2 pin not connected, HS oscillator mode and commercial temperatures. For operation between DC and 20 MHz, See Section 19.1.
 - 2: This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.
 - **3:** The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.
 - a) The test conditions for all IDD measurements in active Operation mode are: OSC1 = external square wave, from rail-to-rail; all I/O pins tristated, pulled to Vss, T0CKI = VDD, MCLR = VDD; WDT enabled/disabled as specified.
 - b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.

[†] Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

19.2 DC Characteristics: PIC16C54C/C55A/C56A/C57C/C58B-40 (Commercial)⁽¹⁾

DC CH	ARACTER	RISTICS	Standard Operating Conditions (unless otherwise specified) Operating Temperature $0^{\circ}C \le TA \le +70^{\circ}C$ for commercial					
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units	Conditions	
D030	VIL	Input Low Voltage I/O Ports MCLR (Schmitt Trigger) T0CKI (Schmitt Trigger) OSC1	Vss Vss Vss Vss	_ _ _	0.8 0.15 VDD 0.15 VDD 0.2 VDD	V V V	$4.5V < VDD \le 5.5V$ HS, 20 MHz \le FOSC \le 40 MHz	
D040	ViH	Input High Voltage I/O ports MCLR (Schmitt Trigger) T0CKI (Schmitt Trigger) OSC1	2.0 0.85 Vdd 0.85 Vdd 0.8 Vdd	_ _ _ _	VDD VDD VDD VDD	V V V	4.5V < VDD ≤ 5.5V HS, 20 MHz ≤ FOSC ≤ 40 MHz	
D050	VHYS	Hysteresis of Schmitt Trigger inputs	0.15 VDD*	_	_	V		
D060	lıL	Input Leakage Current ^(2,3) I/O ports MCLR	-1.0 -5.0	0.5	+1.0 +5.0	μA μA	For VDD ≤ 5.5V: VSS ≤ VPIN ≤ VDD, pin at hi-impedance VPIN = VSS +0.25V	
		MCLR TOCKI OSC1	-3.0 -3.0 -3.0	0.5 0.5 0.5	+3.0 +3.0 +3.0	μΑ μΑ μΑ μΑ	VPIN = VSS +0.25V VPIN = VDD VSS ≤ VPIN ≤ VDD VSS ≤ VPIN ≤ VDD, HS	
D080	Vol	Output Low Voltage I/O ports	_	_	0.6	V	IOL = 8.7 mA, VDD = 4.5V	
D090	Voн	Output High Voltage ⁽³⁾ I/O ports	VDD - 0.7	_	_	V	IOH = -5.4 mA, VDD = 4.5V	

^{*} These parameters are characterized but not tested.

- **Note 1:** Device operation between 20 MHz to 40 MHz requires the following: VDD between 4.5V to 5.5V, OSC1 pin externally driven, OSC2 pin not connected and HS oscillator mode and commercial temperatures. For operation between DC and 20 MHz, See Section 17.3.
 - 2: The leakage current on the MCLR/VPP pin is strongly dependent on the applied voltage level. The specified levels represent normal operating conditions. Higher leakage current may be measured at different input voltage.
 - 3: Negative current is defined as coming out of the pin.

[†] Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

19.3 Timing Parameter Symbology and Load Conditions

The timing parameter symbols have been created with one of the following formats:

- 1. TppS2ppS
- 2. TppS

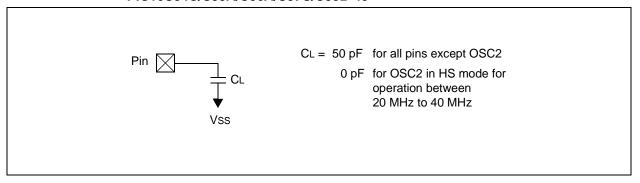
T	
F Frequency	T Time
Lowercase letters (pp) and their meanings:	
рр	
2 45	ma MOLD

pp		
2	to	mc MCLR
ck	CLKOUT	osc oscillator
су	cycle time	os OSC1
drt	device reset timer	t0 T0CKI
io	I/O port	wdt watchdog timer

Uppercase letters and their meanings:

	orease letters and tron meanings.		
S			
F	Fall	Р	Period
Н	High	R	Rise
I	Invalid (Hi-impedance)	V	Valid
L	Low	Z	Hi-impedance

FIGURE 19-2: LOAD CONDITIONS FOR DEVICE TIMING SPECIFICATIONS - PIC16C54C/C55A/C56A/C57C/C58B-40



19.4 Timing Diagrams and Specifications

FIGURE 19-3: EXTERNAL CLOCK TIMING - PIC16C5X-40

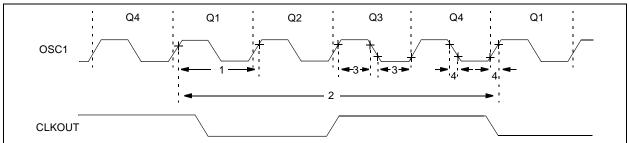


TABLE 19-1: EXTERNAL CLOCK TIMING REQUIREMENTS - PIC16C5X-40

AC Characteristics Standard Operating Conditions (unless otherwise specified Operating Temperature $0^{\circ}\text{C} \le \text{TA} \le +70^{\circ}\text{C}$ for commercial						1)	
Param No.	Symbol	Characteristic	Min	Typ†	Max Units		Conditions
	Fosc	External CLKIN Frequency ⁽¹⁾	20	_	40	MHz	HS osc mode
1	Tosc	External CLKIN Period ⁽¹⁾	25	_	_	ns	HS osc mode
2	Tcy	Instruction Cycle Time ⁽²⁾	_	4/Fosc	_	_	
3	TosL, TosH	Clock in (OSC1) Low or High Time	6.0*	_	_	ns	HS oscillator
4	TosR, TosF	Clock in (OSC1) Rise or Fall Time	_	_	6.5*	ns	HS oscillator

^{*} These parameters are characterized but not tested.

- Note 1: All specified values are based on characterization data for that particular oscillator type under standard operating conditions with the device executing code. Exceeding these specified limits may result in an unstable oscillator operation and/or higher than expected current consumption.

 When an external clock input is used, the "max" cycle time limit is "DC" (no clock) for all devices.
 - 2: Instruction cycle period (TcY) equals four times the input oscillator time base period.

[†] Data in the Typical ("Typ") column is at 5V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

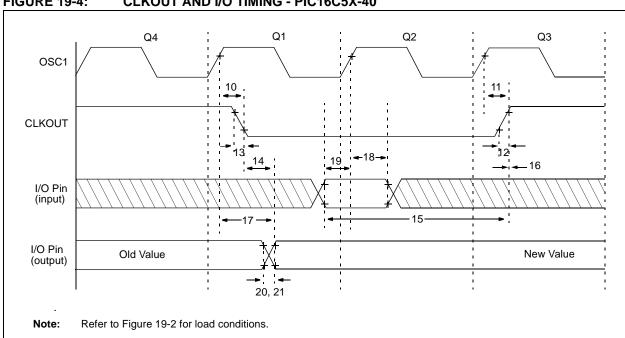


FIGURE 19-4: CLKOUT AND I/O TIMING - PIC16C5X-40

CLKOUT AND I/O TIMING REQUIREMENTS - PIC16C5X-40 TABLE 19-2:

AC Chara	acteristics	Standard Operating Conditions (unless otherwise specified) Operating Temperature $0^{\circ}C \le TA \le +70^{\circ}C$ for commercial							
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units			
10	TosH2ckL	OSC1↑ to CLKOUT↓ ^(1,2)	_	15	30**	ns			
11	TosH2ckH	OSC1↑ to CLKOUT↑ ^(1,2)	_	15	30**	ns			
12	TckR	CLKOUT rise time ^(1,2)	_	5.0	15**	ns			
13	TckF	CLKOUT fall time ^(1,2)	_	5.0	15**	ns			
14	TckL2ioV	CLKOUT↓ to Port out valid ^(1,2)	_	_	40**	ns			
15	TioV2ckH	Port in valid before CLKOUT ^(1,2)	0.25 TCY+30*	_	_	ns			
16	TckH2iol	Port in hold after CLKOUT ^(1,2)	0*	_	_	ns			
17	TosH2ioV	OSC1 [↑] (Q1 cycle) to Port out valid ⁽²⁾	_	_	100	ns			
18	TosH2iol	OSC1 [↑] (Q2 cycle) to Port input invalid (I/O in hold time)	TBD	_	_	ns			
19	TioV2osH	Port input valid to OSC1↑ (I/O in setup time)	TBD	_	_	ns			
20	TioR	Port output rise time ⁽²⁾	_	10	25**	ns			
21	TioF	Port output fall time ⁽²⁾	_	10	25**	ns			

These parameters are characterized but not tested.

Note 1: Measurements are taken in RC Mode where CLKOUT output is 4 x Tosc.

2: Refer to Figure 19-2 for load conditions.

These parameters are design targets and are not tested. No characterization data available at this time.

Data in the Typical ("Typ") column is at 5V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

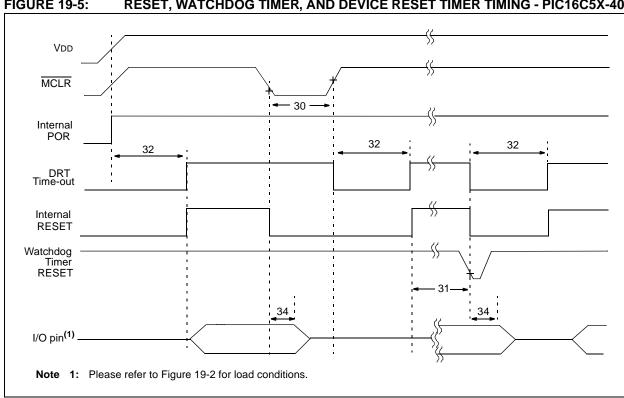


FIGURE 19-5: RESET, WATCHDOG TIMER, AND DEVICE RESET TIMER TIMING - PIC16C5X-40

TABLE 19-3: RESET, WATCHDOG TIMER, AND DEVICE RESET TIMER - PIC16C5X-40

Standard Operating Conditions (unless otherwise specified) AC Characteristics Operating Temperature 0°C ≤ TA ≤ +70°C (commercial) Operating Voltage VDD range is described in Section 19.1.							
Param No.	Symbol	Characteristic	Conditions				
30	TmcL	MCLR Pulse Width (low)	1000*	_	_	ns	VDD = 5.0V
31	Twdt	Watchdog Timer Time-out Period (No Prescaler)	9.0*	18*	30*	ms	VDD = 5.0V (Comm)
32	TDRT	Device Reset Timer Period	9.0*	18*	30*	ms	VDD = 5.0V (Comm)
34	Tioz	I/O Hi-impedance from MCLR Low	100*	300*	1000*	ns	

These parameters are characterized but not tested.

[†] Data in the Typical ("Typ") column is at 5V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

FIGURE 19-6: TIMERO CLOCK TIMINGS - PIC16C5X-40

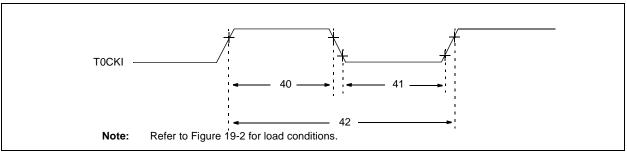


TABLE 19-4: TIMERO CLOCK REQUIREMENTS PIC16C5X-40

AC Characteristics Standard Operating Conditions (unless otherwise specified) Operating Temperature $0^{\circ}C \le TA \le +70^{\circ}C$ for commercial								
Param No.	Symbol	Characteristic	Min	Typ†	Max	Units	Conditions	
40	Tt0H	T0CKI High Pulse Width						
		- No Prescaler	0.5 Tcy + 20*	_	_	ns		
		- With Prescaler	10*	_	_	ns		
41	Tt0L	T0CKI Low Pulse Width						
		- No Prescaler	0.5 Tcy + 20*	_	_	ns		
		- With Prescaler	10*	_	_	ns		
42	Tt0P	T0CKI Period	20 or <u>TCY + 40</u> * N	_	_	ns	Whichever is greater N = Prescale Value (1, 2, 4,, 256)	

^{*} These parameters are characterized but not tested.

[†] Data in the Typical ("Typ") column is at 5V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

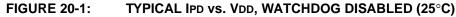
PIC16C5X

NOTES:

20.0 DEVICE CHARACTERIZATION - PIC16LC54C 40MHz

The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.

"Typical" represents the mean of the distribution at 25°C. "Maximum" or "minimum" represents (mean + 3σ) or (mean – 3σ) respectively, where σ is a standard deviation, over the whole temperature range.



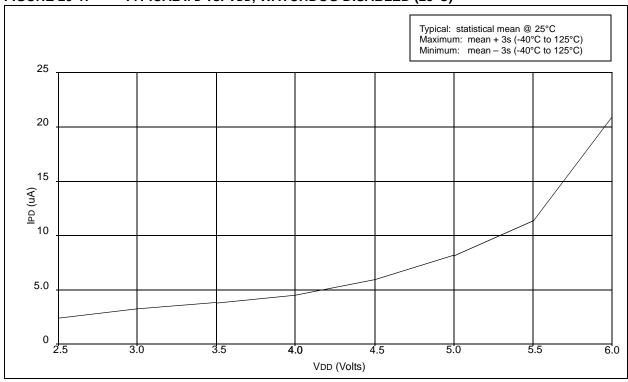


FIGURE 20-2: TYPICAL IPD vs. VDD, WATCHDOG ENABLED (25°C)

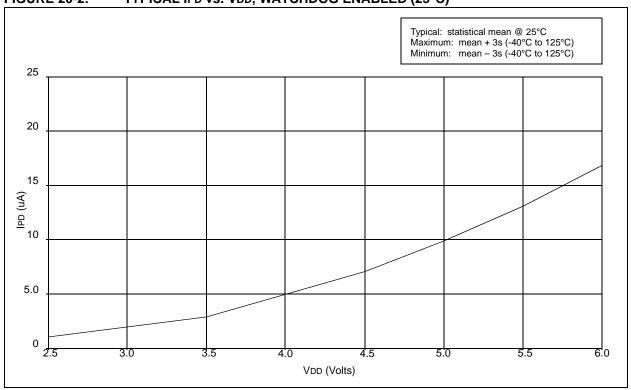
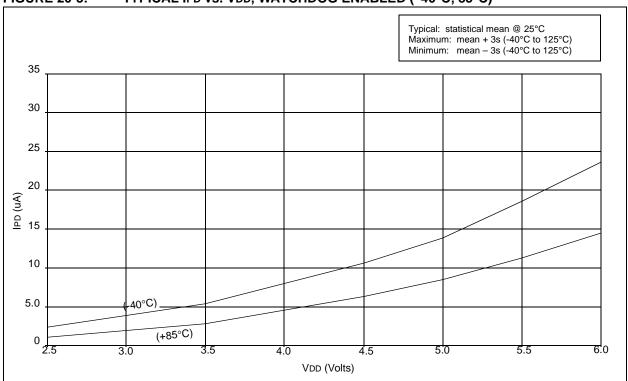


FIGURE 20-3: TYPICAL IPD vs. VDD, WATCHDOG ENABLED (-40°C, 85°C)



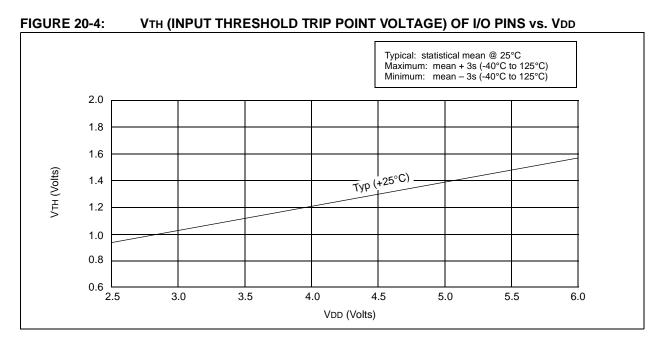
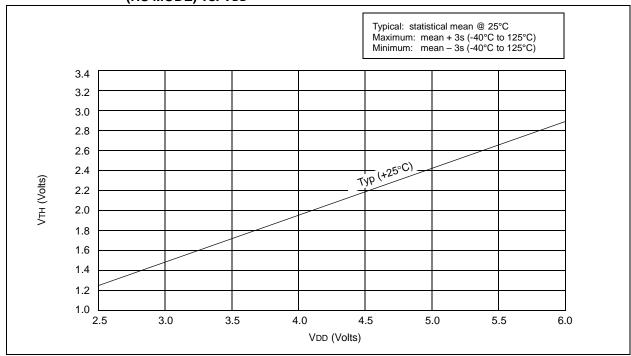


FIGURE 20-5: VTH (INPUT THRESHOLD TRIP POINT VOLTAGE) OF OSC1 INPUT (HS MODE) vs. Vdd



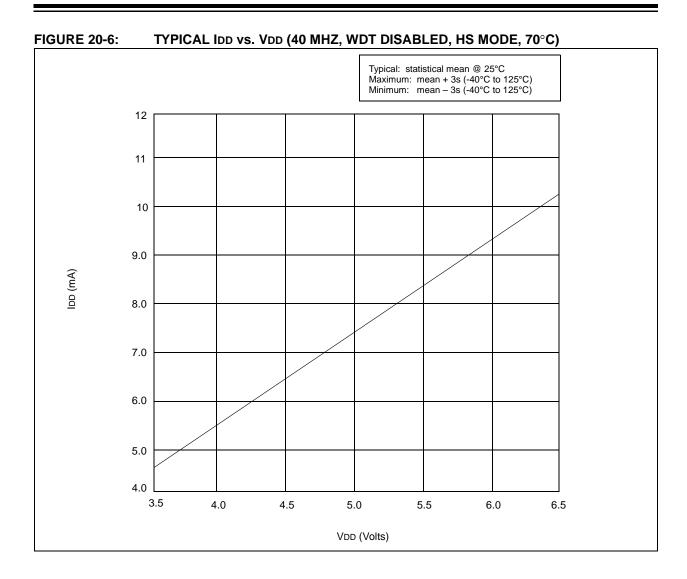


FIGURE 20-7: WDT TIMER TIME-OUT PERIOD vs. VDD⁽¹⁾

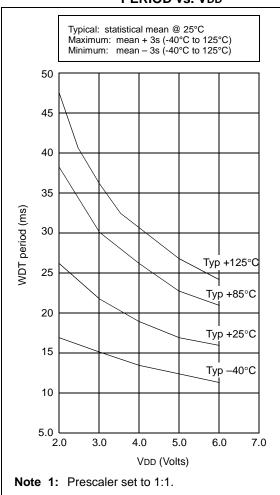
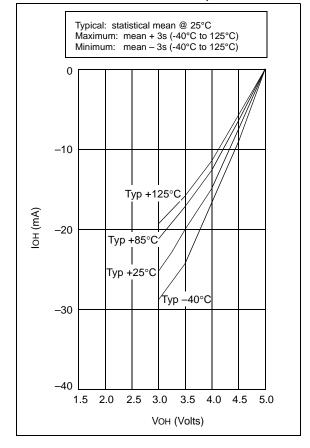


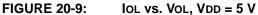
TABLE 20-1: INPUT CAPACITANCE

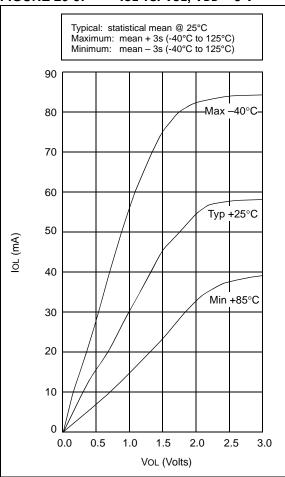
Pin	Typical Capacitance (pF)					
	18L PDIP	18L SOIC				
RA port	5.0	4.3				
RB port	5.0	4.3				
MCLR	17.0	17.0				
OSC1	4.0	3.5				
OSC2/CLKOUT	4.3	3.5				
T0CKI	3.2	2.8				

All capacitance values are typical at 25°C. A part-to-part variation of $\pm 25\%$ (three standard deviations) should be taken into account.

FIGURE 20-8: IOH vs. VOH, VDD = 5 V







21.0 PACKAGING INFORMATION

21.1 Package Marketing Information

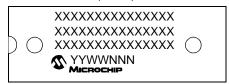
18-Lead PDIP



28-Lead Skinny PDIP (.300")



28-Lead PDIP (.600")



18-Lead SOIC



28-Lead SOIC



20-Lead SSOP



28-Lead SSOP



Example



Example



Example



Example



Example



Example

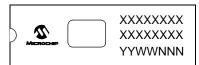


Example

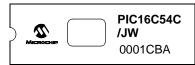


Package Marking Information (Cont'd)

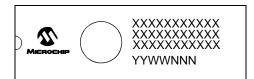
18-Lead CERDIP Windowed



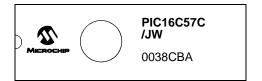
Example



28-Lead CERDIP Windowed



Example



Legend: XX...X Customer-specific information

Year code (last digit of calendar year) Υ YYYear code (last 2 digits of calendar year) WW Week code (week of January 1 is week '01')

NNN Alphanumeric traceability code

e3 Pb-free JEDEC designator for Matte Tin (Sn)

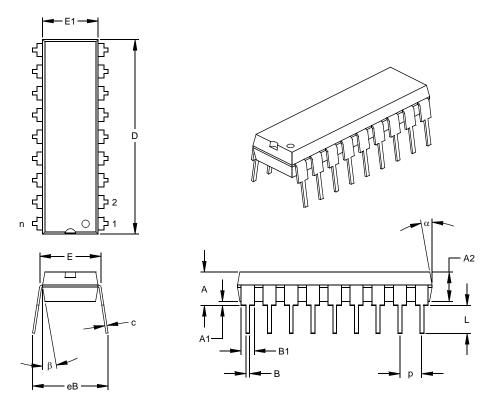
This package is Pb-free. The Pb-free JEDEC designator (e3)

can be found on the outer packaging for this package.

Note: In the event the full Microchip part number cannot be marked on one line, it will be carried over to the next line, thus limiting the number of available characters for customer-specific information.

18-Lead Plastic Dual In-line (P) - 300 mil (PDIP)

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	Units		INCHES*			MILLIMETERS		
Dimension	on Limits	MIN	NOM	MAX	MIN	NOM	MAX	
Number of Pins	n		18			18		
Pitch	р		.100			2.54		
Top to Seating Plane	Α	.140	.155	.170	3.56	3.94	4.32	
Molded Package Thickness	A2	.115	.130	.145	2.92	3.30	3.68	
Base to Seating Plane	A1	.015			0.38			
Shoulder to Shoulder Width	Е	.300	.313	.325	7.62	7.94	8.26	
Molded Package Width	E1	.240	.250	.260	6.10	6.35	6.60	
Overall Length	D	.890	.898	.905	22.61	22.80	22.99	
Tip to Seating Plane	L	.125	.130	.135	3.18	3.30	3.43	
Lead Thickness	С	.008	.012	.015	0.20	0.29	0.38	
Upper Lead Width	B1	.045	.058	.070	1.14	1.46	1.78	
Lower Lead Width	В	.014	.018	.022	0.36	0.46	0.56	
Overall Row Spacing §	eВ	.310	.370	.430	7.87	9.40	10.92	
Mold Draft Angle Top	α	5	10	15	5	10	15	
Mold Draft Angle Bottom	β	5	10	15	5	10	15	

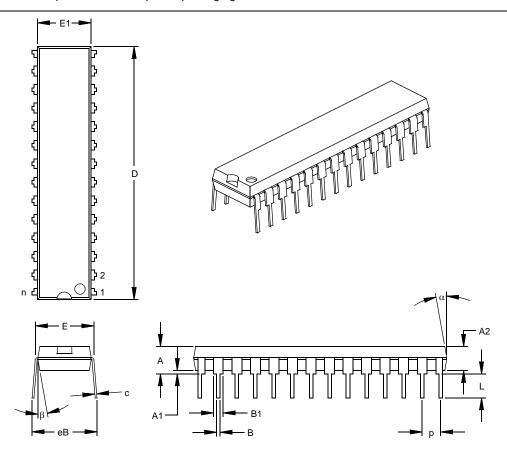
Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed

.010" (0.254mm) per side.
JEDEC Equivalent: MS-001
Drawing No. C04-007

^{*} Controlling Parameter § Significant Characteristic

28-Lead Skinny Plastic Dual In-line (SP) - 300 mil (PDIP)

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	Units	INCHES*			М		
Dimen:	sion Limits	MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		28			28	
Pitch	р		.100			2.54	
Top to Seating Plane	Α	.140	.150	.160	3.56	3.81	4.06
Molded Package Thickness	A2	.125	.130	.135	3.18	3.30	3.43
Base to Seating Plane	A1	.015			0.38		
Shoulder to Shoulder Width	Е	.300	.310	.325	7.62	7.87	8.26
Molded Package Width	E1	.275	.285	.295	6.99	7.24	7.49
Overall Length	D	1.345	1.365	1.385	34.16	34.67	35.18
Tip to Seating Plane	L	.125	.130	.135	3.18	3.30	3.43
Lead Thickness	С	.008	.012	.015	0.20	0.29	0.38
Upper Lead Width	B1	.040	.053	.065	1.02	1.33	1.65
Lower Lead Width	В	.016	.019	.022	0.41	0.48	0.56
Overall Row Spacing	§ eB	.320	.350	.430	8.13	8.89	10.92
Mold Draft Angle Top	α	5	10	15	5	10	15
Mold Draft Angle Bottom	β	5	10	15	5	10	15

^{*} Controlling Parameter § Significant Characteristic

Notes:

Dimension D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed

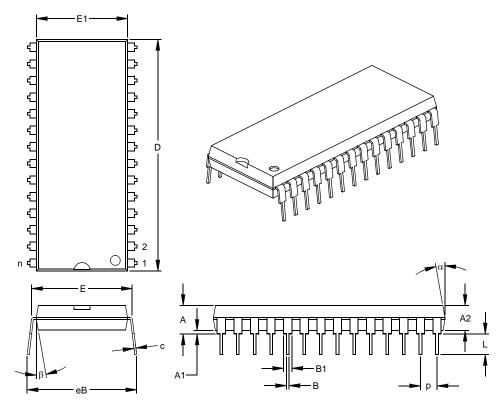
^{.010&}quot; (0.254mm) per side.

JEDEC Equivalent: MO-095

Drawing No. C04-070

28-Lead Plastic Dual In-line (P) - 600 mil (PDIP)

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	Units	INCHES*			MILLIMETERS			
Dimension	Limits	MIN	NOM	MAX	MIN	NOM	MAX	
Number of Pins	n		28			28		
Pitch	р		.100			2.54		
Top to Seating Plane	Α	.160	.175	.190	4.06	4.45	4.83	
Molded Package Thickness	A2	.140	.150	.160	3.56	3.81	4.06	
Base to Seating Plane	A1	.015			0.38			
Shoulder to Shoulder Width	Е	.595	.600	.625	15.11	15.24	15.88	
Molded Package Width	E1	.505	.545	.560	12.83	13.84	14.22	
Overall Length	D	1.395	1.430	1.465	35.43	36.32	37.21	
Tip to Seating Plane	L	.120	.130	.135	3.05	3.30	3.43	
Lead Thickness	С	.008	.012	.015	0.20	0.29	0.38	
Upper Lead Width	B1	.030	.050	.070	0.76	1.27	1.78	
Lower Lead Width	В	.014	.018	.022	0.36	0.46	0.56	
Overall Row Spacing §	eВ	.620	.650	.680	15.75	16.51	17.27	
Mold Draft Angle Top	α	5	10	15	5	10	15	
Mold Draft Angle Bottom	β	5	10	15	5	10	15	

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed

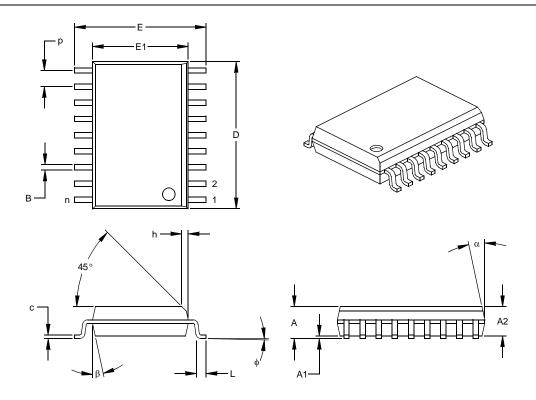
.010" (0.254mm) per side.

JEDEC Equivalent: MO-011 Drawing No. C04-079

^{*} Controlling Parameter § Significant Characteristic

18-Lead Plastic Small Outline (SO) - Wide, 300 mil (SOIC)

For the most current package drawings, please see the Microchip Packaging Specification located Note: at http://www.microchip.com/packaging



	Units	INCHES*			MILLIMETERS		
Dimension	Limits	MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		18			18	
Pitch	р		.050			1.27	
Overall Height	Α	.093	.099	.104	2.36	2.50	2.64
Molded Package Thickness	A2	.088	.091	.094	2.24	2.31	2.39
Standoff §	A1	.004	.008	.012	0.10	0.20	0.30
Overall Width	Е	.394	.407	.420	10.01	10.34	10.67
Molded Package Width	E1	.291	.295	.299	7.39	7.49	7.59
Overall Length	D	.446	.454	.462	11.33	11.53	11.73
Chamfer Distance	h	.010	.020	.029	0.25	0.50	0.74
Foot Length	L	.016	.033	.050	0.41	0.84	1.27
Foot Angle	ф	0	4	8	0	4	8
Lead Thickness	С	.009	.011	.012	0.23	0.27	0.30
Lead Width	В	.014	.017	.020	0.36	0.42	0.51
Mold Draft Angle Top	α	0	12	15	0	12	15
Mold Draft Angle Bottom	β	0	12	15	0	12	15

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed

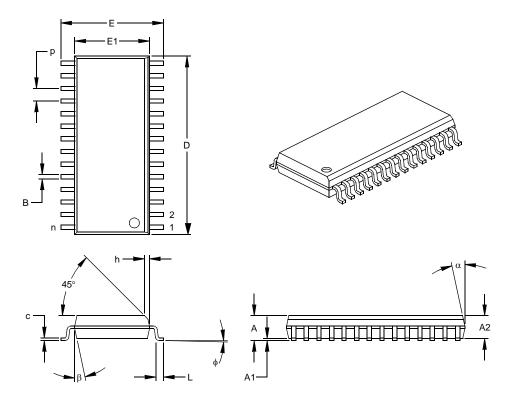
.010" (0.254mm) per side.
JEDEC Equivalent: MS-013
Drawing No. C04-051

^{*} Controlling Parameter § Significant Characteristic

28-Lead Plastic Small Outline (SO) - Wide, 300 mil (SOIC)

Note:

For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	Units	INCHES*			MILLIMETERS			
Dimension	Limits	MIN	NOM	MAX	MIN	NOM	MAX	
Number of Pins	n		28			28		
Pitch	р		.050			1.27		
Overall Height	Α	.093	.099	.104	2.36	2.50	2.64	
Molded Package Thickness	A2	.088	.091	.094	2.24	2.31	2.39	
Standoff §	A1	.004	.008	.012	0.10	0.20	0.30	
Overall Width	Е	.394	.407	.420	10.01	10.34	10.67	
Molded Package Width	E1	.288	.295	.299	7.32	7.49	7.59	
Overall Length	D	.695	.704	.712	17.65	17.87	18.08	
Chamfer Distance	h	.010	.020	.029	0.25	0.50	0.74	
Foot Length	L	.016	.033	.050	0.41	0.84	1.27	
Foot Angle Top	ф	0	4	8	0	4	8	
Lead Thickness	С	.009	.011	.013	0.23	0.28	0.33	
Lead Width	В	.014	.017	.020	0.36	0.42	0.51	
Mold Draft Angle Top	α	0	12	15	0	12	15	
Mold Draft Angle Bottom	β	0	12	15	0	12	15	

Notes:

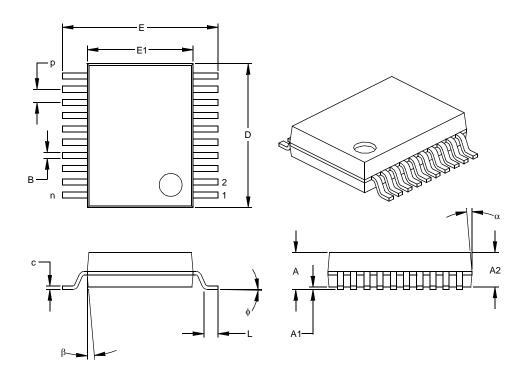
Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed

.010" (0.254mm) per side. JEDEC Equivalent: MS-013 Drawing No. C04-052

^{*} Controlling Parameter § Significant Characteristic

20-Lead Plastic Shrink Small Outline (SS) - 209 mil, 5.30 mm (SSOP)

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	Units	INCHES*			MILLIMETERS			
Dimension	Limits	MIN	NOM	MAX	MIN	NOM	MAX	
Number of Pins	n		20			20		
Pitch	р		.026			0.65		
Overall Height	Α	.068	.073	.078	1.73	1.85	1.98	
Molded Package Thickness	A2	.064	.068	.072	1.63	1.73	1.83	
Standoff §	A1	.002	.006	.010	0.05	0.15	0.25	
Overall Width	Е	.299	.309	.322	7.59	7.85	8.18	
Molded Package Width	E1	.201	.207	.212	5.11	5.25	5.38	
Overall Length	D	.278	.284	.289	7.06	7.20	7.34	
Foot Length	L	.022	.030	.037	0.56	0.75	0.94	
Lead Thickness	С	.004	.007	.010	0.10	0.18	0.25	
Foot Angle	ф	0	4	8	0.00	101.60	203.20	
Lead Width	В	.010	.013	.015	0.25	0.32	0.38	
Mold Draft Angle Top	α	0	5	10	0	5	10	
Mold Draft Angle Bottom	β	0	5	10	0	5	10	

^{*} Controlling Parameter

Notes

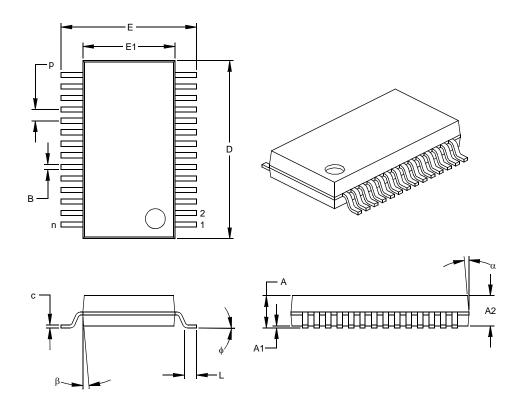
Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed

.010" (0.254mm) per side.
JEDEC Equivalent: MO-150
Drawing No. C04-072

[§] Significant Characteristic

28-Lead Plastic Shrink Small Outline (SS) - 209 mil, 5.30 mm (SSOP)

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	Units	INCHES			MILLIMETERS*		
Dimension	Limits	MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		28			28	
Pitch	р		.026			0.65	
Overall Height	Α	.068	.073	.078	1.73	1.85	1.98
Molded Package Thickness	A2	.064	.068	.072	1.63	1.73	1.83
Standoff §	A1	.002	.006	.010	0.05	0.15	0.25
Overall Width	Е	.299	.309	.319	7.59	7.85	8.10
Molded Package Width	E1	.201	.207	.212	5.11	5.25	5.38
Overall Length	D	.396	.402	.407	10.06	10.20	10.34
Foot Length	L	.022	.030	.037	0.56	0.75	0.94
Lead Thickness	С	.004	.007	.010	0.10	0.18	0.25
Foot Angle	ф	0	4	8	0.00	101.60	203.20
Lead Width	В	.010	.013	.015	0.25	0.32	0.38
Mold Draft Angle Top	α	0	5	10	0	5	10
Mold Draft Angle Bottom	β	0	5	10	0	5	10

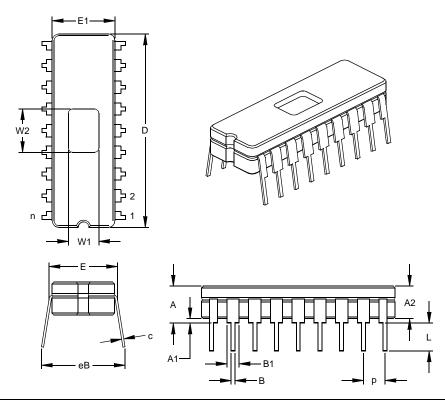
Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" (0.254mm) per side.

JEDEC Equivalent: MS-150 Drawing No. C04-073

^{*} Controlling Parameter § Significant Characteristic

18-Lead Ceramic Dual In-line with Window (JW) - 300 mil (CERDIP)

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



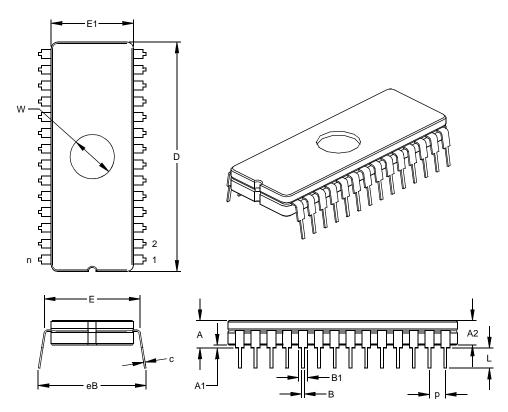
	Units	INCHES*			MILLIMETERS		
Dimension	Limits	MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		18			18	
Pitch	р		.100			2.54	
Top to Seating Plane	Α	.170	.183	.195	4.32	4.64	4.95
Ceramic Package Height	A2	.155	.160	.165	3.94	4.06	4.19
Standoff	A1	.015	.023	.030	0.38	0.57	0.76
Shoulder to Shoulder Width	Е	.300	.313	.325	7.62	7.94	8.26
Ceramic Pkg. Width	E1	.285	.290	.295	7.24	7.37	7.49
Overall Length	D	.880	.900	.920	22.35	22.86	23.37
Tip to Seating Plane	L	.125	.138	.150	3.18	3.49	3.81
Lead Thickness	С	.008	.010	.012	0.20	0.25	0.30
Upper Lead Width	B1	.050	.055	.060	1.27	1.40	1.52
Lower Lead Width	В	.016	.019	.021	0.41	0.47	0.53
Overall Row Spacing §	eВ	.345	.385	.425	8.76	9.78	10.80
Window Width	W1	.130	.140	.150	3.30	3.56	3.81
Window Length	W2	.190	.200	.210	4.83	5.08	5.33

^{*} Controlling Parameter § Significant Characteristic JEDEC Equivalent: MO-036

Drawing No. C04-010

28-Lead Ceramic Dual In-line with Window (JW) - 600 mil (CERDIP)

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	Units	Units INCHES*			MILLIMETERS		
Dimension Limits		MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		28			28	
Pitch	р		.100			2.54	
Top to Seating Plane	Α	.195	.210	.225	4.95	5.33	5.72
Ceramic Package Height	A2	.155	.160	.165	3.94	4.06	4.19
Standoff	A1	.015	.038	.060	0.38	0.95	1.52
Shoulder to Shoulder Width	Е	.595	.600	.625	15.11	15.24	15.88
Ceramic Pkg. Width	E1	.514	.520	.526	13.06	13.21	13.36
Overall Length	D	1.430	1.460	1.490	36.32	37.08	37.85
Tip to Seating Plane	L	.125	.138	.150	3.18	3.49	3.81
Lead Thickness	С	.008	.010	.012	0.20	0.25	0.30
Upper Lead Width	B1	.050	.058	.065	1.27	1.46	1.65
Lower Lead Width	В	.016	.020	.023	0.41	0.51	0.58
Overall Row Spacing §	eВ	.610	.660	.710	15.49	16.76	18.03
Window Diameter	W	.270	.280	.290	6.86	7.11	7.37

^{*} Controlling Parameter § Significant Characteristic JEDEC Equivalent: MO-103 Drawing No. C04-013

APPENDIX A: COMPATIBILITY

To convert code written for PIC16CXX to PIC16C5X, the user should take the following steps:

- Check any CALL, GOTO or instructions that modify the PC to determine if any program memory page select operations (PA2, PA1, PA0 bits) need to be made.
- Revisit any computed jump operations (write to PC or add to PC, etc.) to make sure page bits are set properly under the new scheme.
- Eliminate any special function register page switching. Redefine data variables to reallocate them.
- 4. Verify all writes to STATUS, OPTION, and FSR registers since these have changed.
- Change RESET vector to proper value for processor used.
- 6. Remove any use of the ADDLW, RETURN and SUBLW instructions.
- 7. Rewrite any code segments that use interrupts.

APPENDIX B: REVISION HISTORY

Revision KE (January 2013)

Added a note to each package outline drawing.

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NOTES:

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PART NO.	- <u>xx</u>	<u>X</u>	<u>/XX</u>	XXX	Exam	ples:
Device	Frequency Range/OSC Type	Temperature Range	Package	Pattern	a) I	PIC16C55A - PDIP packag QTP pattern : PIC16LC54C
Device	PIC16C54 PIC16C54A PIC16C754A PIC16C754C PIC16C55 PIC16C55A PIC16C56A PIC16C56A PIC16C57 PIC16C57C PIC16C57C PIC16C58B PIC16C788B	PIC16C54T ^C PIC16C54AT PIC16C55AT PIC16C55AT PIC16C55AT PIC16C55AT PIC16C55AT PIC16C56AT PIC16C56AT PIC16C56AT PIC16C56AT PIC16C56AT PIC16C5AT PIC16C5AT PIC16C5AT PIC16C5AT PIC16C5AT PIC16C5AT PIC16C5AT PIC16C5AT PIC16C5AT	(2) (T ⁽²⁾ (2) (2) (2) (2) (2) (2) (2) (3) (4) (7) (7) (7) (7) (7) (7) (7) (7		c) I	protections of the control of the co
Frequency Range/ Oscillator Type	RC Resistor Capacitor LP Low Power Crystal XT Standard Crystal/Resonator HS High Speed Crystal 2 200 KHz (LP) or 2 MHz (XT and RC) 4 200 KHz (LP) or 4 MHz (XT and RC) 10 10 MHz (HS only) 20 20 MHz (HS only) 40 40 MHz (HS only) 5 No oscillator type for JW packages(3) *RC/LP/XT/HS are for 16C54/55/56/57 devices only -02 is available for 16LV54A only -04/10/20 options are available for all other devices -40 is available for 16C54C/55A/56A/57C/58B devices only					2: I = III packa 3: JW De progration. J requir includ 4: b = Bl
Temperature Range	b ⁽⁴⁾ = 0°C I = -40°C E = -40°C	to +85°C				
Package	JW = 28-pin DIP ⁽³⁾ P = 28-pin SO = 300 m SS = 209 m SP = 28-pin	Waffle Pack 600 mil/18-pin 300 600 mil/18-pin 300 il SOIC il SSOP 300 mil Skinny PE for additional packa) mil PDIP			
Pattern		// code (factory spe lank for OTP and V				

- 04/P 301 = Commercial Temp., ge, 4 MHz, standard VDD limits,
- 04I/SO Industrial Temp., SOIC kHz, extended V_{DD} limits
- RC/SP = RC Oscillator, commernny PDIP package, 4 MHz, stan-
- Γ -40/SS 123 = commercial P package in tape and reel, 4 ded VDD limits, ROM pattern

ormal voltage range

extended

- tape and reel SOIC and SSOP iges only
- evices are UV erasable and can be ammed to any device configura-IW Devices meet the electrical ements of each oscillator type, ing LC devices.
- ank

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